



1. Theory Of Operation

1.1 LOWBAND RECEIVER

The received signal is applied to the radio's antenna input J1 and routed through the harmonic filter and antenna switch which are located on the PA deck. The signal is then routed via coax to J4 on the RF board and passes through a 4 pole bandpass filter.

The signal then passes through one stage of RF amplification Q1, which has a current source comprised of Q2, Q3, and Q4. This circuitry sets a bias current that does not vary regardless of DC Beta variations on Q1. CR2 located on the input side of Q1 is a protective diode that ensures Q1 will be protected from high level RF signals. The amplified signal then passes through a second 4 pole bandpass filter.

The amplified RF signal is then mixed with the receive VCO signal in the double balanced quad diode mixer, CR1. The desired 10.7 MHz IF signal is then amplified through Q51 and passes through a IF delay line used for extender operation. The 10.7 MHz IF signal proceeds through the extender blanker switches, Q52 and Q53. Q54 provides another stage of IF amplification to the signal.

The 10.7 MHz IF signal then passes through a 4 pole crystal filter. One more stage of amplification Q56, occurs before the IF signal is sent to the receiver subsystem IC, U51.

U51 (see Figure 1) is a complete receiver subsystem and the 10.7 MHz signal is mixed with a 10.245 MHz crystal to produce a 455 kHz second IF signal. The second IF signal is then amplified and filtered by 455 kHz ceramic filters, FL51 and FL52.

The audio detector is internal to the U51 IC. The quadrature detector detects the audio and routes it to the PL filter and carrier squelch amplifier. The carrier squelch amplifier amplifies the detected audio and routes it via U51-8 to the squelch control R70. The squelch control output is routed through a high pass filter to remove the receive audio components. The remaining noise above the audio band is

detected via U51-6 by the carrier squelch detector which generates a DC voltage. This voltage controls the audio mute circuits. The detected audio is then sent to the logic board audio circuitry via U51-5 to J6-3.

1.2 EXTENDER OPERATION

After the first mixer stage CR1, the RF signal passes through post mixer filtering comprised of bandpass selectivity circuits surrounding L51, L52, and L53. First IF amplification is provided by Q51. The IF signal divides at the base of Q51. The extender pulse detector and blanker circuits are fed by one path while the first IF amplifier Q51 is driven by the other.

The first IF amplifier Q51 amplifies the signal where it couples into the IF delay line section comprised of circuits associated with L55 and L56. After the signal passes through the delay line the signal can be blanked with the appropriate signal applied to Q52 and Q53. Post blanker isolation is provided by Q54. The signal then passes into the first 4 pole filtering section of the 10.7 MHz IF.

The Extender samples RF from the base of Q51 and drives the extender isolation amplifier Q351. Q351 in turn amplifies the signal and pulse which is then applied to the gain block U351. Q352 detects the output of U351 for further processing. Pulse shaping and amplification are accomplished by Q353 and Q354. Q355 is driven to toggle Q52 and Q53 in the IF to blank the noise pulse as it exits the IF delay line. The output of Q354 also drives a three stage AGC detector comprised of Q356, Q357, and Q358 which reduces the gain of U351 under large signal and high pulse repetition rate conditions.

1.3 VHF RECEIVER

The received signal is applied to the radio's antenna input and routed through the harmonic filter/ antenna switch. The output is then routed via coax to J4 on the RF board. The input at J4 is matched to a fixed tuned 4 pole filter. The 4 pole filter has a 3 dB bandwidth of 40 MHz and 1 dB bandwidth of 35 MHz centered at about 160 MHz.

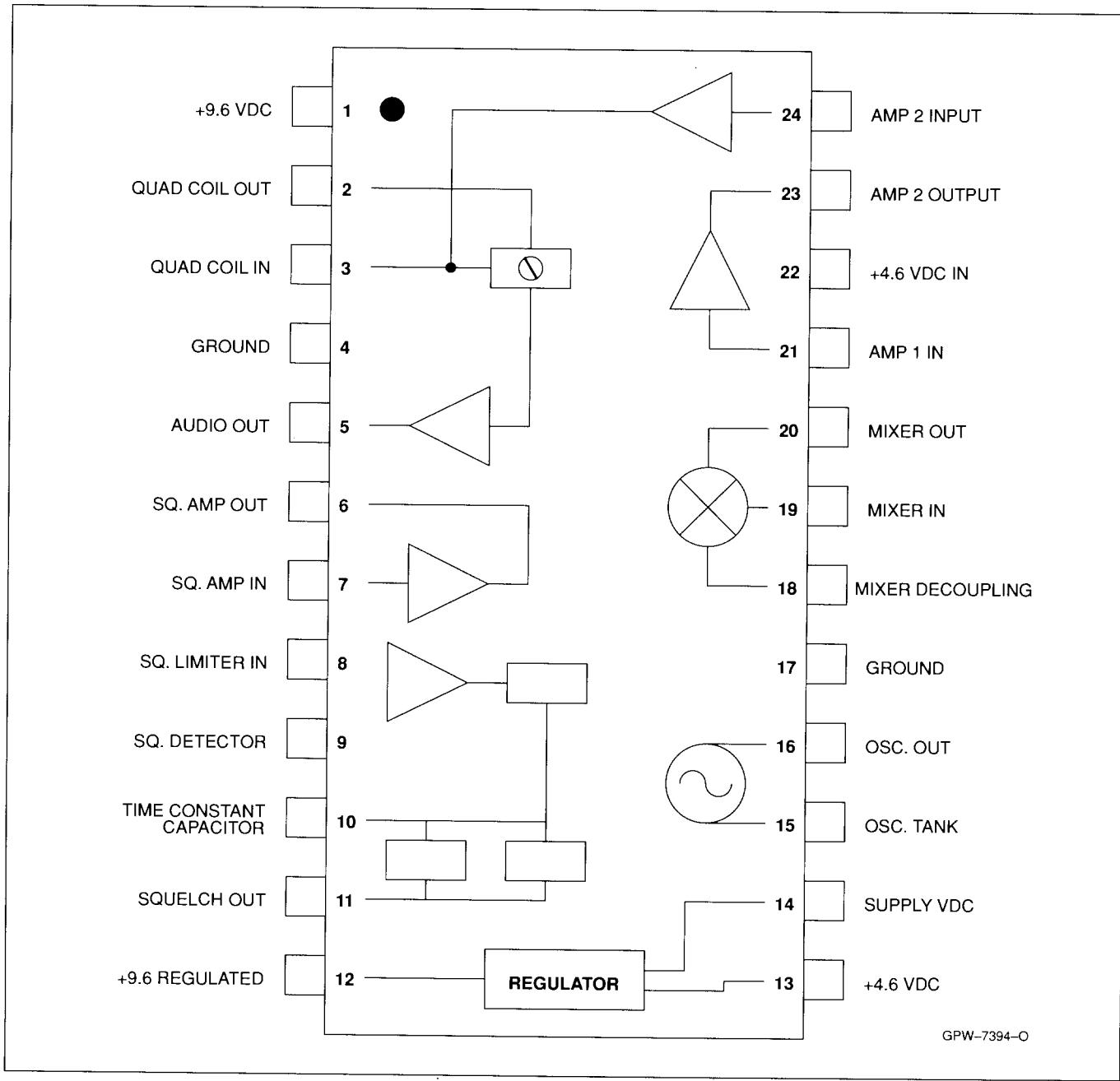


Figure 1. Receiver IC Block Diagram

The output of the filter is matched to the base of RF amplifier Q1. Q1 has a current source, Q2, to set a bias current of 16 mA regardless of DC Beta variations of Q1. The Q1 emitter resistors are used to provide voltage feedback to limit Q1's gain to about 14 dB. CR2, located on Q1's input, is a protective diode that ensures Q1 is protected from high level RF signals.

The output of Q1 is applied to a 3 pole filter centered at about 160 MHz. The first 4 pole filter, RF amplifier and the 3 pole filter provide image spur rejection.

The quad diode mixer, CR1, is a passive double balanced mixer. The output of the mixer goes to the diplexer circuit

which allows the mixer to be matched to the First IF amplifier, Q51, at the IF frequency of 45.1 MHz.

Q51 amplifies the IF signal by approximately 20 dB. The output of Q51 is filtered by matched ceramic filters Y51A and Y51B. The first IF is then

amplified by Q52 by approximately 18 dB and sent to the receiver subsystem IC U51-19 (see Figure 1).

The 45.1 MHz first IF signal is applied to the second mixer section of U51. A 44.645 MHz crystal oscillator provides the low side injection signal for the second mixer via U51-19. The second mixer takes the 45.1 MHz and the 44.645 MHz and produces a 455 kHz second IF signal. The second IF

filtering is achieved by using multiple resonators, FL51 and FL52. These filters are tuned to 455kHz.

The audio detector is internal to the U51 IC. The Quadrature detector detects the audio and rounts it to the PL filter and to the carrier squelch amplifier. The carrier squelch amplifies the detected audio and rounts it via U51-8 to the squelch control R60. The squelch control output is routed through a high pass filter to remove the receive audio components. The remaining noise above the audio band is detected via U51-6 by the carrier squelch detector which generates a D.C. voltage that controls the audio mute circuits. The detected audio is then sent over to the logic board via U51-5/J6-3.

1.4 UHF RECEIVER

The receiver signal is applied to the radio's antenna input and routed through the harmonic filter and antenna switch, which are located on the PA deck. The output is then routed via coax to J4 on the RF board.

The incoming signal at J4 passes through a 3 pole bandpass filter. A stage of RF amplification, Q1, amplifies the signal which passes to a 4 pole bandpass filter. The filtered signal then passes to the first mixer stage, CR1. The voltage controlled oscillator output is fed to the first mixer as a low side local oscillator. The resultant signal of 45.1 MHz is then amplified by the first IF amplifier Q51. Then amplified 45.1 MHz IF signal then passes through a 4 pole crystal filter consisting of Y51A and Y51B. Another stage of amplification, Q52, occurs before the RF signal passes into the receiver subsystem IC, U51 (see Figure 1).

The 45.1 MHz first IF signal is applied to the second mixer section of U51. A 44.645 MHz crystal oscillator provides the low side injection signal for the second mixer via U51-19. Y52 is a 44.645 MHz crystal which feeds the oscillator via U51-15. The second mixer takes the 45.1 MHz and the 44.645 MHz signal and produces a 455kHz second IF signal. The second IF filtering is achieved by using multiple resonators, FL51 and FL52. These filters are tuned to 455kHz.

The audio detector is internal to the U51 IC. The quadrature detector detects the audio and rounts it to the PL filter and to the carrier squelch amplifier. The carrier squelch amplifies the detected audio and rounts it via U51-8 to the squelch control R60. The squelch control output is routed through a high pass filter to remove the receive audio components. The remaining noise above the audio band is detected via U51-6 by the carrier squelch detector which generates a D.C. voltage that controls the audio mute circuits. The detected audio is then sent over to the logic board via U51-5/J6-3.

1.5 800 MHz RECEIVER

The received signal is applied to the radio's antenna input and routed through the harmonic filter and antenna switch, which are located on the PA deck. The output is then routed via coax to J4 on the RF board.

The incoming signal passes through a bandpass filter, FL1 and then through one stage of RF amplification, Q1. The amplified output of Q1 is then sent through another section of filtering, FL2.

The filtered signal then passes to the first mixer, U1. The voltage controlled oscillator output is fed into the mixer and the resultant 45.1 MHz IF signal is then sent to the first IF amplifier, Q51. The amplified 45.1 MHz signal then passes through a 4 pole crystal filter consisting of Y51A and Y51B. Another stage of amplification, Q52, occurs before the signal passes into the receiver subsystem IC, U51 (see Figure 1).

The 45.1 MHZ first IF signal is applied to the second mixer section of U51. A 44.645 MHz crystal oscillator provides the low side injection signal for the second mixer via U51-19. Y52 is a 44.645 MHz crystal which feeds the oscillator via U51-15. The second mixer takes the 45.1 MHz and the 44.645 MHz signals produces a 455 kHz second IF signal. The second IF filtering is achieved by using multiple resonators, FL51 and FL52. These filters are tuned to 455kHz.

The audio detector is internal to the U51 IC. The quadrature detector detects the audio and rounts it to the PL filter and to the carrier squelch amplifier. The carrier squelch amplifier amplifies the detected audio and rounts it via U51-8 to the squelch control R60. The squelch control output is routed through a high pass filter to remove the receive audio components. The remaining noise above the audio band is detected via U51-6 by the carrier squelch detector which generates a D.C. voltage that controls the audio mute circuits. The detected audio is then sent over to the logic board via U51-5/J6-3.

1.6 SYNTHESIZER OPERATION

Before frequency synthesis can begin the microprocessor must load frequency divider information into the PLL IC U101 (see Figure 2). The PLL IC contains 3 programmable dividers. The program is serially loaded via a common data line U101-10. The data is loaded one bit at a time, with each low-to-high transition of the CLOCK at U101-11 latching data from shift registers into the reference divider (R), divide-by-N, or divide-by-A latches depending on the control bit. A logic of the control bit selects the reference counter latch, while a logic low selects the divide-by-N, or divide-by-A counter latch.

After the microprocessor loads data into the PLL IC, SYNTH LATCH ENABLE line goes low. The synthesizer is then ready to generate a transmit or receive first injection frequency.

As an example for the 800MHz trunk models, the latches are loaded with data to give the following:

12.5 kHz at the output of the divided-by-R counter when the reference oscillator signal is applied at U101-1.

12.5 kHz at the output of the divided-by-N counter when the VCO is operating at the desired receive injection or transmit frequency.

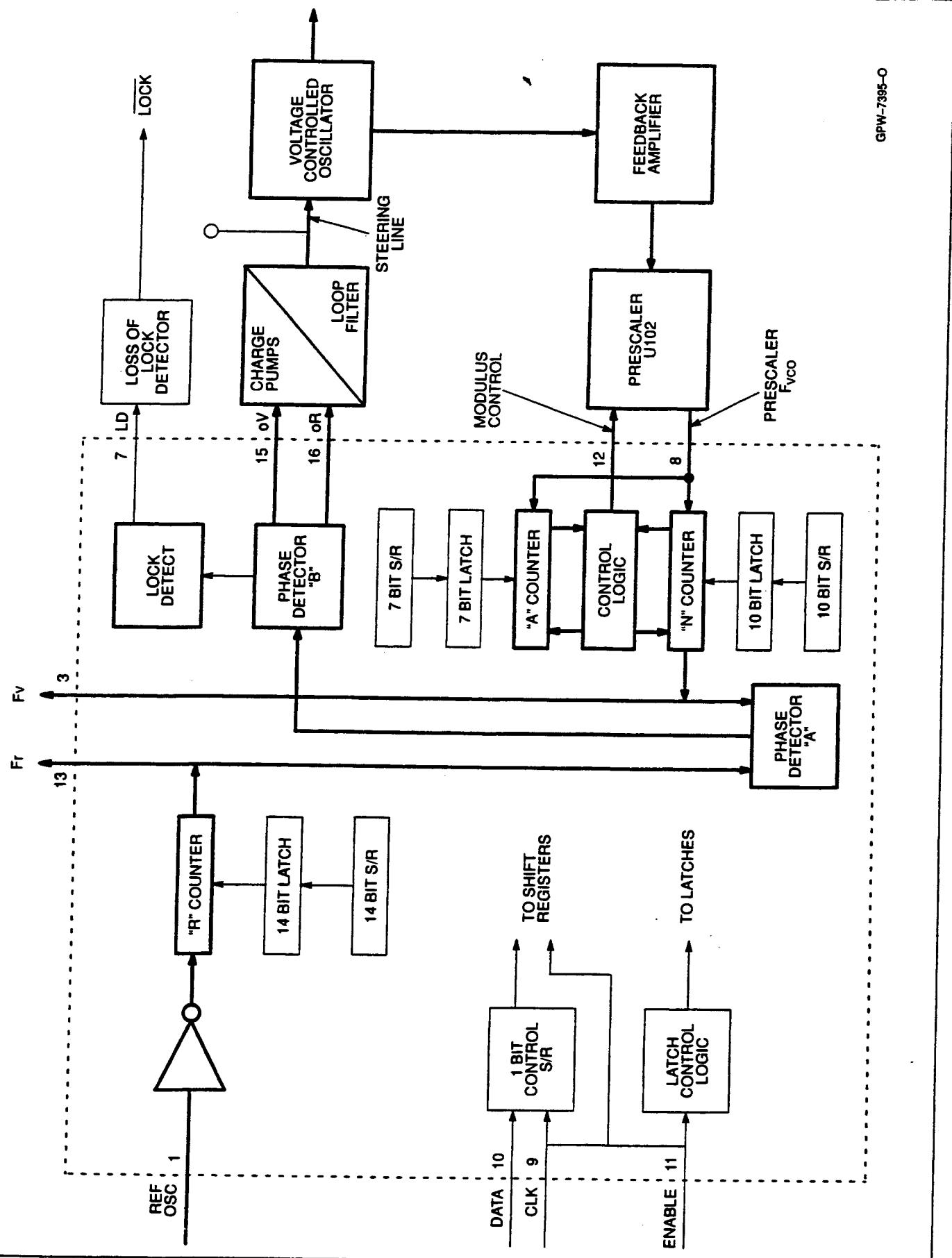


Figure 2. Synthesizer Section Block Diagram

During the frequency synthesis, the divide-by-A and divide-by-N counters begin counting down from the programmed values (A and N respectively) at the same time. The MOD CON line U101-12 is low so the divide-by-127/128 prescaler divides by 128. Therefore, the effect of the prescaler U102 is to divide the VCO output by 128 and apply it to U102-8. When the divide-by-A counter completes counting down, the control logic sets the MOD CON line high, and the divide-by-127/128 prescaler divides by 127 until the divide-by-N counter completes the programmed value on N. After the divide-by-N counter completes counting down, the counters are set back to their programmed values. The MOD CON line is set low and the counters begin counting down again. The effect of the prescaler and divide-by-A, divide-by-N counters is to divide the VCO frequency by a number, N, where:

$$N_T = 128 \times A + 127 \times (N - A) \\ = 127 \times N + A$$

The output of the divide-by-N counter is equal to:

$$\frac{f_{VCO}}{127 \times N + A}$$

where f_{VCO} is the output frequency of the VCO

When the phase-locked loop is locked:

$$\frac{f_{VCO}}{127 \times N + A} = 12.5 \text{ kHz} = \frac{f_{VCO}}{N_T}$$

The reference oscillator frequency is 14.4 MHz and the output of the divide-by-R must be 12.5 kHz. Therefore:

$$R = \frac{14.4 \text{ MHz}}{12.5 \text{ kHz}} = 115210 = 0100 1000 00002$$

The values of A and N are dependent on the desired VCO frequency and the VCO frequency is dependent of the transmit frequency or receive frequency as shown:

$$f_{VCO} = f_T \text{ or } (f_R - 45.1 \text{ MHz}) \\ \text{where } f_T = \text{the transmit frequency} \\ f_R = \text{the receive frequency}$$

The values of A and N can be determined from the desired frequency of the VCO, where:

$$N = \text{integer part of } \frac{N_T}{127}$$

$$A = \text{remainder of } \frac{N_T}{127}$$

For example, if the receive frequency is 851.0125 MHz
 $f_{VCO} = 851.0125 \text{ MHz} - 45.1 \text{ MHz} = 805.9125 \text{ MHz}$

$$\text{then } N_T = \frac{805.9125 \text{ MHz}}{12.5 \text{ MHz}}$$

$$\begin{array}{r} 510 \text{ INTEGER PART OF QUOTIENT} \\ 127 \overline{)64793} \\ 635 \\ \underline{129} \\ 127 \\ 23 \text{ REMAINDER} \end{array}$$

$$N = 510 = 010 1111 11102$$

$$A = 23 = 012 0111$$

The 12.5 kHz outputs of the divide-by-A and divide-by-N counters are applied to phase detector A. The output of phase detector A is applied to phase detector B. There are 2 output signals for phase detector B (phase R and phase V). Signals phase R (U101-16) and phase V (U101-15) consist of pulses with a pulse width that depends on the phase error for the two signals at phase detector A. If the frequency f_V is greater than f_R , then error information is provided by phase V pulsing low, while phase R remains essentially high. When f_V and f_R are both in phase, both phase V and phase R remain high, except for a small minimum time period, and they both pulse low in phase. These pulses are applied to the charge pump and are used to correct VCO frequency.

The *MaxTrac* VHF model uses a divide-by-64/65 prescaler, while the UHF and 800 MHz models use the divide-by-127/128 prescaler. The working principles for the LOWBAND, VHF, UHF and 800 MHz models are the same.

When the synthesizer is locked, U101-7 applies a high level signal with very narrow negative going pulses to the loss-of-lock detector. The very narrow negative going pulses have a high average DC level that is not sufficient to turn on transistor Q101. This keeps the voltage across C102 low which indicates a lock condition.

When the synthesizer is out of lock, the output of U101-7 becomes a pulsating DC signal with an average DC level that varies between 0.5V and 4.4V. This turns on Q101 and charges up C102 to at least 3.0V indicating a out-of-lock condition.

1.6.1 Charge Pump

The charge pump consists of Q102-Q105. The phase V (U101-15) signal from the PLL IC is applied to Q103 while phase R (U101-16) is applied to Q102. When the synthesizer is locked, both signals consist of a pulse train with a period of 80 uSec and negative going pulses. The phase R negative pulse turns off Q102 and brings the emitter of Q104 to 9.6V which turns on Q104. The negative pulse of phase V turns Q103 off which reduces the current flow to R114 and in turn reduces the voltage across R114. This will cause Q105 to turn on and sink current from Q104. When the synthesizer reaches lock, the voltage at the steering line test point (SL) will be between 1.3V to 7.8V. When the synthesizer is reprogrammed with a new frequency, the previous SL voltage would now give a wrong frequency and will cause the phase R and phase V to have differing pulse widths. This will result in a situation whereby Q104 and Q105 turn on and off at different times resulting in a series of summed current pulses to the loop filter that charges or discharges C110 producing the new SL voltage. If the frequency of the VCO is higher than that of phase R, then C110 discharges. The reverse happens when the frequency of the VCO is lower.

1.6.2 Loop Filter

The loop filter consists of R119 and R120, capacitors C109 through C111. This loop filter is a low pass filter that attenuates noise and rejects the loop reference frequency so that these signals cannot modulate the VCO. The voltage across C110 is the steering line voltage that controls the VCO frequency.

1.6.3 Reference Oscillator

The 14.4 MHz reference oscillator is supplied from a 14.4 MHz crystal Y151. This crystal has a 8 digit temperature coefficient that needs to be keyed into the radio during unified chassis auto tune. The reference oscillator is warped into the desired range at room temperature by adjusting L151 manually (new field adjustment). The oscillator is temperature compensated by varactors CR151 and CR152. A change in DC voltage at frequency control J6-9 changes the varactor capacitance and warps the frequency of the oscillator. It is very important that this control voltage be defined when tuning L151 i.e. 5.2V +0.01V DC at J6-9. During the 7 digit code generation this control voltage is changed between 4.9V DC to 5.5V DC and the transmit frequency noted. During auto-tuning of the unified chassis, the electronic warping of the reference oscillator is performed by changing this control voltage. During temperature compensation, the radio "reads" the temperature of Y151 by sensing the forward bias across CR176 and its translation via amplifier U176 to give temp sense voltage at J6-14.

The temp sense voltage is proportional to the actual temperature measured. The reference oscillator will be warped according to the temperature of the oscillator in order to correct the drift in frequency due to heating of the crystal Y151. Analysis of this temp sense circuit centers around the DC voltage measurements of the various nodes. All the resistors associated with this circuit have a 1% tolerance, therefore any component damage or part value change will affect the translated voltage at J6-14. The diode, CR176, needs to be flush to the board to ensure an accurate temp sensing. During transmissions with PL/DPL tones, the reference oscillator will be modulated. Potentiometer R164 controls the reference modulation level.

1.7 VOLTAGE CONTROLLED OSCILLATOR

MaxTrac models for LOWBAND, VHF, and UHF use two separate VCO's, one for transmit and one for receive. The *MaxTrac* 800 MHz radio uses one VCO for transmit and receive. Switching between the transmit and receive VCO's is accomplished by the use of a switching circuit consisting of transistors Q277, Q278, and Q279. Transistor Q276 provides the 8.5 volt source to these transistors to power the VCO's. During the transmit mode, J6-4, the Transmit/Receive Shift Line, is at .1V DC. This will cause Q277 and Q278 to turn on and switch 8.5 volts to the transmit VCO. Q279 is turned off and keeps the 8.5 volts from reaching the receive VCO. During the receive mode, the voltage on J6-4 goes to 9.6 volts. This turns Q277, Q278 off and Q279 on. The 8.5 volts is applied to receive VCO and the transmit VCO is shut off.

The transmit and receive VCO's are very similar in design. The transmit VCO has a modulation circuit added and will be discussed later. The steering line D.C. voltage from the synthesizer is applied to each VCO. L213 in the transmit VCO and L202 in the receive VCO are tuned for a steering line voltage of 7.8V DC at the high end of the band. Varactors CR210-213 in the transmit VCO and CR202-205 in the receive VCO are used to change the frequency of the VCO.

The steering line D.C. voltage is applied to the varactors whose capacitance changes as the voltage increases or decreases. The steering line voltage is checked for greater than 1.8 volts at the low end of the band. This is to ensure that the tuning range is made as large as possible by the synthesizer.

In the transmit mode, the modulating signal applied to J6-10 changes the varactor capacitance of CR209 and modulates the VCO. Resistors R222, R223, and R225 act as potential dividers and only a fraction of the modulating signal is seen by CR209. The resistor combination also helps by attenuating any stray unwanted signals.

Q206 in the transmit VCO and Q203 in the receive VCO are the FET oscillators.

Transistors Q207, Q208 in the transmit VCO and Q204, Q205 in the receive VCO are the buffer amplifiers. A sample of the VCO frequency is fed back to the synthesizer circuit from the base of Q208 (transmit) and Q205 (receive). This sample is necessary for the synthesizer to "know" if the VCO is at the required frequency. The output of Q208 goes to the PA deck to be amplified. The output of Q205 makes up the local oscillator and is fed to the first mixer CR1.

The UHF VCO has an added circuit where the VCO frequency can be shifted by changing the voltage at J6-12. At the lower range, transistor Q209 is turned on and switches 9.6 volts to pin diodes CR201 and CR208. This causes C226 (transmit) and C203 (receive) to be added to the VCO and shifts the frequency of the VCO.

In the 800 MHz radio, there is only one VCO and it is contained in module U201. The transmit frequency range is 806-825 MHz while the receive frequency range is 851-870 MHz. The receive local oscillator signal is extracted from Q202. The transmitter signal is also extracted from Q202 with an additional buffer Q203. During the receive mode, the VCO signal from transistor Q203 is attenuated by turning off Q204. An attenuated VCO output is still available at J5 during the receive mode and the receive injection frequency can be measured. In the 800 MHz talk around radio, there is a similar pin diode shift circuitry like that used in the UHF radios to shift the VCO frequency to the 851-870 MHz range.

2. Troubleshooting Guide

2.1 RECEIVER SECTION

The theory of operation and schematics along with the troubleshooting chart "RECEIVER" will aid the servicer in isolating to the faulty component.

The use of proper test equipment such as the R2021D or R2001D with TEK-10 probe will also help in making accurate comparison measurements.

Refer to the proper schematic for each band for the voltages and waveforms. Observe the notes for information on how to set up for the measurements. When using the TEK-10 probe, be sure of a good RF ground before assuming the reading is correct.

Although many of the components are located on the solder side, the schematics can be used to isolate before having to pull the board from the chassis.

2.2 SYNTHESIZER SECTION

The synthesizer uses a phase locked loop design. Before troubleshooting this section the servicer may wish to review the theory of operation before continuing.

The synthesizer can be checked for an "out-of-lock" condition by looking at the lock detect line at J6-5. When in lock, the voltage will be 0V DC and when out of lock, the line will typically be 3V DC.

Be sure the DC voltages to the synthesizer are correct before proceeding. Troubleshoot the voltage regulators if wrong voltage levels are recorded.

Next, check Fr which is pin 13 of the synthesizer. Depending on the model of radio, a frequency of either 12.5 kHz, 6.25 kHz, or 5 kHz will be seen. This proves that the reference oscillator's output and the programming of the synthesizer are good.

If Fr is bad, check to see that the reference oscillator's output is on frequency and at the proper level. If the reference oscillator is off frequency, use the Radio Service software to try and warp the oscillator frequency on. Do not attempt to warp L151 on the RF board. This coil is factory adjusted and should not be field adjusted.

If the frequency will not warp on, check to make sure the DC voltages around the reference oscillator are correct. Board replacement will have to be done if the fault does not clear after programming.

The use of an open loop test will help to isolate between the synthesizer and VCO. By using a variable DC supply and breaking the steering line voltage away from the VCO, you can insert a DC voltage and observe the VCO's output. If the VCO tracks with the external DC voltage, the problem is in the synthesizer and prior to the steering line.

Tracing the signal through the feedback amplifier, it is important to pay close attention to the signal levels. Refer to the schematics for proper signal level for each band.

At the prescaler, the frequency can be calculated by dividing Fvco by 128 for 800 and UHF. Dividing by 64 is for the VHF model. Check the Modulus Control line on pin 6 of the prescaler. There should be a pulse train at the loop rate (12.5, 6.25, 5 kHz). If this is not present, then either the prescaler is loading down the signal or the synthesizer is bad.

Finally, check Fv. This should be a pulse train at the reference rate. It should be in lock with Fr. If there is no pulse train but you have a good signal from the prescaler, then the synthesizers internal dividers are bad.

If Fv is okay then check the outputs to the Charge Pumps. The ground pulse will be at the reference rate. When Fv leads Fr, the pulse from pin 15 will have an increased pulse width. If Fr leads Fv, then the pulse out pin 16 will have an increased pulse width.

If the DC power supply is still connected on the steering line, disconnect it. Reattach the steering line circuitry and attach a DC DVM to the steering line test point. While monitoring the DVM, momentarily touch the base of Q103. The steering line voltage should drop to almost 0V DC. Next, ground the base of Q102. The DVM should increase to almost +9.6V DC. If either of these checks do not work, troubleshoot that particular side of the pumps.

Finally, if everything in the Phase Locked Loop appears to be normal, except for lock detect J6-5, check out the Lock Detect circuit. Synthesizer pin 7 should be very narrow ground pulses when in lock and the pulse width will be random when out of lock.

3. Extender Field Test

The purpose of this test is to give field technicians the ability to verify extender functionality without using a pulse generator box (such as the TEK-47A or TEK-21). This test does not take the place of factory testing of the extender.

3.1 TEST EQUIPMENT

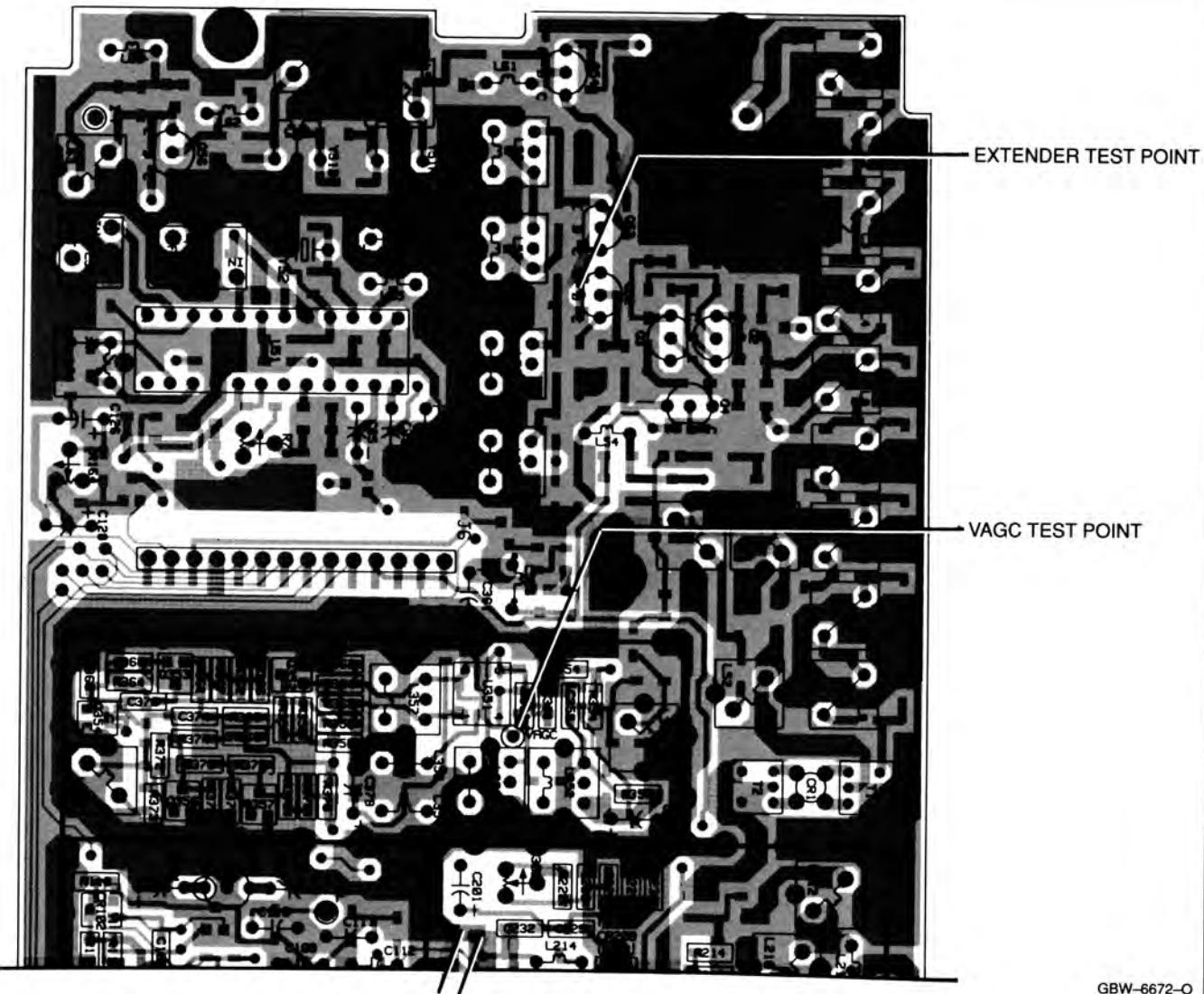
R2001D Motorola Communication System Analyzer or Equivalent.

3.2 TEST PROCEDURE

- (1) Ensure that the radio is turned off; then connect the RF generator output to the antenna port of the radio. Tune the RF generator to the receive (RX) frequency of the radio mode to be tested.
- (2) Adjust the RF output level from the R2001D to -47 dBm (1 millivolt).
- (3) Modulate the RF signal with 100% AM modulation at a frequency of 10 kHz. Use either tone A or B modulation from R2001D with AM limit (RF Section) set to Minimum.
- (4) Locate the VAGC Test Point (see Figure 3) in the extender section of the RF board. Short the test point pad to ground using a small piece of wire soldered from the pad to the coil can (L352/L353) nearby.
- (5) Turn the radio on. The extender is in the "ON" state when the radio is turned on.
- (6) Observe the Extender Test Point (see Figure 3) with a 10:1 oscilloscope probe. Pulses at the repetition rate of 10 kHz should be seen.
- (7) Turn the extender off by depressing the monitor button on the control head for 3 to 4 seconds; listen for the three low-pitched tones. There should be no pulses at the test point. Turn the extender on again by depressing the monitor button on the control head for 3 to 4 seconds; listen for three high-pitched "beeps." The pulses should be seen at the test point.
- (8) Turn the radio off and remove the wire used in Step 4. This concludes the extender functionality test.

Note

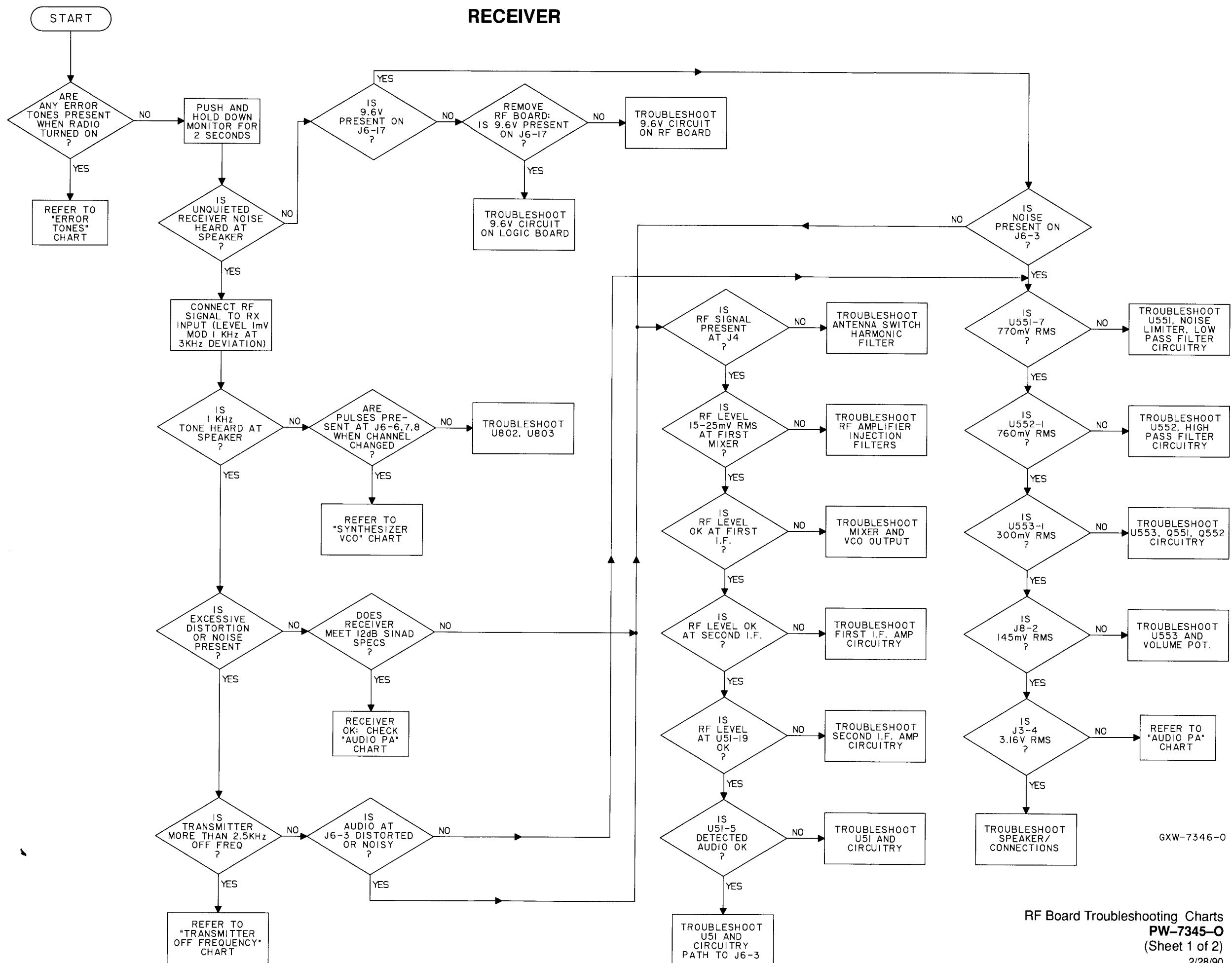
If the Extender does not function as described above, replace the RF board.



GBW-6672-O

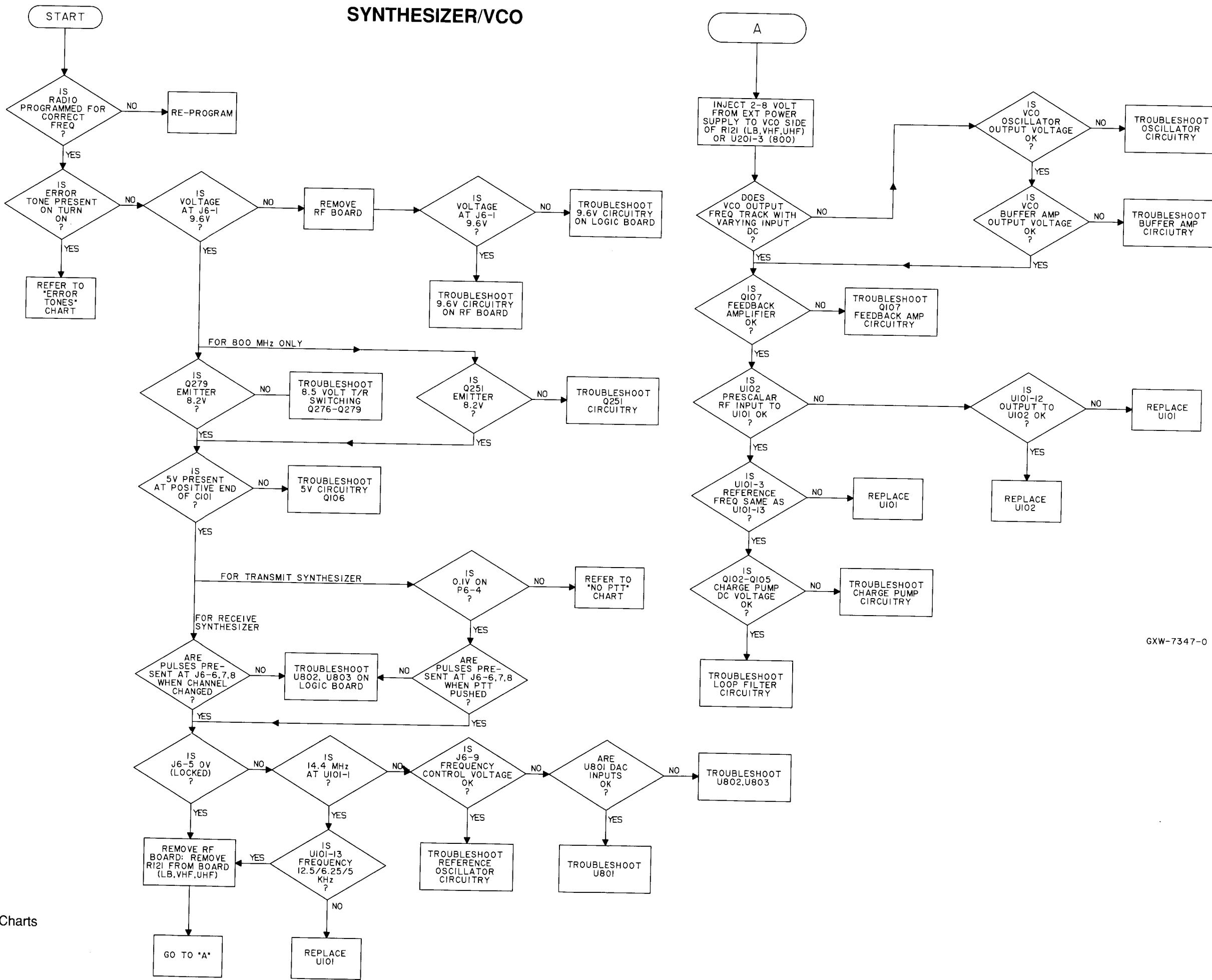
Figure 3. Extender Test Points

RECEIVER

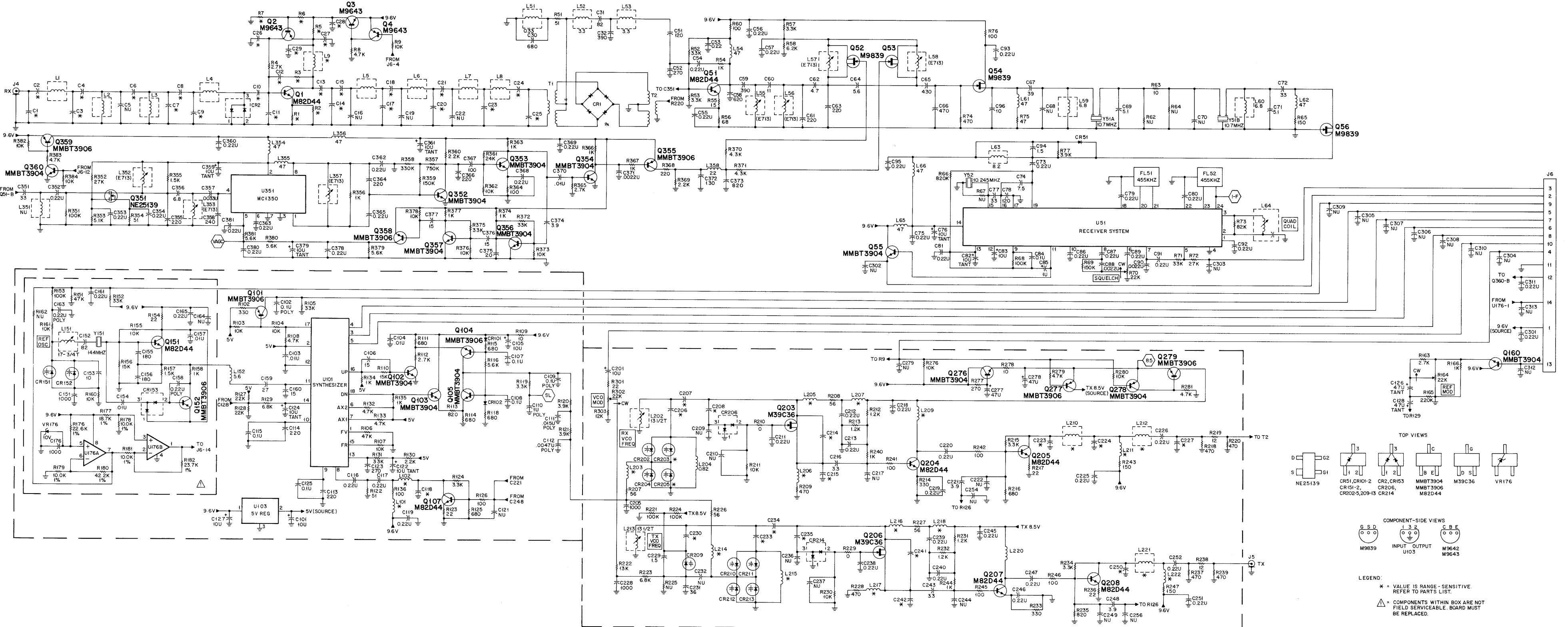


GXW-7346-0

SYNTHESIZER/VCO



GXW-7347-0



Range 1 Parts List

HLB4099A RF Board, 29.7–36 MHz			MXW-6563-B	MXW-6563-B (2)	MXW-6563-B (3)	MXW-6563-B (4)	MXW-6563-B (5)					
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION	REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION	REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION	REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION	
capacitor, chip, pF, ±5%, 50V (unless otherwise indicated)			C208	21-13740B17	4.7, ±25 pF	L216-218	24-80063M24	8.2 uH	R155	06-11077A98	10k	
C1	21-13740B55	180	C211-213	21-11032B15	0.22 uF, +80–20%	L220	24-80063M24	8.2 uH	R156	06-11077B03	15k	
C2	21-11032B15	0.22 uF, +80–20%	C214,215	21-13740B43	56	L221	24-80063M11	0.68 uH	R157	06-11077A78	1.5k	
C3	21-13740B66	510	C216	21-13740B13	3.3, ±25 pF	L222	24-80063M24	8.2 uH	R158	—	not used	
C4	21-13740B57	220	C218-220	21-11032B15	0.22 uF, +80–20%	L352,353	24-80164M01	tunable, 0.7 uH	R160,161	06-11077A98	10k	
C6	21-13740B38	36	C221	21-13740B15	3.9, ±25 pF	L354-356	24-80063M31	47 uH	R163	06-11077A84	2.7k	
C7	21-13740B19	5.6, ±25 pF	C223	21-13740B25	10, ±5 pF	L357	24-80164M01	tunable, 0.7 uH	R164	18-05500L08	variable, 22k	
C8	21-13740B55	180	C224	21-13740B41	47	L358	24-80063M27	22 uH	R165	06-11077B31	220k	
C9	21-13740B68	620	C225,226	21-11032B15	0.22 uF, +80–20%	transistor (see note)			R166	06-11077A74	1k	
C10	21-11032B15	0.22 uF, +80–20%	C227	21-13740B41	47	Q1	48-80182D44	NPN	R176	06-11077G26	22.6k, ±1%	
C11	21-13740B55	180	C228	21-13740B73	1000	Q2-4	48-11043C06	PNP	crystal (see note)	48-80140L15	zener, 10V	
C12,13	21-11032B15	0.22 uF, +80–20%	C229	21-13740B05	1.5, ±25 pF	Q51	48-80182D44	NPN	Y51	91-80172D01	filter, 10.7 MHz	
C14	—	not used	C230	21-13740B19	5.6, ±25 pF	Q52-54	48-11043C12	FET	Y52	48-80908W01	10.245 MHz	
C15	21-13740B46	75	C231	21-13740B38	36	Q55	48-80214G02	NPN	Y151	48-80174D05	14.4 MHz	
C17	21-13740B66	510	C233	21-13740B63	390	Q56	48-11043C12	FET	non-referenced items			
C18	21-13740B61	330	C234	21-13740B49	100	Q101	48-05128M16	PNP	14-05160A01	insulator, crystal (4 used)		
C19	—	not used	C235	21-13740B17	4.7, ±25 pF	Q102,103	48-80214G02	NPN	26-80097M01	shield, coil can (L151)		
C20	21-13740B71	820	C238-240	21-11032B15	0.22 uF, +80–20%	Q104	48-05128M16	PNP	26-80098M01	shield, coil can (10 used)		
C21	21-13740B60	300	C241,242	21-13740B47	82	Q105	48-80214G02	NPN	26-80228L01	shield, can (J4, J5)		
C23	21-13740B69	680	C243	21-13740B13	3.3, ±25 pF	Q107	48-80182D44	NPN	26-80916V01	shield, VCO frame		
C24	21-13740B73	1000	C245-247	21-11032B15	0.22 uF, +80–20%	Q151	48-80182D44	NPN	75-05295B02	pad, crystal (4 used)		
C25	21-13740B61	330	C250	21-13740B29	15	Q152	—	not used	10/15/89			
C26-29	21-11032B15	0.22 uF, +80–20%	C251,252	21-11032B15	0.22 uF, +80–20%	Q160	48-80214G02	NPN	note: For best performance, order diodes, transistors, and integrated circuit devices by Motorola part number.			
C30	21-13740B69	680	C277,278	23-11048B19	47 uF, ±20%, 16V	Q203	48-80141L06	FET				
C31	21-13740B48	91	C301	21-11032B15	0.22 uF, +80–20%	Q204,205	48-80182D44	NPN				
C32	21-13740B63	390	C311	21-11032B15	0.22 uF, +80–20%	Q206	48-80141L06	FET				
C33	—	not used	C351	21-13740B37	33	Q207,208	48-80182D44	NPN				
C51	21-13740B52	130	C352-354	21-11032B15	0.22 uF, +80–20%	Q276	48-80214G02	NPN				
C52	21-13740B59	270	C355	21-13740B57	220	Q277-279	48-05128M16	PNP				
C53-57	21-11032B15	0.22 uF, +80–20%	C356	21-13740B21	6.8, ±5 pF	Q351	48-80390W01	dual gate FET				
C58	21-13740B68	620	C357	21-13741B33	0.0033 uF, ±10%	Q352-354	48-80214G02	NPN				
C59	21-13740B63	390	C358	21-13740B58	240	Q355	48-05128M16	PNP				
C60	21-13740B26	11	C359	23-11013D13	10 uF, ±10%, 20V, tantalum	Q356,357	48-80214G02	NPN				
C61	21-13740B57	220	C360	21-11032B15	0.22 uF, +80–20%	Q358,359	48-05128M16	PNP				
C62	21-13740B17	4.7, ±25 pF	C361	23-11013D13	10 uF, ±10%, 20V, tantalum	Q360	48-80214G02	NPN				
C63	21-13740B57	220	C362,363	21-11032B15	0.22 uF, +80–20%	resistor, chip, ohm, ±5%, 1/8 watt (unless otherwise indicated)						
C64	21-13740B19	5.6, ±25 pF	C364	21-13740B57	220	R1	06-11077A26	10	R234	06-11077A86	3.3k	
C65	21-13740B64	430	C365	21-11032B15	0.22 uF, +80–20%	R2	06-11077A30	15	R235	06-11077A72	820	
C66	21-13740B65	470	C366	21-13740B57	220	R3	06-11077A68	560	R236	06-11077A34	22	
C67	21-13740B39	39	C367	21-13740B49	100	R4	06-11077A84	2.7k	R237	06-11077A61	300	
C69	21-13740B18	5.1, ±25 pF	C368,369	21-11032B15	0.22 uF, +80–20%	R5	06-11077A56	180	R238	06-11077A32	18	
C71	21-13740B18	5.1, ±25 pF	C370	21-13741B37	0.0047 uF, ±10%	R6	06-11077A98	10k	R239	06-11077A61	300	
C72	21-13740B37	33	C371	21-13741B29	0.0022 uF, ±10%	R7	06-11077A94	6.8k	R240	06-11077A74	1k	
C73	21-11032B15	0.22 uF, +80–20%	C372	21-13740B52	130	R8	06-11077A90	4.7k	R241,242	06-11077A50	100	
C74	21-13740B22	7.5, ±5 pF	C373	21-13740B72	910	R9	06-11077A98	10k	R243	06-11077A54	150	
C75	21-11032B15	0.22 uF, +80–20%	C374	21-13740B25	10	R51	06-11077A43	51	R244	06-11077A74	1k	
C76	23-11013D13	10 uF, ±10%, 20V, tantalum	C376,377	21-13740B29	15	R52,53	06-11077A86	3.3k	R245,246	06-11077A50	100	
C77	21-13740B37	33	C378	21-11032B15	0.22 uF, +80–20%	R54	06-11077A74	1k	R247	06-11077A54	150	
C78	21-13740B51	120	C379	23-11013D13	10 uF, ±10%, 20V, tantalum	R55	06-11077A30	15	R276	06-11077A98	10k	
C79-81	21-11032B15	0.22 uF, +80–20%	C380,381	21-11032B15	0.22 uF, +80–20%	R56	06-11077A46	68	R277	06-11077A60	270	
C82	23-11013D13	10 uF, ±10%, 20V, tantalum	diode (see note)	CR1	48-80236E16	quad Schottky, crossed	R57	06-11077A86	3.3k	R278	06-11077A26	10
C83	23-11048B13	10 uF, ±20%, 16V, electrolytic	CR2	48-80154K03	dual Schottky, SOT	R58	06-11077A93	6.2k	R279	06-11077A90	4.7k	
C84	21-11032B13	0.1 uF, +80–20%	CR51	48-05129M76	silicon, SOT	R60	06-11077A50	1				

Range 3 Parts List

HLB4101A RF Board, 42-50 MHz

MXW-6348-B

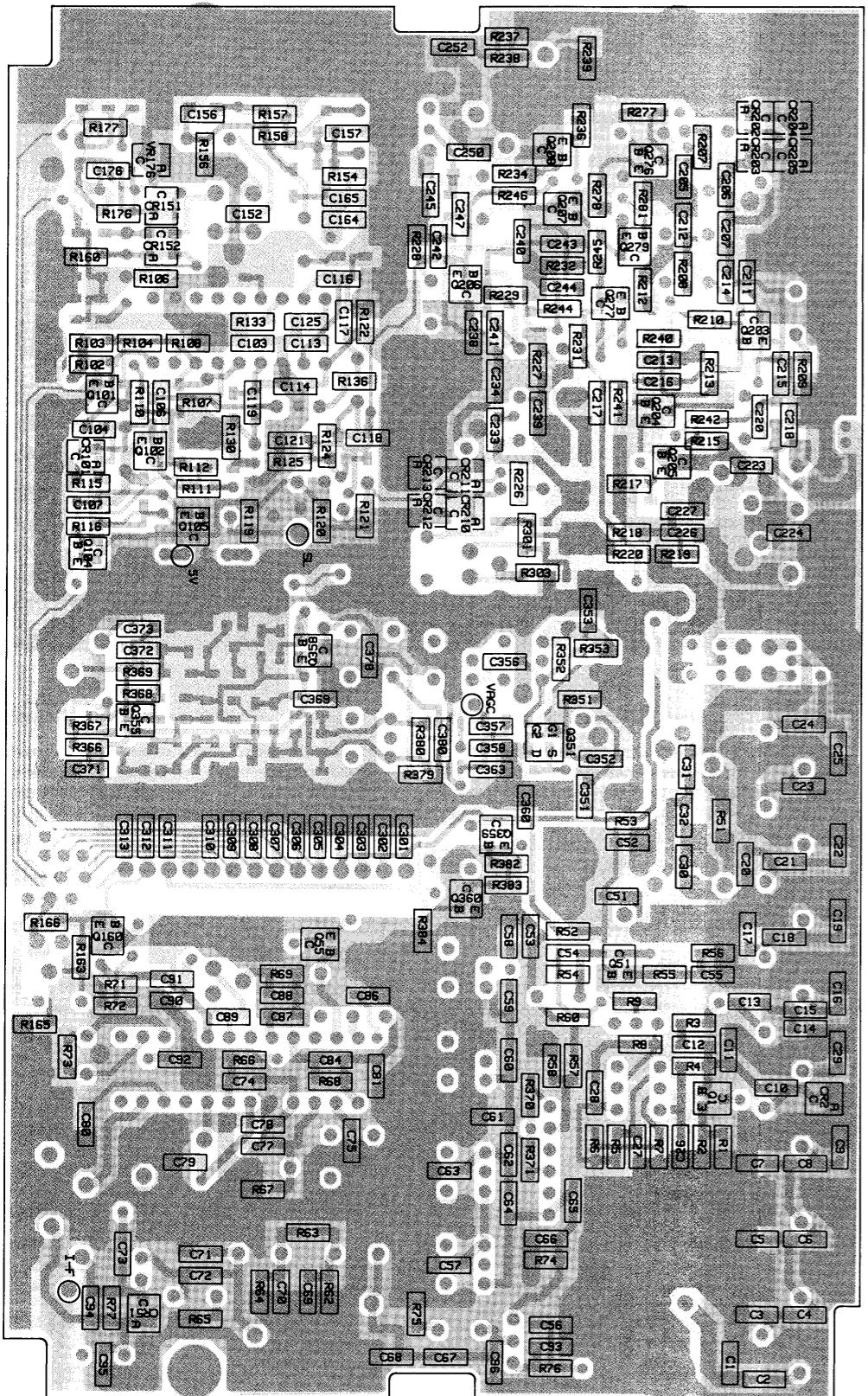
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, chip, pF, ±5%, 50V (unless otherwise indicated)		
C1	21-13740B48	91
C2	21-13740B65	470
C3	21-13740B59	270
C4	21-13740B49	100
C6	21-13740B29	15
C8	21-13740B48	91
C9	21-13740B64	430
C10	21-13740B57	220
C11	21-13740B55	180
C12	21-13741B49	0.015 uF, ±10%
C13	21-13740B51	120
C14	21-13740B62	360
C15	21-13740B51	120
C17	21-13740B67	560
C18	21-13740B52	130
C20	21-13740B67	560
C21	21-13740B52	130
C23	21-13740B64	430
C24	21-13740B58	240
C25	21-13740B56	200
C26-29	21-13741B49	0.015 uF, ±10%
C30	21-13740B69	680
C31	21-13740B47	82
C32	21-13740B63	390
C51	21-13740B51	120
C52	21-13740B59	270
C53-57	21-11032B15	0.22 uF, +80-20%
C58	21-13740B68	620
C59	21-13740B63	390
C60	21-13740B26	11
C61	21-13740B57	220
C62	21-13740B17	4.7, ±25 pF
C63	21-13740B57	220
C64	21-13740B19	5.6, ±25 pF
C65	21-13740B64	430
C66	21-13740B65	470
C67	21-13740B39	39
C69	21-13740B18	5.1, ±25 pF
C71	21-13740B18	5.1, ±25 pF
C72	21-13740B37	33
C73	21-11032B15	0.22 uF, +80-20%
C74	21-13740B22	7.5, ±5 pF
C75	21-11032B15	0.22 uF, +80-20%
C76	23-11013D13	10 uF, ±10%, 20V, tantalum
C77	21-13740B37	33
C78	21-13740B51	120
C79-81	21-11032B15	0.22 uF, +80-20%
C82	23-11013D13	10 uF, ±10%, 20V, tantalum
C83	23-11048B13	10 uF, ±20%, 16V, electrolytic
C84	21-11032B13	0.1 uF, +80-20%
C85	23-11048B05	1 uF, ±20%, electrolytic
C86,87	21-11032B15	0.22 uF, +80-20%
C88	21-13741B29	0.0022 uF, ±10%
C89	21-11032B15	0.22 uF, +80-20%
C90	21-13741B29	0.0022 uF, ±10%
C91-93	21-11032B15	0.22 uF, +80-20%
C94	21-13740B05	1.5, ±25 pF
C95	21-11032B15	0.22 uF, +80-20%
C96	21-13740B25	10, ±5 pF
C101	23-11048B13	10 uF, ±20%, 16V, electrolytic
C102	08-11051A13	0.1 uF, 63V
C103,104	21-13741B45	0.01 uF, ±10%
C105	23-11048B13	10 uF, ±20%, 16V, electrolytic
C106	21-13740B29	15
C107,108	21-11032B13	0.1 uF, +80-20%
C109	08-11051A13	0.1 uF, 63V
C110	08-11044A33	1 uF
C111	08-11051A08	0.015 uF, 63V
C112	08-11051A05	0.0047 uF, 63V
C113,114	21-13740B57	220
C115	21-11032B13	0.1 uF, +80-20%
C116,117	21-11032B15	0.22 uF, +80-20%
C118	21-13740B27	12
C119	21-11032B15	0.22 uF, +80-20%
C122	23-11013D13	10 uF, ±10%, 20V, tantalum
C123	21-13740B59	270
C124	23-11013D13	10 uF, ±10%, 20V, tantalum
C125	21-11032B13	0.1 uF, +80-20%
C126	23-11013A56	47 uF, ±20%, 6V, tantalum
C127	23-11048B13	10 uF, ±20%, 16V, electrolytic
C128	23-11013A56	47 uF, ±20%, 6V, tantalum
C151	21-13740B73	1000
C152	21-13740B47	82
C153	21-13740B25	10, ±5 pF
C154	21-13741B45	0.01 uF, ±10%
C155,156	21-13740B55	180
C157	21-13741B45	0.01 uF, ±10%
C158	08-11051A15	0.22 uF, 63V
C159	21-13740B35	27
C160	21-13740B29	15
C161	21-11032B15	0.22 uF, +80-20%
C163	08-11051A15	0.22 uF, 63V
C165	21-11032B15	0.22 uF, +80-20%
C176	21-13740B73	1000
C201	23-11048B13	10 uF, ±20%, 16V, electrolytic
C205	21-13740B73	1000
C206	21-13740B37	33
C207	21-13740B27	12
C208	21-13740B17	4.7, ±25 pF
C211-213	21-11032B15	0.22 uF, +80-20%

Schematic, Circuit Board Diagrams, and
Parts Lists for HLB4099A and HLB4101A
Low Band RF Boards
PW-6346-C
(Sheet 3 of 4)
3/31/90

MXW-6348-B

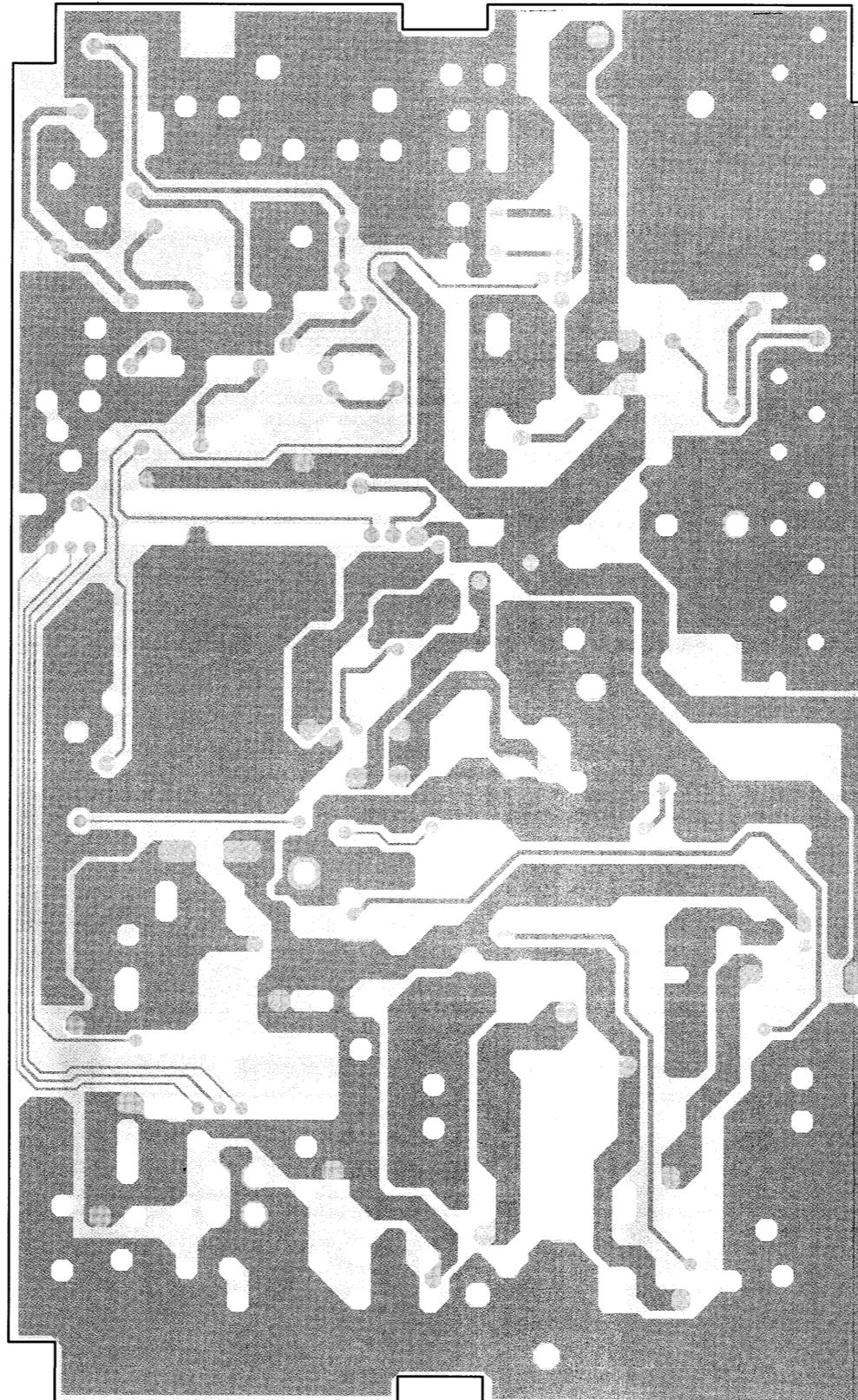
MXW-6348-B (2)

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
transistors (see note)		
Q1	48-80182D44	NPN
Q2-4	48-11043C06	PNP
Q51	48-80182D44	NPN
Q52-54	48-11043C12	FET
Q55	48-80214G02	NPN
Q56	48-11043C12	FET
Q101	48-05128M16	NPN
Q102,103	48-80214G02	NPN
Q104	48-05128M16	NPN
Q105	48-80214G02	NPN
Q107	48-08182D44	NPN
Q151	48-08182D44	NPN
Q152	48-05128M16	NPN
Q160	48-80214G02	NPN
Q203	48-80141L06	FET
Q204,205	48-80182D44	NPN
Q206	48-08141L06	FET
Q207,208	48-08182D44	NPN
Q276	48-80214G02	NPN
Q277-279	48-05128M16	NPN
Q351	48-80930W01	dual gate FET
Q352-354	48-80214G02	NPN
Q355	48-05128M16	NPN
Q356,357	48-80214G02	NPN
Q357	48-13741B33	0.0033 uF, ±10%
Q358	21-13740B58	240
Q359	23-11013D13	10 uF, ±10%, 20V, tantalum
Q360	21-11032B15	0.22 uF, +80-20%
Q361	23-11013D13	10 uF, ±10%, 20V, tantalum
Q362,363	21-11032B15	0.22 uF, +80-20%
Q364	21-13740B57	220
Q365	21-11032B15	0.22 uF, +80-20%
Q366	21-13740B57	220
Q367	21-13740B49	100
Q368,369	21-11032B15	0.22 uF, +80-20%
Q370	21-13741B37	0.0047 uF, ±10%
Q371	21-13741B29	0.0022 uF, ±10%
Q372	21-13740B52	130
Q373	21-13740B72	910
Q374	21-13740B25	10
Q376,377	21-13740B29	15
Q378	21-11032B15	0.22 uF, +80-20%
Q379	23-11013D13	10 uF, ±10%, 20V, tantalum
Q380,381	21-11032B15	0.22 uF, +80-20%
diodes (see note)		
CR1	48-80236E16	quad Schottky, crossed
CR2	48-80154K03	dual Schottky, SOT
CR51	48-05129M76	silicon, SOT
CR101,102	48-05129M76	silicon, SOT
CR151,152	48-80006E10	silicon varactor, SOT
CR202-205	48-80006E10	silicon varactor, SOT
CR206	48-80154K03	dual Schottky, SOT
CR209-213	48-80006E10	silicon varactor, SOT
CR214	48-80154K03	dual Schottky, SOT
filters		
FL51	91-80097D05	455 kHz, 6E
FL52	91-80098D05	455 kHz, 4E
connectors, receptacle		
J4	09-80135M01	coaxial (RX)
J5	09-80135M01	coaxial (TX)
J6	09-80130M02	14-pin socket (logic board)
coils		
L1-9	24-80148M22	9-1/2 turns (white)
L51	24-80063M07	0.33 uH
L52,53	24-80063M19	3.3 uH
L54	24-80063M31	47 uH
L55-58	24-80164M01	tunable, 0.7 uH
L59,60	24-80063M23	6.8 uH
L61,62	24-80063M31	47 uH
L63	24-80063M24	8.2 uH
L64	25-80000E01	tunable, 455 kHz
L6		



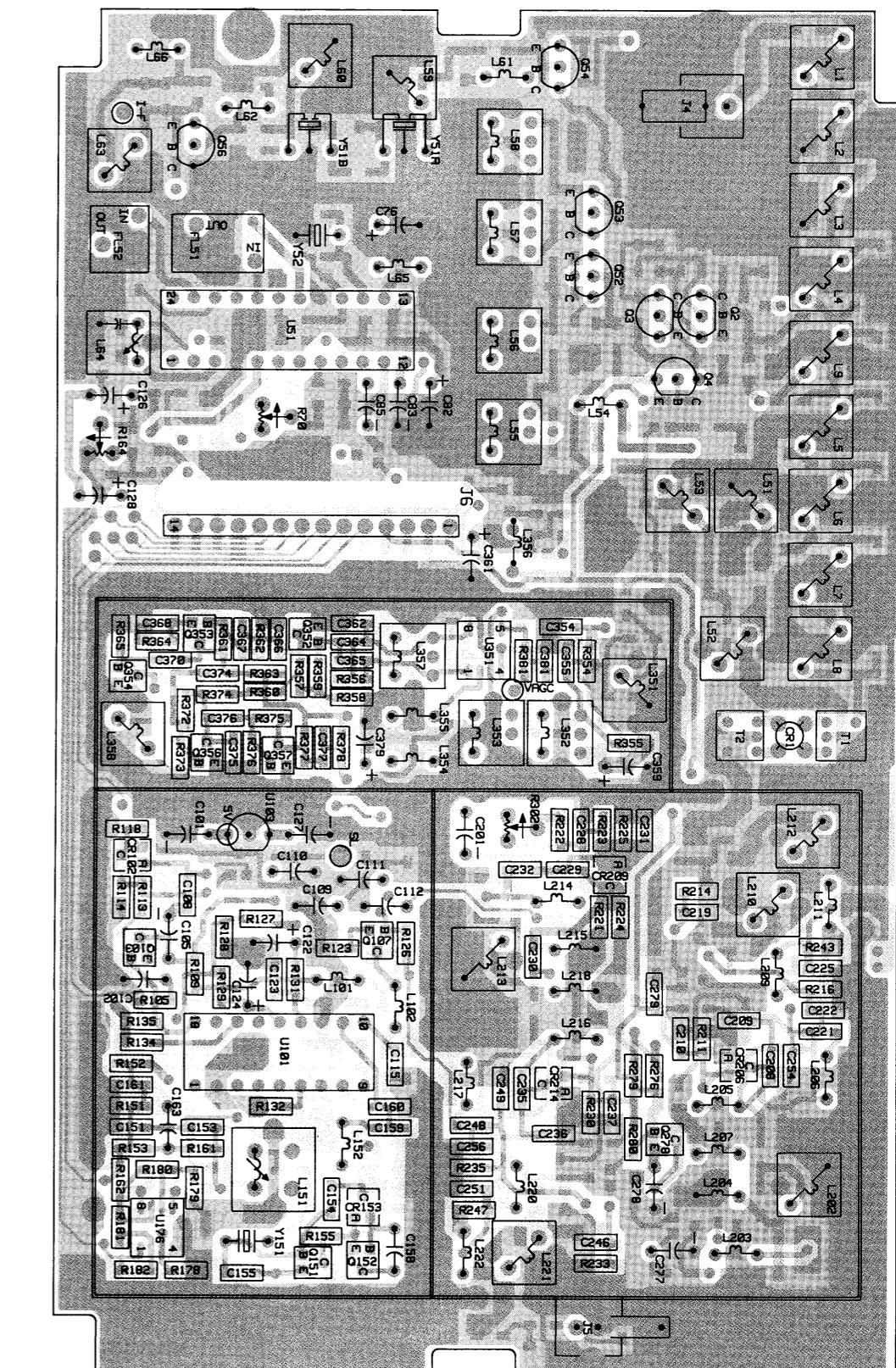
SOLDER SIDE VIEW

SOLDER SIDE ● GBW-6349-O
COMPONENT SIDE ● GBW-6350-O
OVERLAY — GBW-6351-O



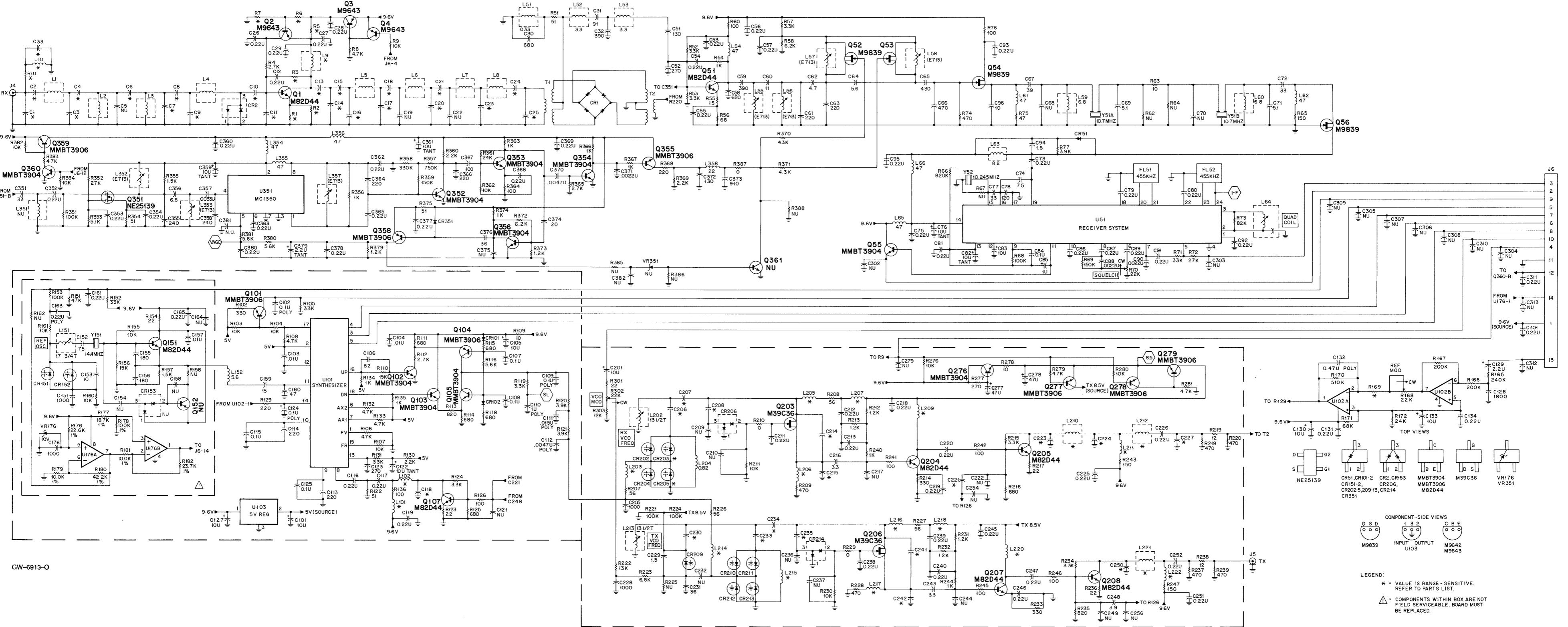
INNER LAYERS

SOLDER INNER LAYER GCW-6389-O
COMPONENT INNER LAYER GCW-6390-O



COMPONENT SIDE VIEW

SOLDER SIDE ● GBW-6349-O
COMPONENT SIDE ● GBW-6350-O
OVERLAY — GBW-6391-O



Schematic, Circuit Board Diagram, and Parts List for HLB4100A Low Band RF Board (Early Version)

(Early Version)
PW-6916-A

(Sheet 1 of 3)

Range 2 Parts List

HLB4100A RF Board, 36-42 MHz

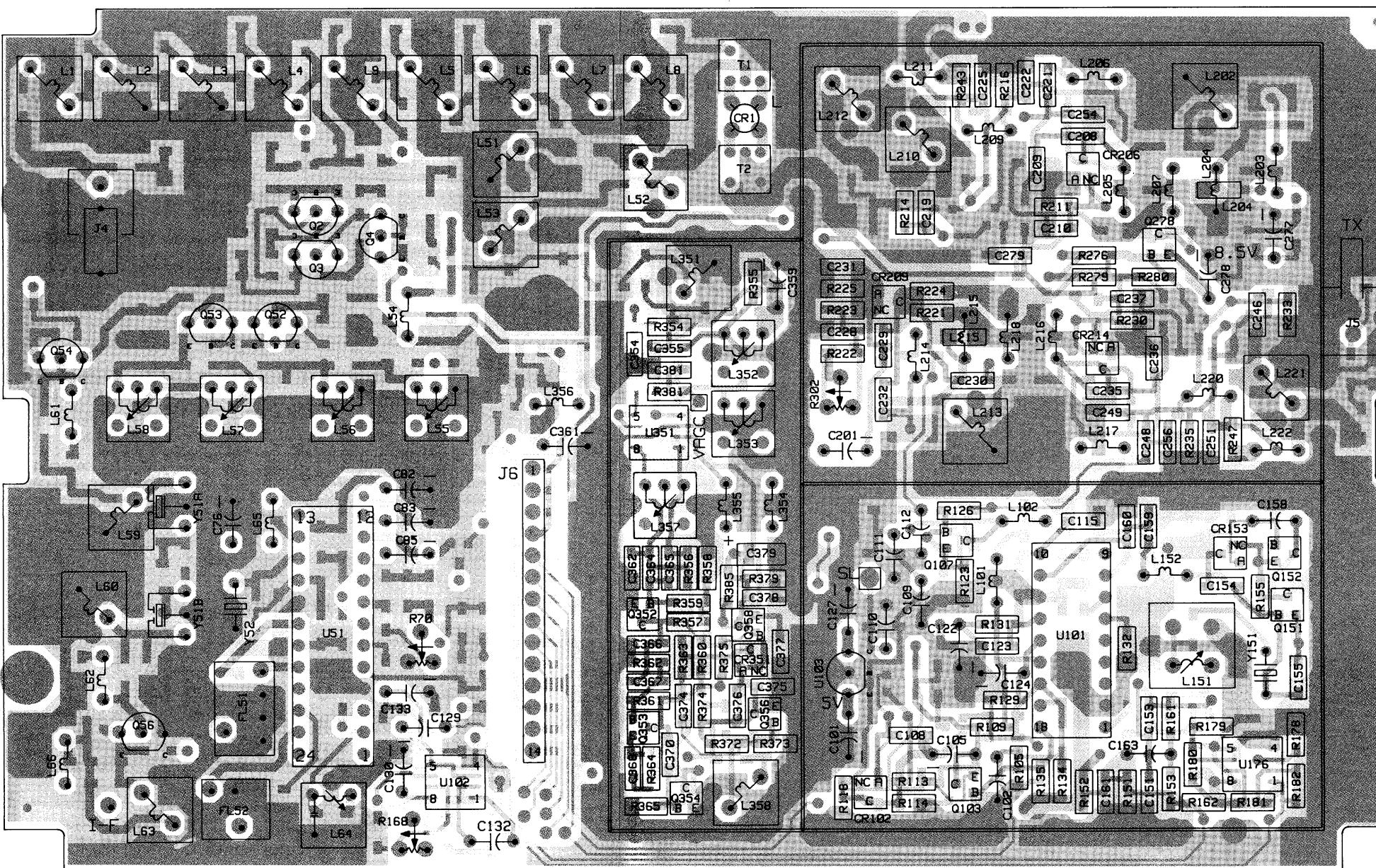
MXW-6910-O

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, chip, pF, ±5%, 50V (unless otherwise indicated)		
C1	21-13740B53	150
C2	21-13740B74	1200
C3	21-13740B63	390
C4	21-13740B53	150
C6	21-13740B36	30
C8	21-13740B52	130
C9	21-13740B65	470
C10	21-13740B73	1000
C11	21-13740B54	160
C12,13	21-11032B15	0.22 uF, +80-20%
C15	21-11032B15	0.22 uF, +80-20%
C16	21-13740B51	120
C17	21-13740B66	510
C18	21-13740B55	180
C20	21-13740B66	510
C21	21-13740B56	200
C23	21-13740B65	470
C24	21-13740B61	330
C25	21-13740B60	300
C26-29	21-11032B15	0.22 uF, +80-20%
C30	21-13740B69	680
C31	21-13740B48	91
C32	21-13740B63	390
C51	21-13740B52	130
C52	21-13740B59	270
C53-57	21-11032B15	0.22 uF, +80-20%
C58	21-13740B68	620
C59	21-13740B63	390
C60	21-13740B26	11
C61	21-13740B57	220
C62	21-13740B17	4.7, ±25 pF
C63	21-13740B57	220
C64	21-13740B19	5.6, ±25 pF
C65	21-13740B64	430
C66	21-13740B65	470
C67	21-13740B39	39
C69	21-13740B18	5.1, ±25 pF
C71	21-13740B18	5.1, ±25 pF
C72	21-13740B37	33
C73	21-11032B15	0.22 uF, +80-20%
C74	21-13740B22	7.5, ±5 pF
C75	21-11032B15	0.22 uF, +80-20%
C76	23-11013D13	10 uF, ±10%, 20V, tantalum
C77	21-13740B37	33
C78	21-13740B51	120
C79-81	21-11032B15	0.22 uF, +80-20%
C82	23-11013D13	10 uF, ±10%, 20V, tantalum
C83	23-11048B13	10 uF, ±20%, 16V, electrolytic
C84	21-13741B69	0.1 uF, ±10%
C85	23-11048B05	1 uF, ±20%, electrolytic
C86,87	21-11032B15	0.22 uF, +80-20%
C88	21-13741B29	0.0022 uF, ±10%
C89	21-11032B15	0.22 uF, +80-20%
C90	21-13741B29	0.0022 uF, ±10%
C91-93	21-11032B15	0.22 uF, +80-20%
C94	21-13740B05	1.5, ±25 pF
C95	21-11032B15	0.22 uF, +80-20%
C96	21-13740B25	10, ±5 pF
C101	23-11048B13	10 uF, ±20%, 16V, electrolytic
C102	08-11051A13	0.1 uF, 63V
C103,104	21-13741B45	0.01 uF, ±10%
C105	23-11048B13	10 uF, ±20%, 16V, electrolytic
C106	21-13740B47	82
C107,108	21-13741B69	0.1 uF, ±10%
C109	08-11051A13	0.1 uF, 63V
C110	08-11044A33	1 uF
C111	08-11051A08	0.015 uF, 63V
C112	08-11051A05	0.0047 uF, 63V
C113,114	21-13740B57	220
C115	21-13741B69	0.1 uF, ±10%
C116,117	21-11032B15	0.22 uF, +80-20%
C118	21-13740B29	15
C119	21-11032B15	0.22 uF, +80-20%
C122	23-11013D13	10 uF, ±10%, 20V, tantalum
C123	21-13740B59	270
C124	08-11051A13	0.1 uF, 63V
C125	21-13741B69	0.1 uF, ±10%
C127	23-11048B13	10 uF, ±20%, 16V, electrolytic
C128	21-13740B78	1800
C129	23-11048B06	2.2 uF, ±20%, electrolytic
C130	23-11048B13	10 uF, ±20%, 16V, electrolytic
C131	21-11032B15	0.22 uF, +80-20%
C132	08-11051A17	0.47 uF, 63V
C133	23-11048B13	10 uF, ±20%, 16V, electrolytic
C134	21-11032B15	0.22 uF, +80-20%
C151	21-13740B73	1000
C152	21-13740B46	75
C153	21-13740B25	10, ±5 pF
C155,156	21-13740B55	180
C157	21-13741B45	0.01 uF, ±10%
C159	21-13740B29	15
C160	21-13740B41	47
C161	21-11032B15	0.22 uF, +80-20%
C163	08-11051A15	0.22 uF, 63V
C165	21-11032B15	0.22 uF, +80-20%
C176	21-13740B73	1000
C201	23-11048B13	10 uF, ±20%, 16V, electrolytic
C205	21-13740B73	1000
C206	21-13740B38	36

MXW-6910-O

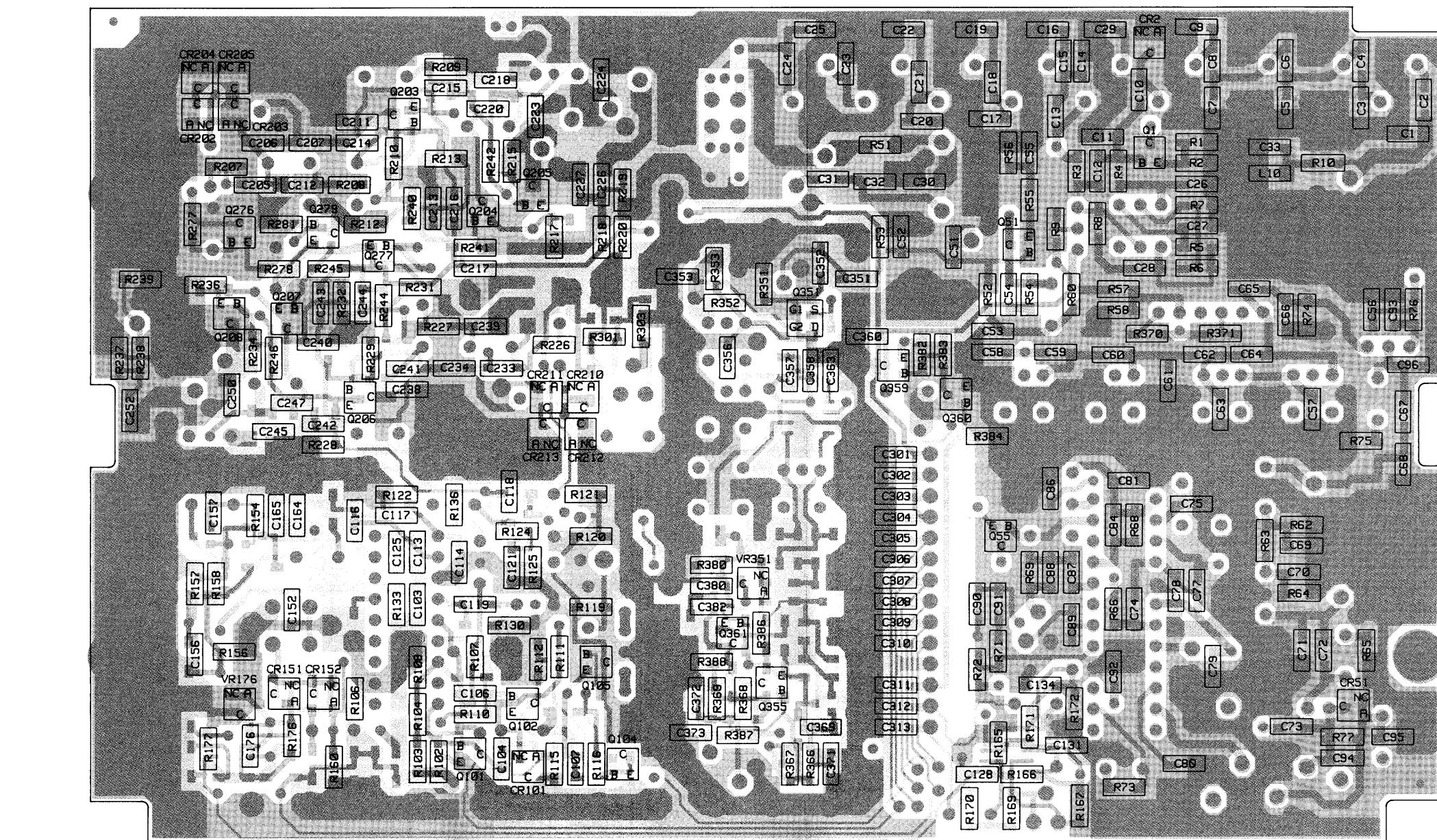
MXW-6910-O (2)

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, chip, pF, ±5%, 50V (unless otherwise indicated)		
C207	21-13740B35	27
C208	21-13740B17	4.7, ±25 pF
C211-213	21-11032B15	0.22 uF, +80-20%
C214,215	21-13740B35	27
C216	21-13740B13	3.3, ±25 pF
C218-220	21-11032B15	0.22 uF, +80-20%
C221	21-13740B09	2.2, ±25 pF
C223	21-13740B23	8.2, ±5 pF
C224	21-13740B39	39
C225,226	21-11032B15	0.22 uF, +80-20%
C227	21-13740B37	33
C228	21-13740B73	1000
C229	21-13740B05	1.5, ±25 pF
C230	21-13740B17	4.7, ±25 pF
C231	21-13740B38	36
C233	21-13740B49	100
C234	21-13740B38	36
C235	21-13740B17	4.7, ±25 pF
C238-240	21-11032B15	0.22 uF, +80-20%
C241,242	21-13740B31	18
C243	21-13740B13	3.3, ±25 pF
C245-247	21-11032B15	0.22 uF, +80-20%
C248	21-13740B15	3.9, ±25 pF
C250	21-13740B31	18
C251,252	21-11032B15	0.22 uF, +80-20%
C277,278	23-11048B19	47 uF, ±20%, 16V
C301	21-11032B15	0.22 uF, +80-20%
C311	21-11032B15	0.22 uF, +80-20%
C351	21-13740B37	33
C352-354	21-11032B15	0.22 uF, +80-20%
C355	21-13740B58	240
C356	21-13740B21	6.8, ±5 pF
C357	21-13741B33	0.0033 uF, ±10%
C358	21-13740B58	240
C359	23-11013D13	10 uF, ±10%, 20V, tantalum
C360	21-11032B15	0.22 uF, +80-20%
C361	23-11013D13	10 uF, ±10%, 20V, tantalum
C362,363	21-11032B15	0.22 uF, +80-20%
C364	21-13740B57	220
C365	21-11032B15	0.22 uF, +80-20%
C366	21-13740B57	220
C367	21-13740B49	100
C368,369	21-11032B15	0.22 uF, +80-20%
C370	21-13741B37	0.0047 uF, ±10%
C371	21-13741B29	0.0022 uF, ±10%
C372	21-13740B52	130
C373	21-13740B72	910
C374	21-13740B32	20
C376	21-13740B38	36
C377,C378	21-11032B15	0.22 uF, +80-20%
C379	23-11049A09	2.2 uF, ±10%, 20V, tantalum
C380	21-11032B15	0.22 uF, +80-20%
diode (see note)		
CR1	48-80236E16	quad Schottky, crossed
CR2	48-80154K03	dual Schottky, SOT
CR51	48-05129M76	silicon, SOT
CR101,102	48-05129M76	silicon, SOT
CR151,152	48-8000E10	silicon varactor, SOT
CR202-205	48-8000E10	silicon varactor, SOT
CR206	48-80154K03	dual Schottky, SOT
CR209	48-8000E10	silicon varactor, SOT
CR210-213	48-80991T01	silicon varactor, SOT
CR214	48-80154K03	dual Schottky, SOT
CR351	48-80939T01	barrier Schottky
filters		
FL51	91-80097D05	455 kHz, 6E
FL52	91-80098D05	455 kHz, 4E
connector, receptacle		



COMPONENT SIDE

PONENT SIDE GW-6915-O
SOLDER SIDE GW-6914W01-O
OVERLAY

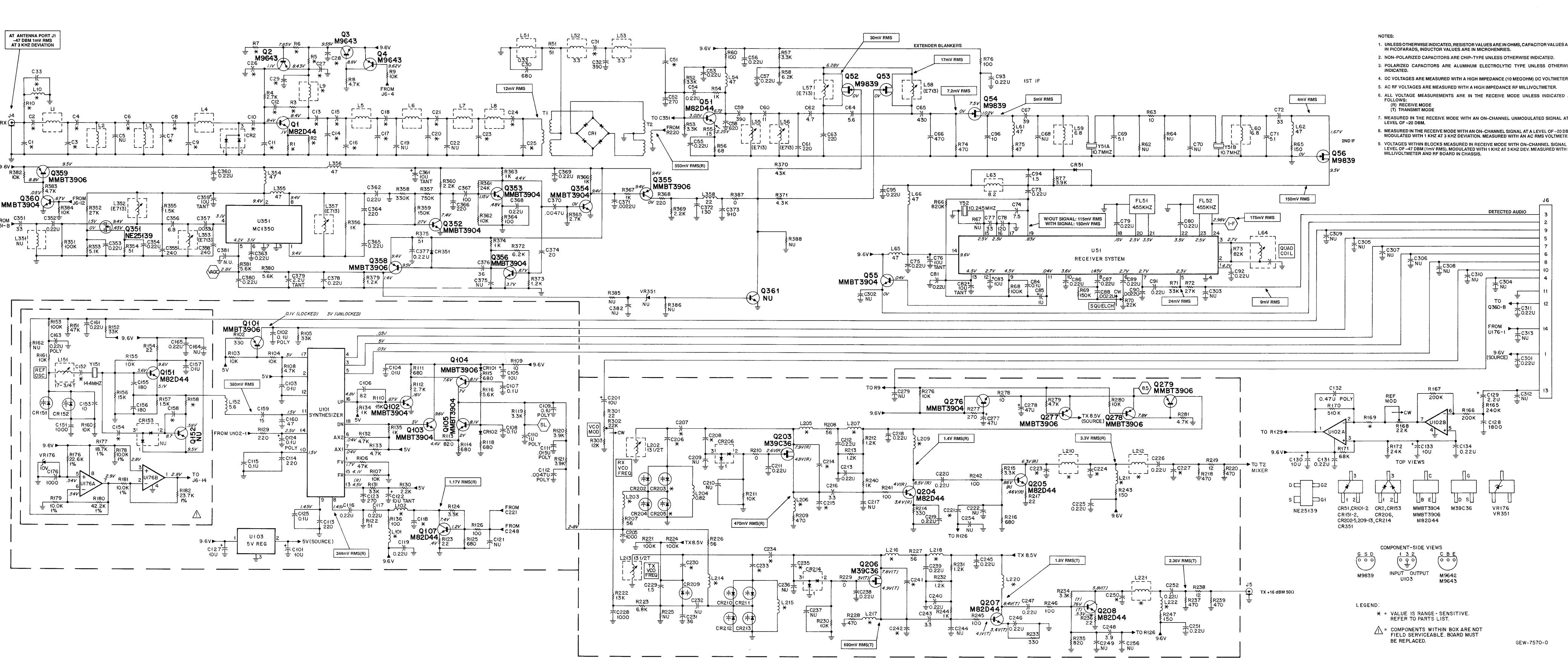


SOLDER SIDE

COMPONENT SIDE 
SOLDER SIDE 
OVERLAY  GW-6915-
GW-6914W

Low Band RF Board Transistor D.C. Voltage Table

Transistor Ref. No.	VOLTAGE			VOLTAGE		
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN
Q1	0.8	0.1	8.4	—	—	—
Q2	7.8	8.4	1.1	—	—	—
Q3	8.8	9.6	9.5	—	—	—
Q4	9.6	9.6	8.8	—	—	—
Q51	3.0	2.3	6.7	—	—	—
Q52	—	—	—	0	6.3	6.3
Q53	—	—	—	0	6.3	6.3
Q54	—	—	—	0	1.1	7.5
Q55	.04	0	9.6	—	—	—
Q56	—	—	—	0	1.7	9.5
Q101	5.0	5.0	0.1	—	—	—
Q102	0.7	0	0.1	—	—	—
Q103	5.0	4.4	9.6	—	—	—
Q104	8.1	2-8v	2-8v	—	—	—
Q105	8.1	2.0	2-8v	—	—	—
Q107	1.2	0.4	7.4	—	—	—
Q151	5.6	5.1v	9.6	—	—	—
Q152	8.7v	9.5	5.8	—	—	—
Q160	4.3	3.6	9.6	—	—	—
Q203	—	—	2.6(R)	4.8(R)	7.9(R)	—
Q204	4.0(R)	3.4(R)	8.5(R)	—	—	—
Q205	.86(R)	.46(R)	6.3(R)	—	—	—
Q206	—	—	—	3.0(T)	4.9(T)	7.8(T)
Q207	4.1(T)	3.4(T)	8.4(T)	—	—	—
Q208	.76(T)	53(T)	5.8(T)	—	—	—
Q276	9.6	8.5	9.6	—	—	—
Q277	9.5	8.5	9.5	—	—	—
Q278	9.6	8.5	7.8	—	—	—
Q279	7.8	8.5	8.5	—	—	—
Q352	.27	0	7.4	—	—	—
Q353	.12	.48	4.4	—	—	—
Q354	0	0	9.4	—	—	—
Q355	9.4	9.4	0	—	—	—
Q356	.67	0	3.7	—	—	—
Q357	.67	0	3.7	—	—	—
Q358	9.5	9.4	1.4	—	—	—
Q359	8.8	9.6	9.5	—	—	—
Q360	.67	0	.05	—	—	—



Schematic, Circuit Board Diagrams, and Parts Lists for HLB4100A/4099B/4101B
Low Band RF Board

PW-7569-O

(Sheet 1 of 4)

3/31/90

parts list

HLB409B Low Band RF Board 29.7-36.0 MHz (Range 1)			MXW-7571-O	MXW-7571-O (2)	MXW-7571-O (3)	MXW-7571-O (4)	MXW-7571-O (5)	MXW-7572-O (2)	MXW-7572-O (3)	MXW-7572-O (4)	MXW-7572-O (5)			
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION	REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION	REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION	REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION	REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)			C0208	21-13740B17	4.7 pF, ±25 pF, 50V	L0221	24-80063M11	.68 uH	R0168	18-05500L08	22k, ±20%, 100V	C0066	21-13740B57	220 pF, ±5%, 50V
C0001	21-13740B55	180 pF, ±5% 50V	C0211-0213	21-1032B15	22.0 pF, ±80, -20, 50V	L0224	24-80063M24	8.2 uH	R0169	06-1107B15	47k	C0067	21-13740B49	100 pF, ±5%, 50V
C0002	21-1032B15	.22 uF, ±80, -20, 50V	C0214,0215	21-13740B43	58 pF, ±5%, 50V	L0352,0353	24-80164M01	1.6 turns	R0170	06-1107B740	510k	C0068	21-13740B25	22.0 pF, ±80, -20, 50V
C0003	21-13740B66	510 pF, ±5% 50V	C0216	21-13740B13	3.3 pF, ±25 pF, 50V	L0354-0356	24-80063M34	.47 uH	R0171	06-1107B719	68k	C0069	21-13740B33	100 pF, ±5%, 50V
C0004	21-13740B57	220 pF, ±5% 50V	C0218-0220	21-1032B15	.22 uF, ±80, -20, 50V	L0357	24-80063M41	1.6 turns	R0172	06-1107B800	24k	C0070	21-13740B52	22.0 pF, ±80, -20, 50V
C0005	21-13740B33	36 pF, ±5%, 50V	C0220	21-13740B25	10 pF, ±5%, 50V	L0358	24-80063M27	22 uH	R0176	06-1107G28	3.3 k	C0071	21-13740B17	22.7k, ±1%
C0006	21-13740B57	5.6 pF, ±25 pF, 50V	C0223	21-13740B25	10 pF, ±5%, 50V	L0359	24-80063M27	22 uH	R0177	06-1107G18	18.7k, ±1%	C0072	21-13740B52	10 uF, ±10%, 20V
C0007	21-13740B55	180 pF, ±5% 50V	C0224	21-13740B41	47 pF, ±5%, 50V	L0360	24-80063M27	22 uH	R0178,0179	06-1107F791	10k, ±1%	C0073	21-13740B41	10 uF, ±20%, 16V
C0008	21-13740B55	180 pF, ±5% 50V	C0225,0226	21-1032B15	22.0 uF, ±80, -20, 50V	L0361	24-80164M04	1.047 uF, ±5%, 50V	R0179	06-1107G52	42.2k, ±1%	C0074	21-13740B41	10 uF, ±80, -20, 50V
C0009	21-13740B66	620 pF, ±5% 50V	C0227	21-13740B41	47 pF, ±5%, 50V	L0362	24-80164M04	NPN	R0180	06-1107F791	10k, ±1%	C0075	21-13740B38	36 pF, ±5%, 50V
C0010	21-1032B15	.22 uF, ±80, -20, 50V	C0228	21-13740B73	1000 pF, ±5%, 50V	L0363	24-80164M04	NPN	R0181	06-1107G28	23.7k, ±1%	C0076	21-13740B38	22.0 uF, ±80, -20, 50V
C0011	21-13740B66	180 pF, ±5% 50V	C0229	21-13740B05	1.5 pF, ±25 pF, 50V	L0364	24-80214G03	n-Channel	R0182	06-1107G28	100	C0077	21-13740B37	100 pF, ±5%, 50V
C0012,0013	21-1032B15	.22 uF, ±80, -20, 50V	C0230	21-13740B19	36 pF, ±5%, 50V	L0365	24-80214G03	NPN	R0183	06-1107G44	50	C0078	21-13740B37	0.0208
C0013	21-13740B46	75 pF, ±5%, 50V	C0231	21-13740B25	10 pF, ±5%, 50V	L0366	24-80164M16	NPN	R0184	06-1107G44	470	C0079	21-13740B25	22.0 uF, ±80, 20, 50V
C0014	21-13740B66	510 pF, ±5% 50V	C0232	21-13740B25	30 pF, ±5%, 50V	L0367	24-80164M16	NPN	R0185	06-1107G44	0	C0080	21-13740B25	10k
C0015	21-13740B46	75 pF, ±5%, 50V	C0233	21-13740B25	30 pF, ±5%, 50V	L0368	24-80164M16	NPN	R0186	06-1107G44	470	C0081	21-13740B46	10k
C0016	21-13740B66	510 pF, ±5% 50V	C0234	21-13740B49	47 pF, ±5%, 50V	L0369	24-80164M16	NPN	R0187	06-1107G44	10k	C0082	21-13740B39	10 uF, ±10%, 20V
C0017	21-13740B66	510 pF, ±5% 50V	C0235	21-13740B17	4.7 pF, ±25 pF, 50V	L0370	24-80164M16	NPN	R0188	06-1107G44	10k	C0083	21-13740B17	10 uF, ±20%, 16V
C0018	21-13740B66	510 pF, ±5% 50V	C0236	21-13740B17	4.7 pF, ±25 pF, 50V	L0371	24-80164M16	NPN	R0189	06-1107G44	10k	C0084	21-1032B13	10 uF, ±80, -20, 50V
C0019	21-13740B66	680 pF, ±5% 50V	C0237	21-1032B15	22.0 uF, ±80, -20, 50V	L0372	24-80164M16	NPN	R0190	06-1107G44	150	C0085	21-13740B25	1.0 uF, ±20%, 16V
C0020	21-13740B66	680 pF, ±5% 50V	C0238	21-13740B73	1000 pF, ±5%, 50V	L0373	24-80164M16	NPN	R0191	06-1107G44	100	C0086	21-13740B25	0.022 uF, ±5%, 50V
C0021	21-13740B66	680 pF, ±5% 50V	C0239	21-13740B73	1000 pF, ±5%, 50V	L0374	24-80164M16	NPN	R0192	06-1107G44	100	C0087	21-1032B15	2.2 uF, ±80, -20, 50V
C0022	21-13740B73	1000 pF, ±5%, 50V	C0240	21-13740B17	3.3 pF, ±25 pF, 50V	L0375	24-80164M16	NPN	R0193	06-1107G44	100	C0088	21-13740B25	0.022 uF, ±5%, 50V
C0023	21-13740B66	680 pF, ±5% 50V	C0241	21-13740B47	82 pF, ±5%, 50V	L0376	24-80164M16	NPN	R0194	06-1107G44	100	C0089	21-1032B15	2.2 uF, ±80, 20, 50V
C0024	21-13740B66	680 pF, ±5% 50V	C0242	21-13740B47	82 pF, ±5%, 50V	L0377	24-80164M16	NPN	R0195	06-1107G44	100	C0090	21-13740B47	0.022 uF, ±5%, 50V
C0025	21-13740B66	680 pF, ±5% 50V	C0243	21-13740B17	3.3 pF, ±25 pF, 50V	L0378	24-80164M16	NPN	R0196	06-1107G44	100	C0091	21-1032B15	2.2 uF, ±80, -20, 50V
C0026-0029	21-1032B15	.22 uF, ±80, -20, 50V	C0244	21-1032B15	22.0 pF, ±25 pF, 50V	L0379	24-80164M16	NPN	R0197	06-1107G44	100	C0092	21-1032B15	2.2 uF, ±80, 20, 50V
C0027	21-13740B66	680 pF, ±5% 50V	C0245	21-13740B17	3.3 pF, ±25 pF, 50V	L0380	24-80164M16	NPN	R0198	06-1107G44	100	C0093	21-1032B15	2.2 uF, ±80, -20, 50V
C0028	21-13740B66	680 pF, ±5% 50V	C0246	21-13740B17	3.3 pF, ±25 pF, 50V	L0381	24-80164M16	NPN	R0199	06-1107G44	100	C0094	21-13740B17	3.3 pF, ±25 pF, 50V
C0029	21-13740B66	680 pF, ±5% 50V	C0247	21-13740B17	3.3 pF, ±25 pF, 50V	L0382	24-80164M16	NPN	R0200	06-1107G44	100	C0095	21-13740B17	1.5 pF, ±25 pF, 50V
C0030	21-13740B66	680 pF, ±5% 50V	C0248	21-13740B17	3.3 pF, ±25 pF, 50V	L0383	24-80164M16	NPN	R0201	06-1107G44	100	C0096	21-13740B17	1.5 pF, ±25 pF, 50V
C0031	21-13740B66	680 pF, ±5% 50V	C0249	21-13740B17	3.3 pF, ±25 pF, 50V	L0384	24-80164M16	NPN	R0202	06-1107G44	100	C0097	21-13740B17	3.3 pF, ±25 pF, 50V
C0032	21-13740B66	680 pF, ±5% 50V	C0250	21-13740B17	3.3 pF, ±25 pF, 50V	L0385	24-80164M16	NPN	R0203	06-1107G44	100	C0098	21-13740B17	3.3 pF, ±25 pF, 50V
C0033	21-13740B66	680 pF, ±5% 50V	C0251	21-13740B17	3.3 pF, ±25 pF, 50V	L0386	24-80164M16	NPN	R0204	06-1107G44	100	C0099	21-13740B17	3.3 pF, ±25 pF, 50V

parts list

HLB4100A Low Band RF Board 36.0-41.999 MHz (Range 2) MXW-6910-A

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C0001	21-13740B53	150 pF, ±5%, 50V
C0002	21-13740B74	1200 pF, ±5%, 50V
C0003	21-13740B63	390 pF, ±5%, 50V
C0004	21-13740B53	150 pF, ±5%, 50V
C0006	21-13740B36	30 pF, ±5%, 50V
C0008	21-13740B52	130 pF, ±5%, 50V
C0009	21-13740B65	470 pF, ±5%, 50V
C0010	21-13740B73	1000 pF, ±5%, 50V
C0011	21-13740B53	160 pF, ±5%, 50V
C0012,0013	21-11032B15	.22 uF, ±80-20, 50V
C0015	21-11032B15	.22 uF, ±80-20, 50V
C0016	21-13740B51	120 pF, ±5%, 50V
C0017	21-13740B66	510 pF, ±5%, 50V
C0018	21-13740B55	180 pF, ±5%, 50V
C0020	21-13740B66	510 pF, ±5%, 50V
C0021	21-13740B56	200 pF, ±5%, 50V
C0023	21-13740B65	470 pF, ±5%, 50V
C0024	21-13740B61	330 pF, ±5%, 50V
C0025	21-13740B60	300 pF, ±5%, 50V
C0026-0029	21-11032B15	.022 uF, ±80-20, 50V
C0030	21-13740B69	680 pF, ±5%, 50V
C0031	21-13740B48	91 pF, ±5%, 50V
C0032	21-13740B63	390 pF, ±5%, 50V
C0051	21-13740B52	130 pF, ±5%, 50V
C0052	21-13740B59	270 pF, ±5%, 50V
C0053-0057	21-11032B15	.22 uF, ±80-20, 50V
C0058	21-13740B68	620 pF, ±5%, 50V
C0059	21-13740B63	390 pF, ±5%, 50V
C0060	21-13740B26	11 pF, ±5%, 50V
C0061	21-13740B57	220 pF, ±5%, 50V
C0062	21-13740B17	4.7 pF, ±25 pF, 50V
C0063	21-13740B57	220 pF, ±5%, 50V
C0064	21-13740B19	5.6 pF, ±25 pF, 50V
C0065	21-13740B64	430 pF, ±5%, 50V
C0066	21-13740B65	470 pF, ±5%, 50V
C0067	21-13740B39	39 pF, ±5%, 50V
C0069	21-13740B18	5.1 pF, ±25 pF, 50V
C0071	21-13740B18	5.1 pF, ±25 pF, 50V
C0072	21-13740B37	33 pF, ±5%, 50V
C0073	21-11032B15	.22 uF, ±80-20, 50V
C0074	21-13740B22	7.5 pF, ±25 pF, 50V
C0075	21-11032B15	.22 uF, ±80-20, 50V
C0076	23-13749C39	10 uF, ±10%, 20V
C0077	21-13740B37	33 pF, ±5%, 50V
C0078	21-13740B51	120 pF, ±5%, 50V
C0079-0081	21-11032B15	.22 uF, ±80-20, 50V
C0082	23-13749C39	10 uF, ±10%, 20V
C0083	23-11048B13	10 uF, ±20%, 16V
C0084	21-13741B69	.01 uF, ±5%, 50V
C0085	23-11048B80	1 uF, ±20%, 50V
C0086,0087	21-11032B15	.22 uF, ±80-20, 50V
C0088	21-13741B29	.0022 uF, ±5%, 50V
C0089	21-11032B15	.22 uF, ±80-20, 50V
C0090	21-13741B29	.0022 uF, ±5%, 50V
C0091-0093	21-11032B15	.22 uF, ±80-20, 50V
C0094	21-13740B09	1.5 pF, ±25 pF, 50V
C0095	21-11032B15	.22 uF, ±80-20, 50V
C0096	21-13740B25	10 pF, ±5%, 50V
C0101	23-11048B13	10 uF, ±20%, 16V
C0102	08-11051A13	.1 uF, ±5%, 63V
C0103,0104	21-13741B45	.01 uF, ±5%, 50V
C0105	23-11048B13	10 uF, ±20%, 16V
C0106	21-13740B47	82 pF, ±5%, 50V
C0107,0108	21-13741B69	.01 uF, ±5%, 50V
C0109	08-11051A13	.1 uF, ±5%, 63V
C0110	08-11051A19	1.0 uF, ±5%, 63V
C0111	08-11051A08	.015 uF, ±5%, 63V
C0112	08-11051A05	.0047 uF, ±5%, 63V
C0113,0114	21-13740B57	220 pF, ±5%, 50V
C0115	21-13741B69	.01 uF, ±5%, 50V
C0116,0117	21-11032B15	.22 uF, ±80-20, 50V
C0118	21-13740B25	15 pF, ±5%, 50V
C0119	21-11032B15	.22 uF, ±80-20, 50V
C0122	23-13749C39	10 uF, ±10%, 20V
C0123	21-13740B59	270 pF, ±5%, 50V
C0124	08-11051A13	.1, ±5%, 63V
C0125	21-13741B69	.01 uF, ±5%, 50V
C0127	23-11048B13	10 uF, ±20%, 16V
C0128	21-13740B78	180 uF, ±5%, 50V
C0129	23-11048B01	2.2 uF, ±20%, 50V
C0130	23-11048B13	10 uF, ±20%, 16V
C0131	21-11032B15	.22 uF, ±80-20, 50V
C0132	08-11051A17	.47 uF, ±5%, 63V
C0133	23-11048B13	10 uF, ±20%, 16V
C0134	21-11032B15	.22 uF, ±80-20, 50V
C0151	21-13740B73	1000 pF, ±5%, 50V
C0152	21-13740B45	68 pF, ±5%, 50V
C0153	21-13740B25	10 pF, ±5%, 50V
C0155,0156	21-13740B55	180 pF, ±5%, 50V
C0157	21-13741B45	.01 uF, ±5%, 50V
C0159	21-13740B29	15 pF, ±5%, 50V
C0160	21-13740B41	47 pF, ±5%, 50V
C0161	21-11032B15	.22 uF, ±80-20, 50V
C0163	08-11051A15	.22 uF, ±5%, 63V
C0165	21-11032B15	.22 uF, ±20%, 50V
C0176	21-13740B73	1000 pF, ±5%, 50V
C0201	23-11048B13	10 uF, ±20%, 16V
C0205	21-13740B73	1000 pF, ±5%, 50V
C0206	21-13740B38	36 pF, ±5%, 50V

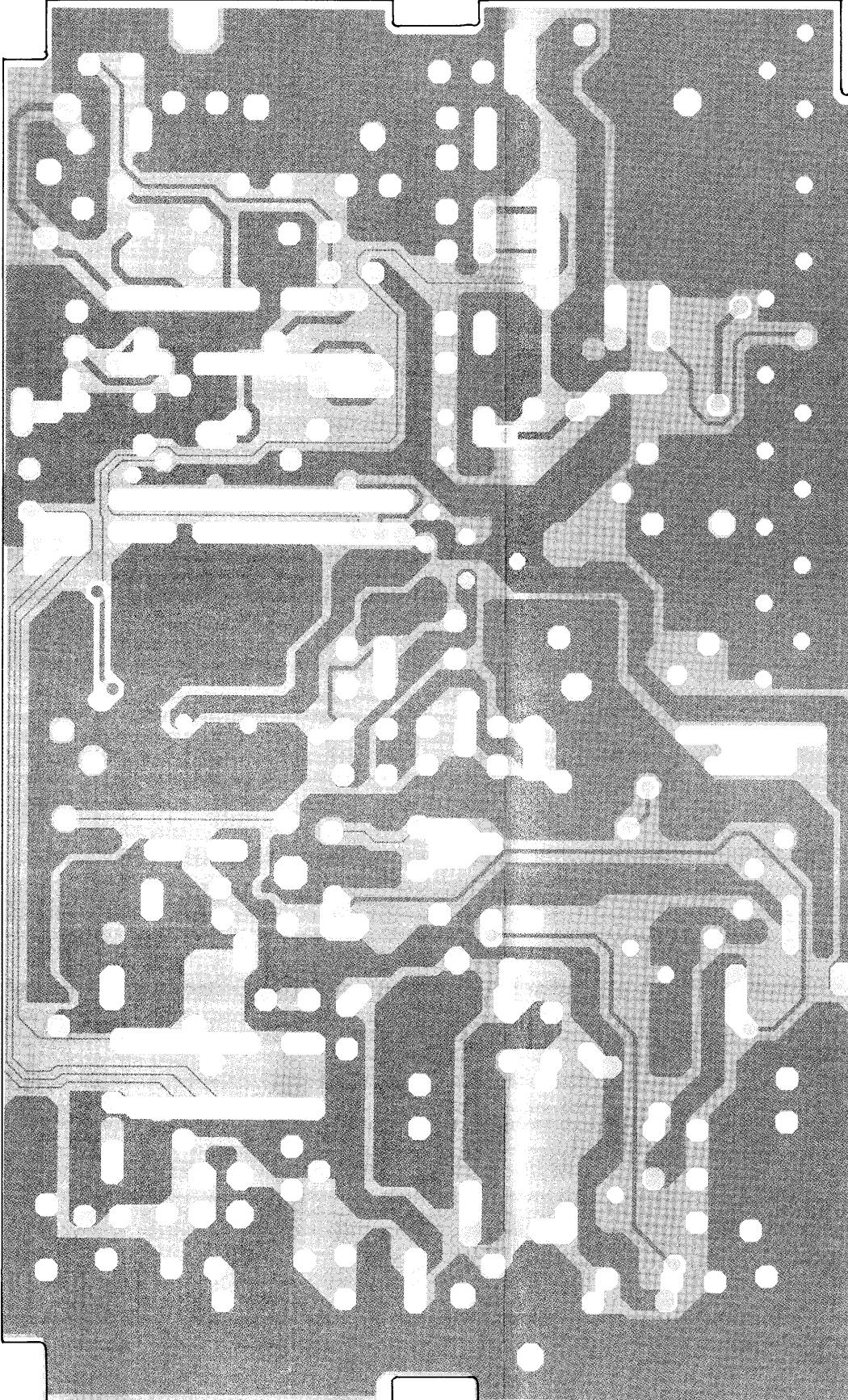
MXW-6910-A (2)

MXW-6910-A (3)

MXW-6910-A (4)

MXW-6910-A (5)

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C0207	21-13740B27	12 pF, ±5%, 50V
C0208	21-13740B35	27 pF, ±25 pF, 50V
C0211-0213	21-11032B15	.22 uF, ±80-20, 50V
C0214,0215	21-13740B35	27 pF, ±5%, 50V
C0216	21-13740B13	3.3 pF, ±25 pF, 50V
C0218-0220	21-11032B15	.22 uF, ±80-20, 50V
C0221	21-13740B09	2.2 pF, ±25 pF, 50V
C0223	21-13740B23	8.2 pF, ±25 pF, 50V
C0224	21-13740B39	39 pF, ±5%, 50V
C0225,0226	21-11032B15	.22 uF, ±80-20, 50V
C0227	21-13740B37	33 pF, ±5%, 50V
C0228	21-13740B73	1000 pF, ±5%, 50V
C0229	21-13740B05	1.5 pF, ±25 pF, 50V
C0230	21-13740B17	4.7 pF, ±25 pF, 50V
C0231	21-13740B38	36 pF, ±5%, 50V
C0233	21-13740B49	100 pF, ±5%, 50V
C0234	21-13740B38	36 pF, ±5%, 50V
C0235	21-13740B17	4.7 pF, ±25 pF, 50V
C0238-0240	21-11032B15	.22 uF, ±80-20, 50V
C0241,0242	21-13740B31	18 pF, ±5%, 50V
C0243	21-13740B13	3.3 pF, ±25 pF, 50V
C0245-0247	21-11032B15	.22 uF, ±80-20, 50V
C0248	21-13740B15	3.9 pF, ±25 pF, 50V
C0250	21-13740B31	18 pF, ±5%, 50V
C0251,0252	21-11032B15	.22 uF, ±80-20, 50V
C0277,0278	23-11048B19	47 pF, ±20%, 16V
C0301	21-11032B15	.22 uF, ±80-20, 50V
C0311	21-11032B15	.22 uF, ±80-20, 50V
C0351	21-13740B37	33 pF, ±5%, 50V
C0352-0354	21-11032B15	.22 uF, ±80-20, 50V
C0355	21-13740B58	240 pF, ±5%, 50V
C0356	21-13740B21	6.8 pF, ±25 pF, 50V
C0357	21-13741B33	.0033 uF, ±5%, 50V
C0358	21-13740B58	240 pF, ±5%, 50V
C0359	21-13749C39	10 uF, ±10%, 20V
C0360	21-11032B15	.22 uF, ±80-20, 50V
C0368,0369	21-11032B15	.22 uF, ±80-20, 50V
C0370	21-13741B37	.0047 uF, ±5%, 50V
C0371	21-13741B29	.0022 uF, ±5%, 50V
C0372	21	



INNER LAYER 1 RED GAW-7688-O
INNER LAYER 2 GREY GAW-7689-O
OVERLAY BLACK GDW-7690-O

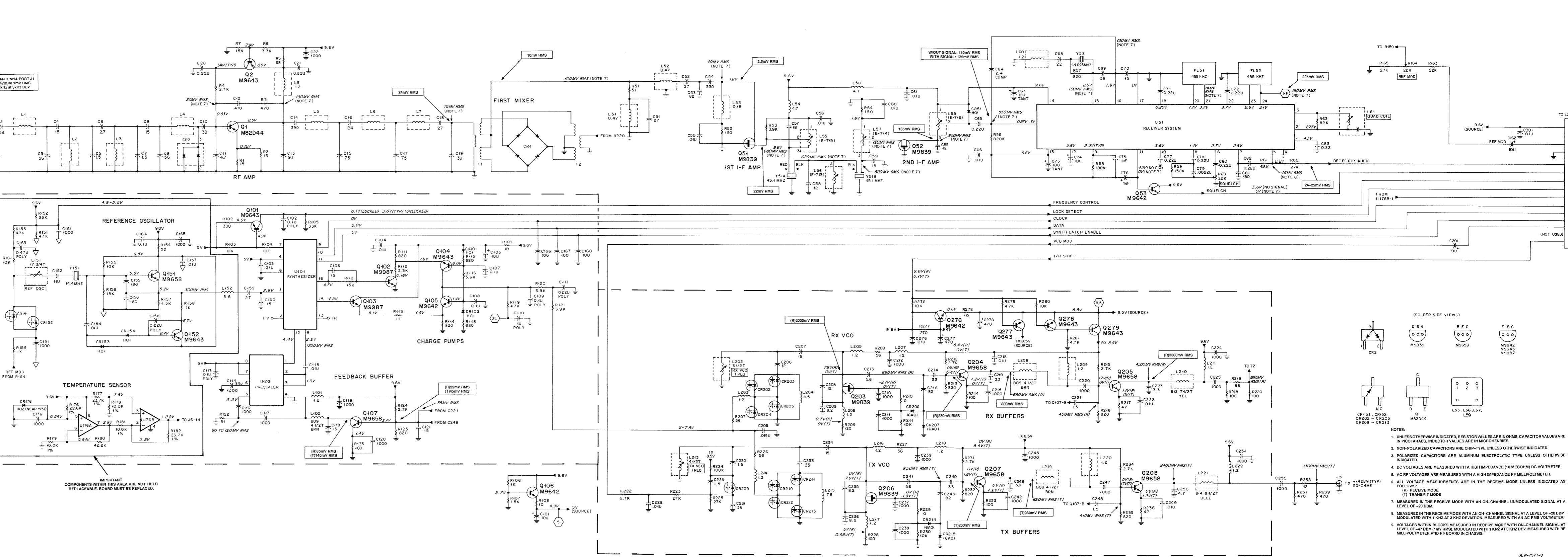
COMPONENT SIDE VIEW

SOLDER SIDE VIEW

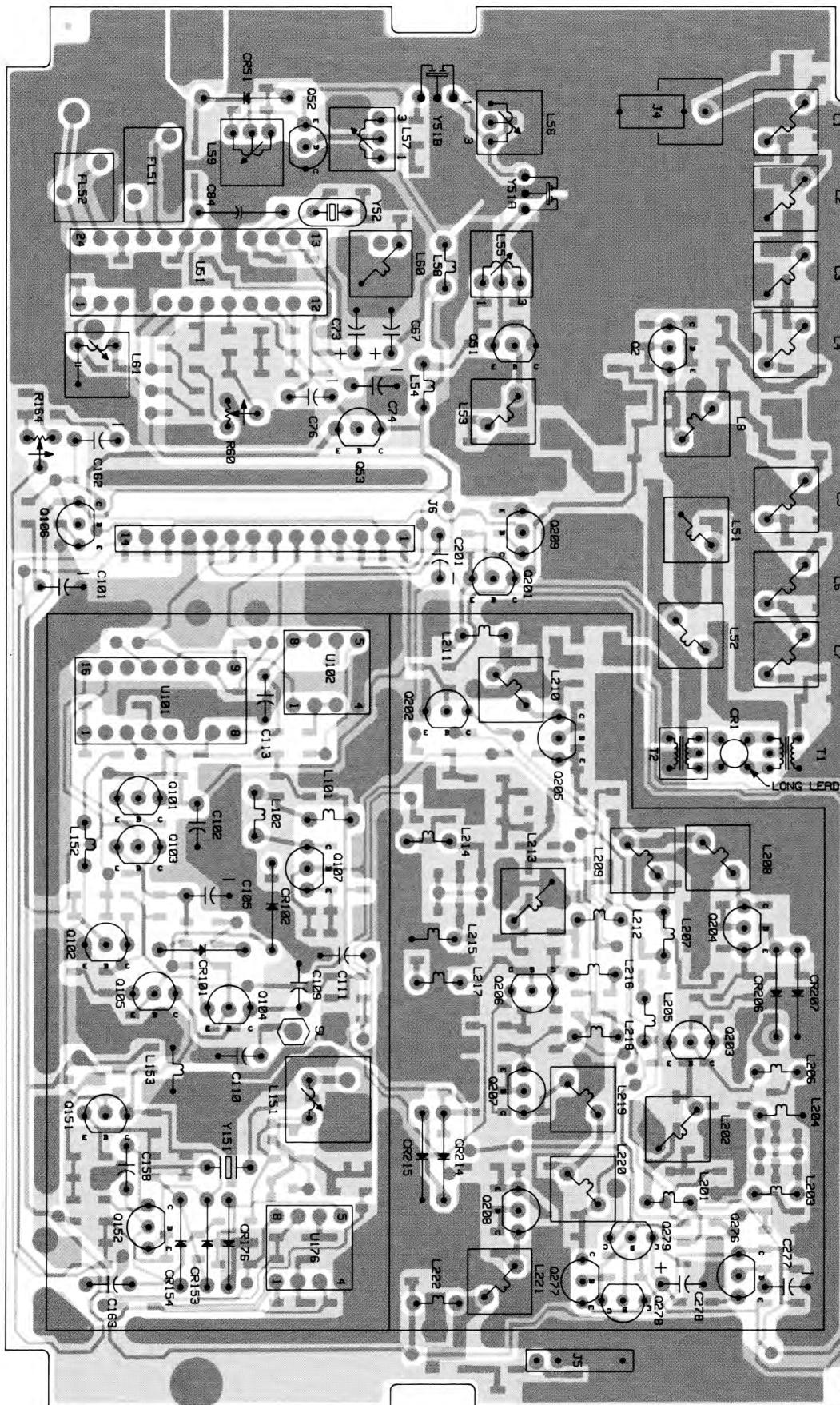
Schematic, Circuit Board Diagrams, and
Parts Lists for HLB4100A/4099B/4101B
Low Band RF Board
PW-7569-O
(Sheet 4 of 4)
2/21/96

RF Board Transistor D.C. Voltage Table

Transistor Ref. No.	VOLTAGE			VOLTAGE		
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN
Q1	.83	.12	8.5	—	—	—
Q2	7.9	8.5	1.1	—	—	—
Q51	—	—	—	0	1.8	9.6
Q52	—	—	—	0	1.8	9.6
Q53	4.2	3.6	9.6	—	—	—
Q101	5.0	5.0	.1 (LOCKED)	—	—	—
Q102	0.7	0	0	—	—	—
Q103	4.8	4.1	9.6	—	—	—
Q104	8.1	7.6	2-8v	—	—	—
Q105	1.4	1.9	2-8v	—	—	—
Q106	5.7	4.9	9.6	—	—	—
Q107	2.1	1.4	9.6	—	—	—
Q151	5.5	5.2	9.5	—	—	—
Q152	8.7	9.5	6.7	—	—	—
Q203	—	—	—	-2.1(R)	.7(R)	7.9
Q204	1.9(R)	1.2(R)	8.5	—	—	—
Q205	1.7(R)	1.1(R)	9.6	—	—	—
Q206	—	—	—	-1.9(T)	.95(T)	7.9
Q207	1.8(T)	1.2(T)	8.5	—	—	—
Q208	1.7(T)	1.2(T)	9.6	—	—	—
Q276	9.5	8.6	9.6	—	—	—
Q277	9.6	8.5(T)	8.5	—	—	—
Q278	9.6(R)	8.5	8.5	—	—	—
Q279	7.6(R)	8.5	8.5	—	—	—

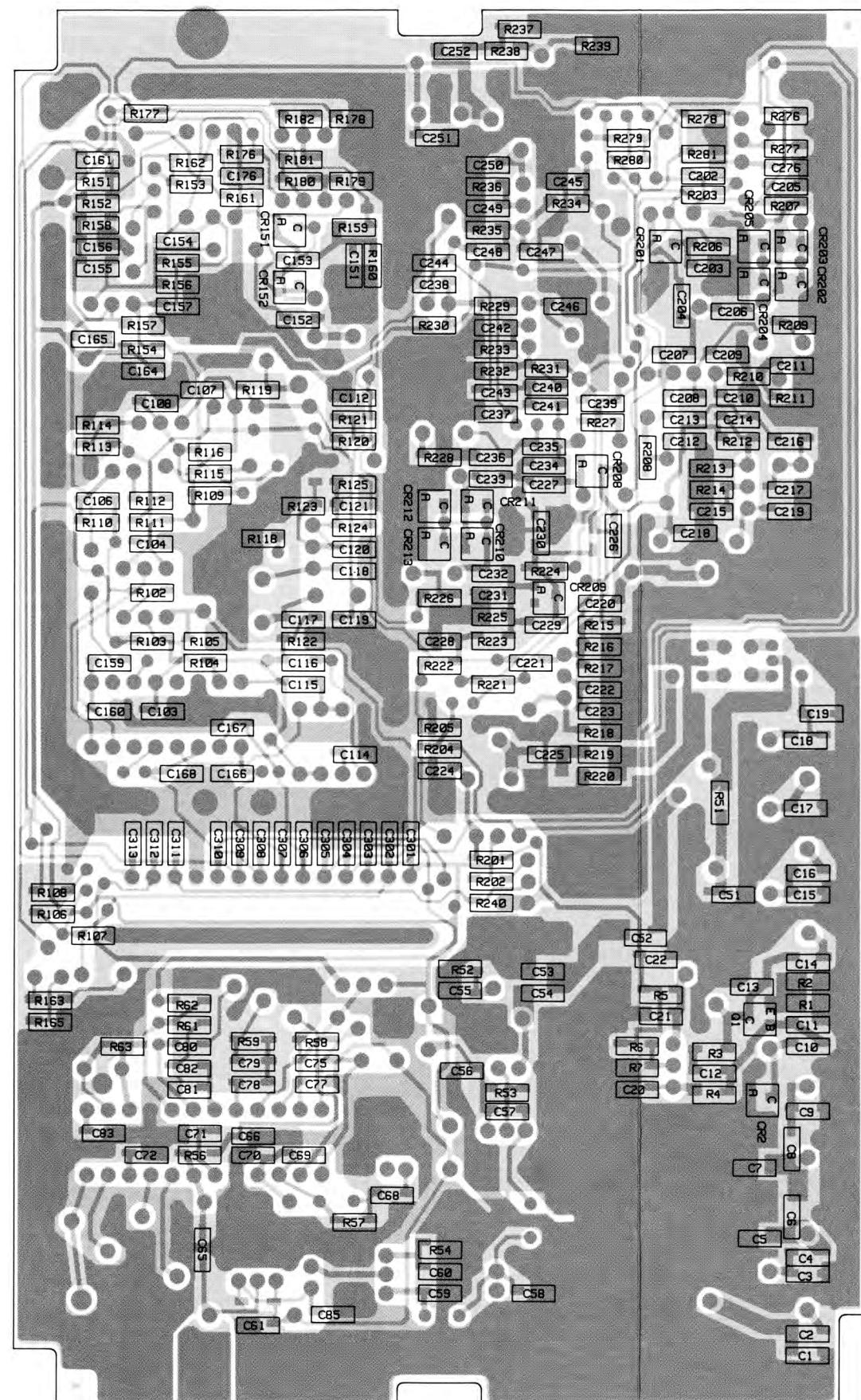


Schematic, Circuit Board Diagrams, and
Parts List for HLD4322B VHF RF Board
W-7576-O
Sheet 1 of 3



COMPONENT SIDE VIEW

SOLDER SIDE COMPONENT SIDE OVERLAYS	RED GREY BLACK	GAW-7702-O GAW-7701-O GDW-7703-O
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SOLDER SIDE VIEW

Schematic, Circuit Board Diagrams, and
Parts List for HLD4322B VHF RF Board
PW-7576-O
(Sheet 2 of 3)
3/31/90

parts list

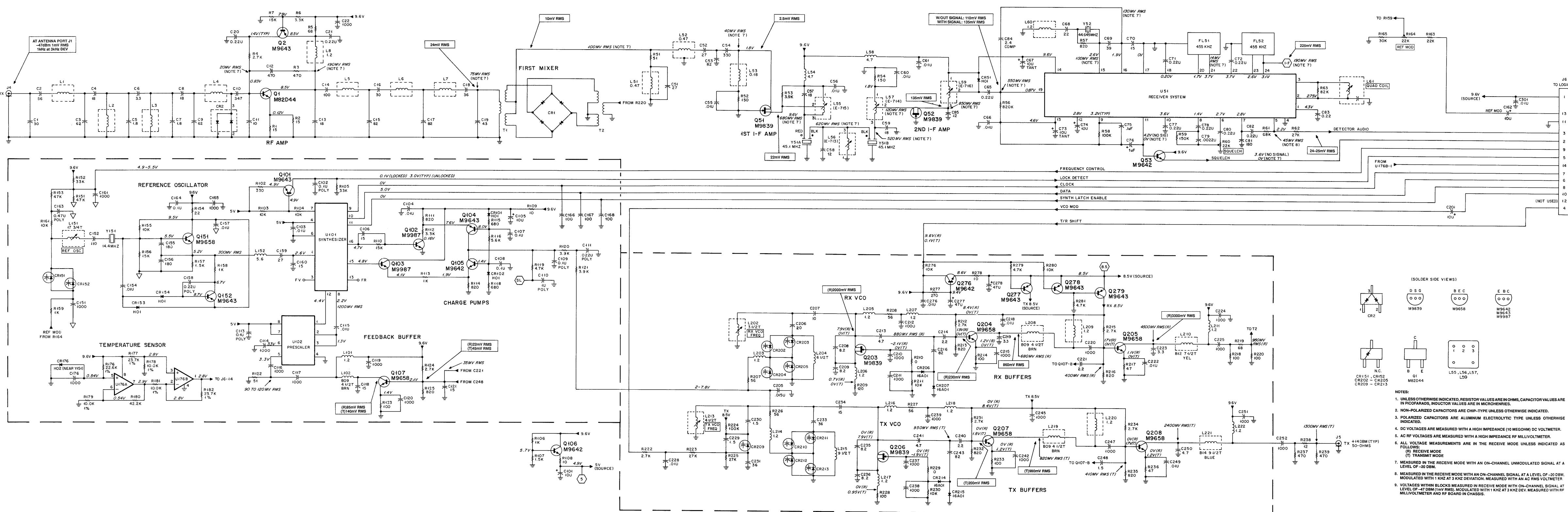
HLD4322B MaxTrac VHF RF Board

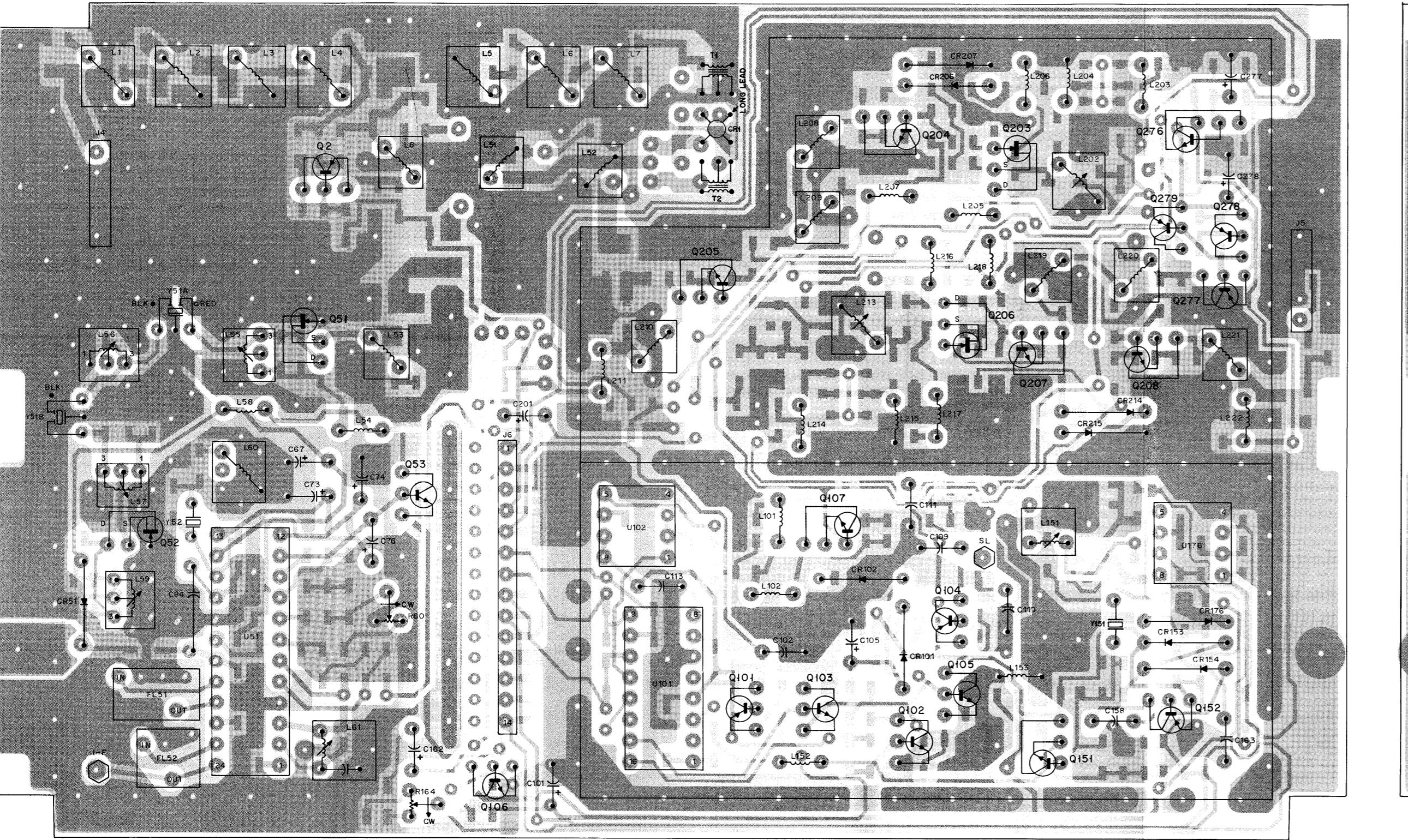
MXW-7404-O

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
C0001	21-13740B35	.27 pF, ±5%, 50V
C0002	21-13740B39	.39 pF, ±5%, 50V
C0003	21-13740B43	.56 pF, ±5%, 50V
C0004	21-13740B29	.15 pF, ±5%, 50V
C0005	21-13740B05	.1.5 pF, ±5%, 50V
C0006	21-13740B11	.27 pF, ±5%, 50V
C0007	21-13740B05	.1.5 pF, ±5%, 50V
C0008	21-13740B29	.15 pF, ±5%, 50V
C0009	21-13740B43	.56 pF, ±5%, 50V
C0010	21-13740B39	.39 pF, ±5%, 50V
C0011	21-13740B17	.4.7 pF, ±5%, 50V
C0012	21-13740B65	.470 pF, ±5%, 50V
C0013	21-13740B24	.9.1 pF, ±5%, 50V
C0014	21-13740B63	.390 pF, ±5%, 50V
C0015	21-13740B46	.75 pF, ±5%, 50V
C0016	21-13740B34	.24 pF, ±5%, 50V
C0017	21-13740B46	.75 pF, ±5%, 50V
C0018	21-13740B35	.27 pF, ±5%, 50V
C0019	21-13740B39	.39 pF, ±5%, 50V
C0020,0021	21-11032B15	.22 uF, +80, -20%, 50V
C0022	21-13740B73	.001 uF, ±5%, 50V
C0051,0052	21-13740B35	.27 pF, ±5%, 50V
C0053	21-13740B47	.82 pF, ±5%, 50V
C0054	21-13740B61	.330 pF, ±5%, 50V
C0055,0056	21-13741B45	.01 uF, ±5%, 50V
C0057	21-13740B31	.18 pF, ±5%, 50V
C0058	21-13740B27	.12 pF, ±5%, 50V
C0059	21-13740B31	.18 pF, ±5%, 50V
C0060,0061	21-13741B45	.01 uF, ±5%, 50V
C0065	21-11032B15	.22 uF, +80, -20%, 50V
C0066	21-13741B45	.01 uF, ±5%, 50V
C0067	23-13749C39	.10 uF, ±10%, 50V, tantalum
C0068	21-13740B33	.22 pF, ±5%, 50V
C0069	21-13740B39	.39 pF, ±5%, 50V
C0070	21-13740B29	.15 pF, ±5%, 50V
C0071,0072	21-11032B15	.22 uF, +80, -20%, 50V
C0073	23-13749C39	.10 uF, ±10%, 50V, tantalum
C0074	23-11048B13	.10 uF, ±20%, 16V, electrolytic
C0075	21-13741B69	.1 uF, ±5%, 50V
C0076	23-11048B05	.1 uF, ±20%, 50V, electrolytic
C0077,0078	21-11032B15	.22 uF, +80, -20%, 50V
C0079	21-13741B29	.0022 uF, ±5%, 50V
C0080	21-11032B15	.22 uF, +80, -20%, 50V
C0081	21-13740B55	.180 pF, ±5%, 50V
C0082,0083	21-11032B15	.22 uF, +80, -20%, 50V
C0084	21-82450B14	.2.4 pF, ±5%, 500V
C0085	21-13740B27	.12 pF, ±5%, 50V
C0101	23-11048B13	.10 uF, ±20%, 16V, electrolytic
C0102	08-11051A13	.1 uF, ±5%, 63V
C0103,0104	21-13741B45	.01 uF, ±5%, 50V
C0105	23-11048B13	.10 uF, ±20%, 16V, electrolytic
C0106	21-13740B29	.15 pF, ±5%, 50V
C0107,0108	21-13741B69	.1 uF, ±5%, 50V
C0109	08-11051A13	.1 uF, ±5%, 63V
C0110	08-11051A19	.1 uF, ±5%, 63V
C0111	08-11051A09	.022 uF, ±5%, 63V
C0113	08-11051A13	.1 uF, ±5%, 63V
C0114	21-13740B73	.001 uF, ±5%, 50V
C0115	21-13741B45	.01 uF, ±5%, 50V
C0116,0117	21-13740B73	.001 uF, ±5%, 50V
C0118	21-13740B29	.15 pF, ±5%, 50V
C0119,0120	21-13740B73	.001 uF, ±5%, 50V
C0121	21-13740B29	.15 pF, ±5%, 50V
C0151	21-13740B73	.001 uF, ±5%, 50V
C0152	21-13740B50	.110 pF, ±5%, 50V
C0154	21-13741B45	.01 uF, ±5%, 50V
C0155,0156	21-13740B55	.180 pF, ±5%, 50V
C0157	21-13741B45	.01 uF, ±5%, 50V
C0158	08-11051A15	.22 uF, ±5%, 63V
C0159	21-13740B35	.27 pF, ±5%, 50V
C0160	21-13740B29	.15 pF, ±5%, 50V
C0161	21-13740B73	.001 uF, ±5%, 50V
C0162	23-11048B13	.10 uF, ±20%, 16V, electrolytic
C0163	08-11051A17	.47 uF, ±5%, 63V
C0164	21-13741B69	.1 uF, ±5%, 50V
C0165	21-13740B73	.001 uF, ±5%, 50V
C0166-0168	21-13740B49	.100 pF, ±5%, 50V
C0176	21-13740B73	.001 uF, ±5%, 50V
C0201	23-11048B13	.10 uF, ±20%, 16V, electrolytic
C0205	21-13741B49	.015 uF, ±5%, 50V
C0206	21-13740B27	.12 pF, ±5%, 50V
C0207	21-13740B29	.15 pF, ±5%, 50V
C0208	21-13740B27	.12 pF, ±5%, 50V
C0209	21-13740B23	.8.2 pF, ±5%, 50V
C0210-212	21-13740B73	.001 uF, ±5%, 50V
C0213	21-13740B19	.5.6 pF, ±5%, 50V
C0214	21-13740B13	.3.3 pF, ±5%, 50V
C0215	21-13740B73	.001 uF, ±5%, 50V
C0216	21-13740B47	.82 pF, ±5%, 50V

MXW-7404-O (2)

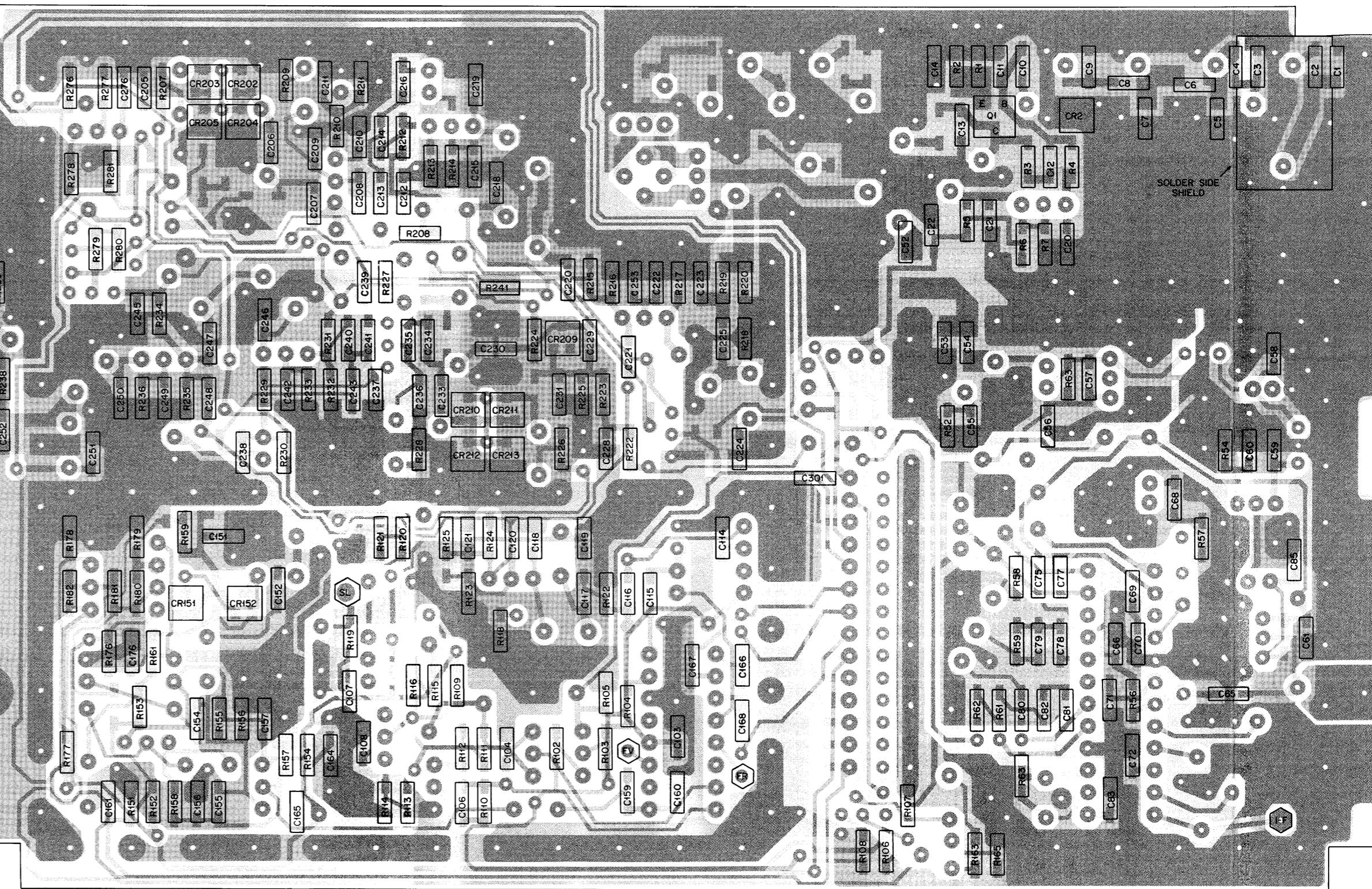
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
C0218	21-13741B45	.01 uF, ±5%, 50V
C0219	21-13740B13	.3.3 pF, ±5%, 50V
C0220	21-13740B73	.001 uF, ±5%, 50V
C0221	21-13740B05	.1.5 pF, ±5%, 50V
C0222	21-13741B45	.01 uF, ±5%, 50V
C0223	21-13740B13	.3.3 pF, ±5%, 50V
C0224,0225	21-13740B73	.001 uF, ±5%, 50V
C0228	21-13741B45	.01 uF, ±5%, 50V
C0229,0230	21-13740B05	.1.5 pF, ±5%, 50V
C0231	21-13740B38	.36 pF, ±5%, 50V
C0233	21-13740B37	.33 pF, ±5%, 50V
C0234	21-13740B29	.15 pF, ±5%, 50V
C0235,0236	21-13740B23	.8.2 pF, ±5%, 50V
C0237-0239	21-13740B73	.001 uF, ±5%, 50V
C0240	21-13740B13	.3.3 pF, ±5%, 50V
C0241	21-13740B19	.5.6 pF, ±5%, 50V
C0242	21-13740B73	.001 uF, ±5%, 50V
C0243	21-13740B47	.82 pF, ±5%, 50V
C0245	21-13740B73	.001 uF, ±5%, 50V
C0246	21-13740B13	.3.3 pF, ±5%, 50V
C0247	21-13740B73	.001 uF, ±5%, 50V
C0248	21-13740B05	.1.5 pF, ±5%, 50V
C0249	21-13741B45	.01 uF, ±5%, 50V
C0250	21-13740B17	.4.7 pF, ±5%, 50V
C0251,0252	21-13740B73	.001 uF, ±5%, 50V
C0253	21-13740B29	.15 pF, ±5%, 50V
C0276	21-13741B45	.01 uF, ±5%, 50V
C0277,0278	23-11048B19	.47 uF, ±20%, 16V, electrolytic
C0301	21-13741B45	.01 uF, ±5%, 50V
diode (see note)		
CR0001	48-80236E16	Schottky
CR002	48-80154K03	Schottky
CR0051	48-83654H01	silicon
CR0101,0102	48-83654H01	silicon
CR0151,0152	48-8000E10	silicon
CR0153,0154	48-83654H01	silicon
CR0176	48-83654H02	silicon
CR0202-0205	48-8000E10	silicon
CR0206,0207	48-84616A01	hot carrier
CR0209-0213	48-8000E10	silicon
CR0214,0215	48-84616A01	hot carrier
filter		
FL0051	91-80097D06	6 element, ceramic
FL0052	91-80098D06	3 wire, ceramic
connector receptacle		
J0004,0005	09-80135M01	2 pin coax
J0006	09-80130M03	14 position socket
RF coil		
L0001-0007	24-80148M06	82 nH, 4.5 turns
L0008	24-80063M14	1.2 uH
L0051,0052	24-80063M09	.47 uH
L0053	24-80063M04	.18 uH
L0054	24-80063M21	.47 uH
L0055	24-80164M02	1.8 turns, variable
L0056	24-80164M01	1.6 ratio, variable
L0057	24-80164M04	5.2 turns, variable
L0058	24-80063M21	.47 uH
L0059	24-80164M03	4.3 turns, variable
L0060	24-80063M14	1.2 uH
L0061	25-80000E01	transformer
L0101	24-80063M14	1.2 uH
L0102	24-11030B09	4.5 turns, brown
L0151	24-80299D01	17.75 turns, orange
L0152	24-80063M22	5.6 uH
L0202	24-80148M05	.62 nH, 3.5 turns
L0203	24-80063M14	





SIDE	RED	GAW-7714-0
SIDE	GRAY	GAW-7715-0
ERLAY	BLACK	GDW-7716-0

ENT SIDE VIEW



FR SIDE	RED	GAW-7714-0
NT SIDE	GRAY	GAW-7715-0
VERLAY	BLACK	GDW-7889-0

SOLDER SIDE VIEW

Schematic, Circuit Board Diagrams, and
Parts List for HLD4321B VHF RF Board
PW-7578-O
(Sheet 2 of 3)
3/31/90

parts list

HLD4321B MaxTrac VHF 30 kHz RF Board

MXW-7405-O

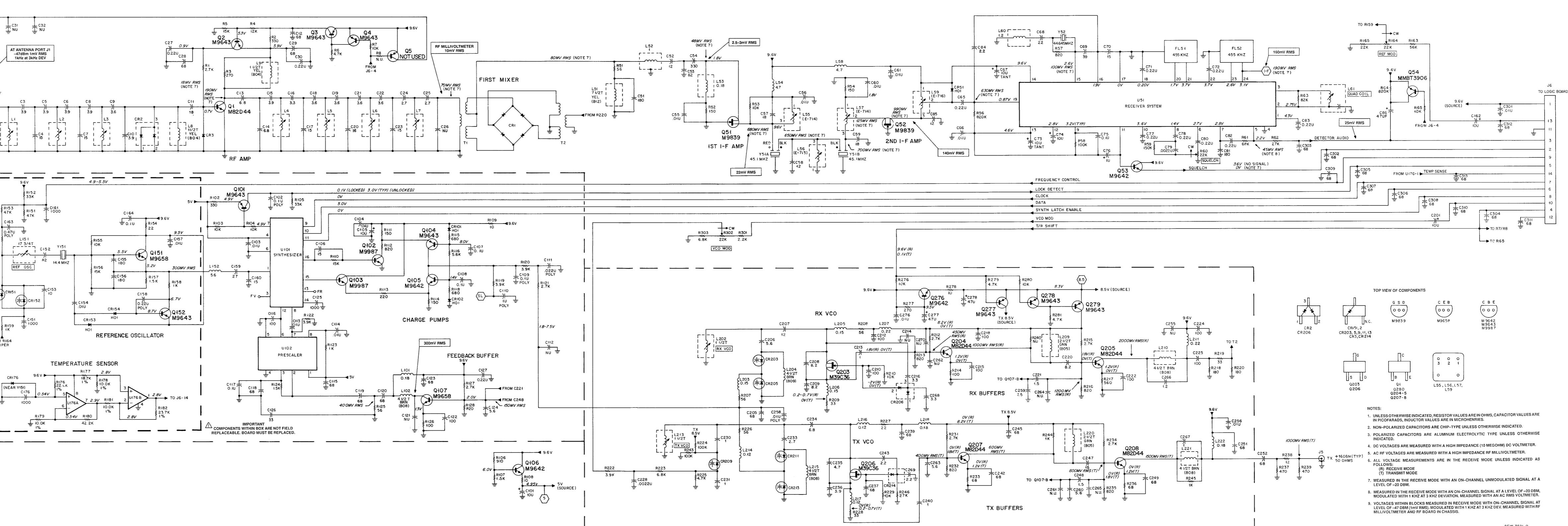
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C0001	21-13740B36	30 pF, ±5%, 50V
C0002	21-13740B43	56 pF, ±5%, 50V
C0003	21-13740B44	62 pF, ±5%, 50V
C0004	21-13740B31	18 pF, ±5%, 50V
C0005	21-13740B07	1.8 pF, ±5%, 50V
C0006	21-13740B13	3.3 pF, ±5%, 50V
C0007	21-13740B07	1.8 pF, ±5%, 50V
C0008	21-13740B31	18 pF, ±5%, 50V
C0009	21-13740B44	62 pF, ±5%, 50V
C0010	21-13740B41	347pF, ±5%, 50V
C0011	21-13740B25	10 pF, ±5%, 50V
C0012	21-13740B65	470 pF, ±5%, 50V
C0013	21-13740B31	18 pF, ±5%, 50V
C0014	21-13740B49	100 pF, ±5%, 50V
C0015	21-13740B47	82 pF, ±5%, 50V
C0016	21-13740B36	30 pF, ±5%, 50V
C0017	21-13740B47	82 pF, ±5%, 50V
C0018	21-13740B38	36 pF, ±5%, 50V
C0019	21-13740B40	43 pF, ±5%, 50V
C0020,0021	21-11032B15	.22 uF, +80, -20%, 50V
C0022	21-13740B73	.001 uF, ±5%, 50V
C0051,0052	21-13740B35	27 pF, ±5%, 50V
C0053	21-13740B47	82 pF, ±5%, 50V
C0054	21-13740B61	330 pF, ±5%, 50V
C0055,0056	21-13741B45	.01 uF, ±5%, 50V
C0057	21-13740B31	18 pF, ±5%, 50V
C0058	21-13740B27	12 pF, ±5%, 50V
C0059	21-13740B31	18 pF, ±5%, 50V
C0060,0061	21-13741B45	.01 uF, ±5%, 50V
C0065	21-11032B15	.22 uF, +80, -20%, 50V
C0066	21-13741B45	.01 uF, ±5%, 50V
C0067	23-13749C39	10 uF, ±10%, 50V, tantalum
C0068	21-13740B33	22 pF, ±5%, 50V
C0069	21-13740B39	39 pF, ±5%, 50V
C0070	21-13740B29	15 pF, ±5%, 50V
C0071,0072	21-11032B15	.22 uF, +80, -20%, 50V
C0073	23-13749C39	10 uF, ±10%, 50V, tantalum
C0074	23-11048B13	10 uF, ±20%, 16V, electrolytic
C0075	21-13741B69	.1 uF, ±5%, 50V
C0076	23-11048B05	1 uF, ±20%, 50V, electrolytic
C0077,0078	21-11032B15	.22 uF, +80, -20%, 50V
C0079	21-13741B29	.0022 uF, ±5%, 50V
C0080	21-11032B15	.22 uF, +80, -20%, 50V
C0081	21-13740B55	180 pF, ±5%, 50V
C0082,0083	21-11032B15	.22 uF, +80, -20%, 50V
C0084	21-82450B14	2.4 pF, ±5%, 500V
C0085	21-13740B27	12 pF, ±5%, 50V
C0101	23-11048B13	10 uF, ±20%, 16V, electrolytic
C0102	08-11051A13	.1 uF, ±5%, 63V
C0103,0104	21-13741B45	.01 uF, ±5%, 50V
C0105	23-11048B13	10 uF, ±20%, 16V, electrolytic
C0106	21-13740B29	15 pF, ±5%, 50V
C0107,0108	21-13741B69	.1 uF, ±5%, 50V
C0109	08-11051A13	.1 uF, ±5%, 63V
C0110	08-11051A19	1 uF, ±5%, 63V
C0111	08-11051A09	.022 uF, ±5%, 63V
C0113	08-11051A13	.1 uF, ±5%, 63V
C0114	21-13740B73	.001 uF, ±5%, 50V
C0115	21-13741B45	.01 uF, ±5%, 50V
C0116,0117	21-13740B73	.001 uF, ±5%, 50V
C0118	21-13740B29	15 pF, ±5%, 50V
C0119,0120	21-13740B73	.001 uF, ±5%, 50V
C0121	21-13740B29	15 pF, ±5%, 50V
C0151	21-13740B73	.001 uF, ±5%, 50V
C0152	21-13740B50	110 pF, ±5%, 50V
C0154	21-13741B45	.01 uF, ±5%, 50V
C0155	21-13740B55	180 pF, ±5%, 50V
C0156,0157	21-13740B55	180 pF, ±5%, 50V
C0158	08-11051A15	.22 uF, ±5%, 63V
C0159	21-13740B35	27 pF, ±5%, 50V
C0160	21-13740B29	15 pF, ±5%, 50V
C0161	21-13740B73	.001 uF, ±5%, 50V
C0162	23-11048B13	10 uF, ±20%, 16V, electrolytic
C0163	08-11051A17	.47 uF, ±5%, 63V
C0164	21-13741B69	.1 uF, ±5%, 50V
C0165	21-13740B73	.001 uF, ±5%, 50V
C0166-0168	21-13740B49	100 pF, ±5%, 50V
C0176	21-13740B73	.001 uF, ±5%, 50V
C0201	23-11048B13	10 uF, ±20%, 16V, electrolytic
C0205	21-13741B49	.015 uF, ±5%, 50V
C0206	21-13740B32	20 pF, ±5%, 50V
C0207	21-13740B25	10 pF, ±5%, 50V
C0208,0209	21-13740B23	8.2 pF, ±5%, 50V
C0210-0212	21-13740B73	.001 uF, ±5%, 50V
C0213	21-13740B17	4.7 pF, ±5%, 50V
C0214	21-13740B09	2.2 pF, ±5%, 50V
C0215	21-13740B73	.001 uF, ±5%, 50V
C0216	21-13740B47	82 pF, ±5%, 50V
C0218	21-13741B45	.01 uF, ±5%, 50V
C0219	21-13740B13	3.3 pF, ±5%, 50V
C0220	21-13740B73	.001 uF, ±5%, 50V
C0221	21-13740B09	2.2 pF, ±5%, 50V
C0222	21-13741B45	.01 uF, ±5%, 50V
C0223	21-13740B13	3.3 pF, ±5%, 50V
C0224,0225	21-13740B73	.001 uF, ±5%, 50V
C0228	21-13741B45	.01 uF, ±5%, 50V
C0229,0230	21-13740B05	1.5 pF, ±5%, 50V
C0231	21-13740B38	36 pF, ±5%, 50V
C0233	21-13740B38	36 pF, ±5%, 50V

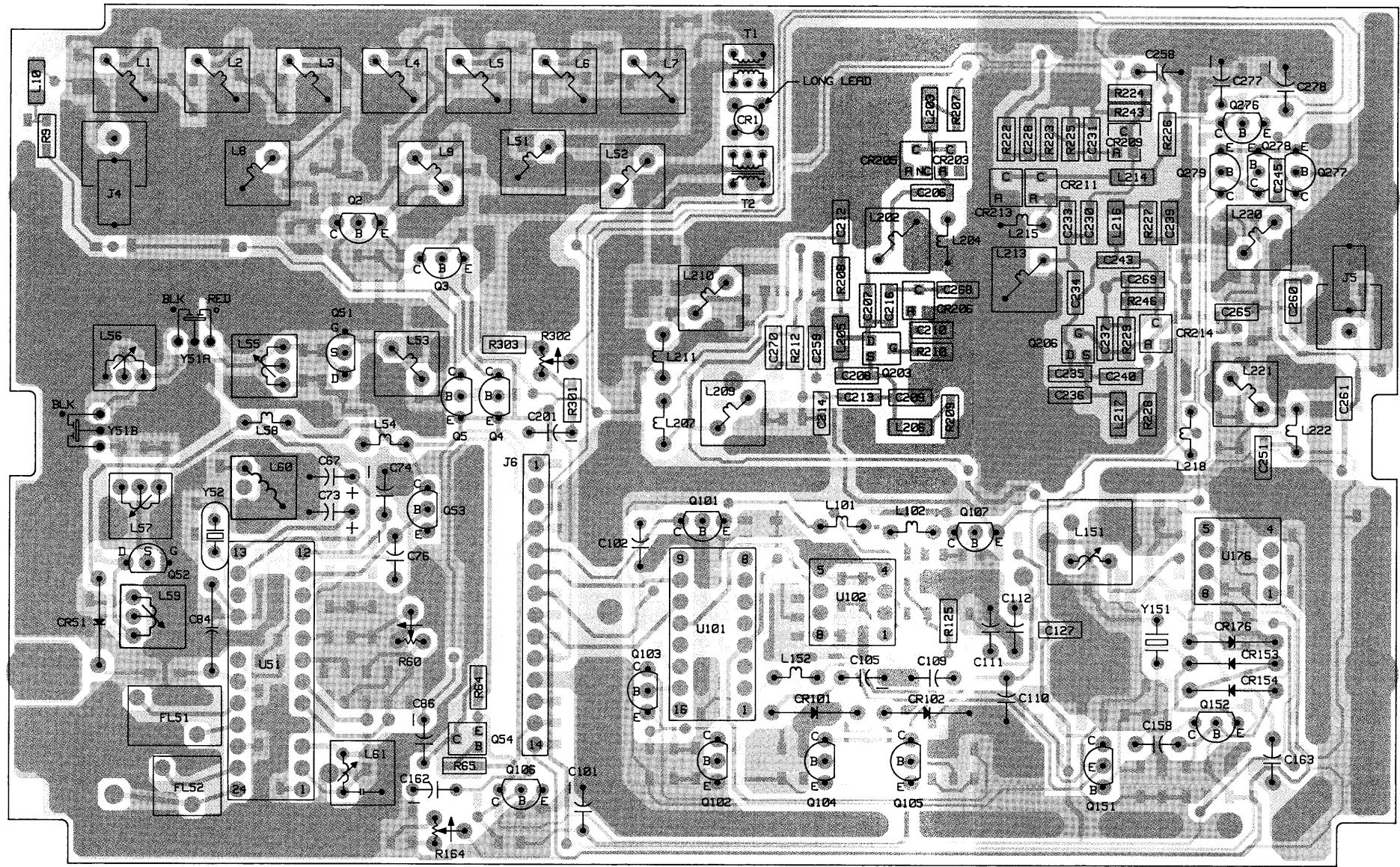
MXW-7405-O (2)

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C0234	21-13740B29	15 pF, ±5%, 50V
C0235,0236	21-13740B23	8.2 pF, ±5%, 50V
C0237-0239	21-13740B73	.001 uF, ±5%, 50V
C0240	21-13740B09	2.2 pF, ±5%, 50V
C0241	21-13740B17	4.7 pF, ±5%, 50V
C0242	21-13740B73	.001 uF, ±5%, 50V
C0243	21-13740B47	82 pF, ±5%, 50V
C0245	21-13740B73	.001 uF, ±5%, 50V
C0247	21-13740B73	.001 uF, ±5%, 50V
C0248	21-13740B05	1.5 pF, ±5%, 50V
C0249	21-13741B45	.01 uF, ±5%, 50V
C0250	21-13740B17	4.7 pF, ±5%, 50V
C0251,0252	21-13740B73	.001 uF, ±5%, 50V
C0276	21-13741B45	.01 uF, ±5%, 50V
C0277,0278	23-11048B19	47 uF, ±20%, 16V, electrolytic
C0301	21-13741B45	.01 uF, ±5%, 50V
diode (see note)		
CR0001	48-80236E16	Schottky
CR0002	48-80154K03	Schottky
CR0051	48-83654H01	silicon
CR0101,0102	48-83654H01	silicon
CR0151,0152	48-80006E10	silicon
CR0153,0154	48-83654H01	silicon
CR0176	48-83654H02	silicon
CR0202-0205	48-05129M21	silicon
CR0206,0207	48-84616A01	hot carrier
CR0209-0213	48-05129M21	silicon
CR0214,0215	48-84616A01	hot carrier
filter		
FL0051	91-80097D06	6 element, ceramic
FL0052	91-80098D06	3 wire, ceramic
connector receptacle		
J0004,0005	09-80135M01	2 pin coax
J0006	09-80130M03	14 position socket
RF coil		
L0001-0007	24-80148M06	82 nH, 4.5 turns
L0008	24-80063M14	1.2 uH
L0051,0052	24-80063M09	.47 uH
L0053	24-80063M04	.18 uH
L0054	24-80063M21	4.7 uH
L0055	24-80164M02	1.8 turns, variable
L0056	24-80164M01	1:6 ratio, variable
L0057	24-80164M04	5.2 turns, variable
L0058	24-80063M21	4.7 uH
L0059	24-80164M03	4.3 turns, variable
L0060	24-80063M14	1.2 uH
L0061	25-80000E01	transformer
L0101	24-80063M14	1.2 uH
L0102	24-11030B09	4.5 turns, brown
L0151	24-80299D01	17.75 turns, orange
L0152	24-80063M22	5.6 uH
L0202	24-80148M05	62 nH, 3.5 turns
L0203	24-80063M1	

MaxTrac UHF RF Board Transistor D.C. Voltage Table

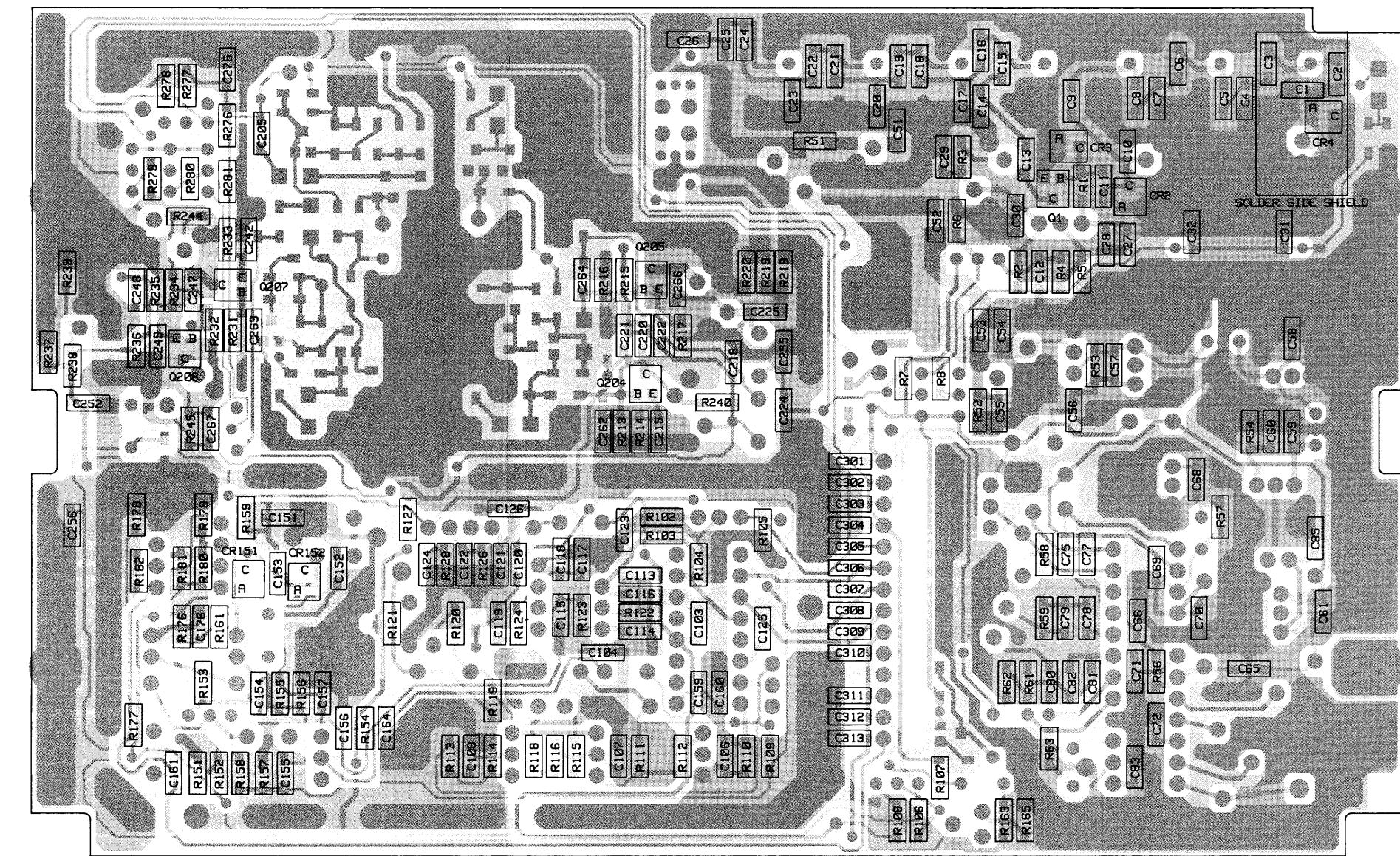
Transistor Ref. No.	VOLTAGE			VOLTAGE		
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN
Q1	.7	0	5.9	—	—	—
Q2	5.3	5.9	.9	—	—	—
Q51	—	—	—	0	1.8	9.6
Q52	—	—	—	0	1.8	9.6
Q53	0	0 (W/SIG)	9.6	—	—	—
Q101	5.0	4.9	.1 (LOCKED)	—	—	—
Q102	.7	0	0.1	—	—	—
Q103	5.0	4.4	9.6	—	—	—
Q104	8.1	2.8v	2-8v	—	—	—
Q105	1.4	VAR.	2-8v	—	—	—
Q106	6.0	5.0	9.6	—	—	—
Q107	2.0	1.3	9.6	—	—	—
Q151	5.5	5.2	9.5	—	—	—
Q152	8.7	9.5	6.7	—	—	—
Q201	—	9.6	0(U) 9.3(L)	U=UPPER L=LOWER RANGE	—	—
Q202	0(U).7(L)	0	6.7(U)0(L)	—	—	—
Q203	—	—	2.6(R)	4.8(R)	7.9(R)	—
Q204	1.8(R)	1.2(R)	8.2(R)	—	—	—
Q205	1.8(R)	1.2(R)	9.6	—	—	—
Q206	—	—	—5(T)	1.1(T)	7.8(T)	—
Q207	1.8(T)	1.2(T)	8.5(T)	—	—	—
Q208	1.8(T)	1.2(T)	9.6	—	—	—
Q209	9.5	8.6	9.6	—	—	—
Q210	9.6	8.5(T)	8.5	—	—	—
Q211	9.6	8.3	7.6(R)	—	—	—
Q212	7.6(R)	8.5	8.5	—	—	—





COMPONENT SIDE VIEW

SOLDER SIDE GCW-7617-O
 COMPONENT SIDE GCW-7616-O
 OVERLAY GCW-7618-O



SOLDER SIDE VIEW

SOLDER SIDE GCW-7617-O
 COMPONENT SIDE GCW-7616-O
 OVERLAY GCW-7619-O

parts list

HLE9310A UHF RF Board

MXW-7406-O

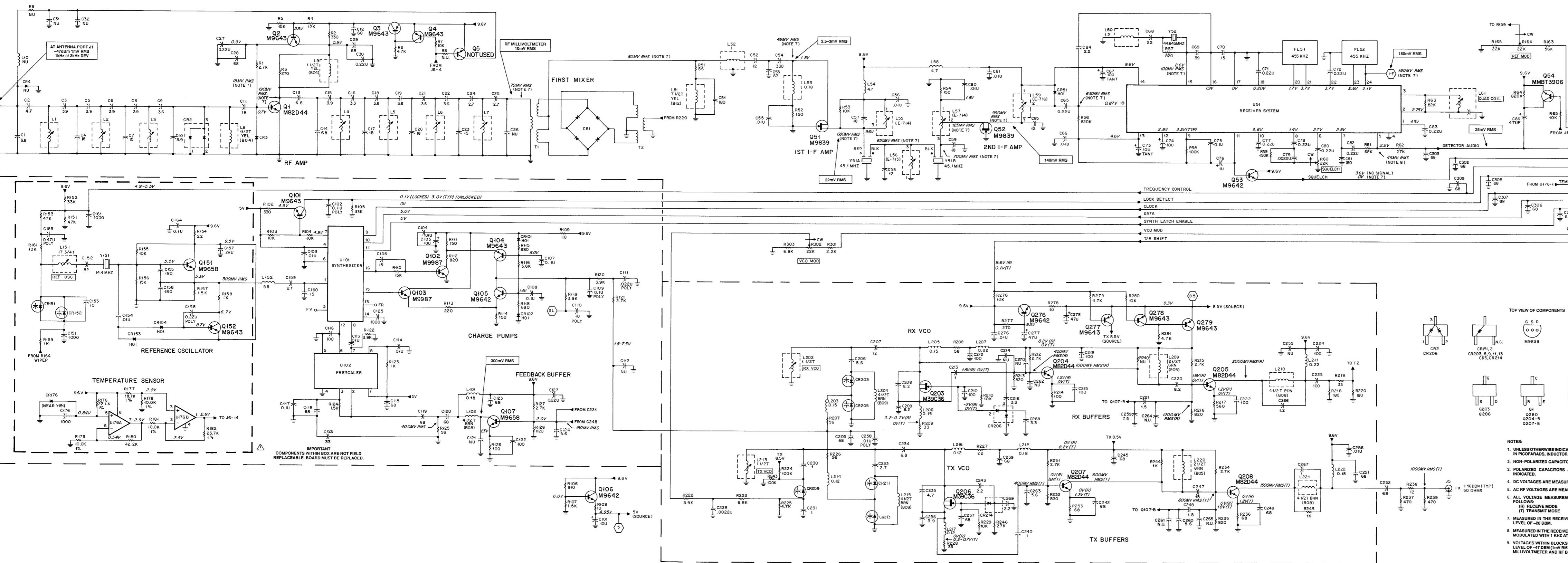
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C1	21-13740B21	6.8 pF, ±5%, 50V
C2	21-13740B17	4.7 pF, ±5%, 50V
C3	21-13740B15	3.9 pF, ±5%, 50V
C4	21-13740B29	15 pF, ±5%, 50V
C5,6	21-13740B15	3.9 pF, ±5%, 50V
C7	21-13740B29	15 pF, ±5%, 50V
C8	21-13740B15	3.9 pF, ±5%, 50V
C9	21-13740B14	3.6 pF, ±5%, 50V
C10	21-13740B15	3.9 pF, ±5%, 50V
C11	21-13740B31	18 pF, ±5%, 50V
C12	21-13740B45	68 pF, ±5%, 50V
C13,14	21-13740B21	6.8 pF, ±5%, 50V
C15	21-13740B15	3.9 pF, ±5%, 50V
C16	21-13740B13	3.3 pF, ±5%, 50V
C17	21-13740B29	15 pF, ±5%, 50V
C18,19	21-13740B14	3.6 pF, ±5%, 50V
C20	21-13740B30	16 pF, ±5%, 50V
C21,22	21-13740B14	3.6 pF, ±5%, 50V
C23	21-13740B29	15 pF, ±5%, 50V
C24,25	21-13740B11	2.7 pF, ±5%, 50V
C27	21-11032B15	.22 uF, +80, -20%, 50V
C28,29	21-13740B45	68 pF, ±5%, 50V
C30	21-11032B15	.22 uF, +80, -20%, 50V
C51	21-13740B55	180 pF, ±5%, 50V
C52	21-13740B27	12 pF, ±5%, 50V
C53	21-13740B47	82 pF, ±5%, 50V
C54	21-13740B61	330 pF, ±5%, 50V
C55,56	21-13741B45	.01 uF, ±5%, 50V
C57	21-13740B31	18 pF, ±5%, 50V
C58	21-13740B27	12 pF, ±5%, 50V
C59	21-13740B31	10 pF, ±5%, 50V
C60,61	21-13741B45	.01 uF, ±5%, 50V
C65	21-11032B15	.22 uF, +80, -20%, 50V
C66	21-13741B45	.01 uF, ±5%, 50V
C67	23-13749C39	10 uF, ±10%, 50V, tantalum
C68	21-13740B33	22 pF, ±5%, 50V
C69	21-13740B39	38 pF, ±5%, 50V
C70	21-13740B29	15 pF, ±5%, 50V
C71	21-11032B15	.22 uF, +80, -20%, 50V
C72	21-11032B15	.22 uF, +80, -20%, 50V
C73	23-13749C39	10 uF, ±10%, 50V, tantalum
C74	23-11048B13	10 uF, ±20%, 16V, electrolytic
C75	21-13741B69	.1 uF, ±5%, 50V
C76	23-11048B05	1 uF, ±20%, 50V, electrolytic
C77,78	21-11032B15	.22 uF, +80, -20%, 50V
C79	21-13741B29	.0022 uF, ±5%, 50V
C80	21-11032B15	.22 uF, +80, -20%, 50V
C81	21-13740B55	180 pF, ±5%, 50V
C82,83	21-11032B15	.22 uF, +80, -20%, 50V
C84	21-13740B09	2.2 pF, ±5%, 50V
C85	21-13740B27	12 pF, ±5%, 50V
C86	23-11048B49	.47 uF, ±20%, 16V, electrolytic
C101	23-11048B13	10 uF, ±20%, 16V, electrolytic
C102	08-11051A13	.1 uF, ±5%, 63V
C103,104	21-13741B45	.01 uF, ±5%, 50V
C105	23-11048B13	10 uF, ±20%, 16V, electrolytic
C106	21-13740B29	15 pF, ±5%, 50V
C107,108	21-13741B69	.1 uF, ±5%, 50V
C109	08-11051A13	.1 uF, ±5%, 63V
C110	08-11051A19	1 uF, ±5%, 63V
C111	08-11051A09	.022 uF, ±5%, 63V
C113-114	21-13741B45	.01 uF, ±5%, 50V
C115	21-13740B45	.68 pF, ±5%, 50V
C116	21-13740B49	100 pF, ±5%, 50V
C117	21-13741B69	.1 uF, ±5%, 50V
C118-120	21-13740B45	.68 pF, ±5%, 50V
C121		not used
C122	21-13740B49	100 pF, ±5%, 50V
C123	21-13740B45	.68 pF, ±5%, 50V
C124	21-13740B19	5.6 pF, ±5%, 50V
C125	21-13740B73	.001 uF, ±5%, 50V
C126	21-13740B37	33 pF, ±5%, 50V
C127	21-11032B15	.22 uF, +80, -20%, 50V
C151	21-13740B73	.001 uF, ±5%, 50V
C152	21-13740B47	.82 pF, ±5%, 50V
C153	21-13740B25	10 pF, ±5%, 50V
C154	21-13741B45	.01 uF, ±5%, 50V
C155,156	21-13740B55	180 pF, ±5%, 50V
C157	21-13741B45	.01 uF, ±5%, 50V
C158	08-11051A15	.22 uF, ±5%, 63V
C159	21-13740B35	.27 pF, ±5%, 50V
C160	21-13740B29	15 pF, ±5%, 50V
C161	21-13740B73	.001 uF, ±5%, 50V
C162	23-11048B13	10 uF, ±20%, 16V, electrolytic
C163	08-11051A17	.47 uF, ±5%, 63V
C164	21-13741B69	.1 uF, ±5%, 50V
C165		not used
C166		not used
C167		not used
C168		not used
C176	21-13740B73	.001 uF, ±5%, 50V
C201	23-11048B13	10 uF, ±20%, 16V, electrolytic
C205	21-13740B45	.68 pF, ±5%, 50V
C206	21-13740B19	5.6 pF, ±5%, 50V
C207	21-13740B27	12 pF, ±5%, 50V
C208,209	21-13740B23	8.2 pF, ±5%, 50V
C210	21-13740B49	100 pF, ±5%, 50V
C211		not used
C212	21-13740B49	100 pF, ±5%, 50V

MXW-7406-O

MXW-7406-O (2)

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C213	21-13740B01	1 pF, ±5%, 50V
C121		not used
C215	21-13740B49	100 pF, ±5%, 50V
C216	21-13740B13	3.3 pF, ±5%, 50V
C218	21-13741B49	100 pF, ±5%, 50V
C219		not used
C220	21-13740B23	8.2 pF, ±5%, 50V
C221	21-13740B05	1.5 pF, ±5%, 50V
C222	21-13740B49	100 pF, ±5%, 50V
C223		not used
C224,225	21-13740B49	100 pF, ±5%, 50V
C228	21-13741B29	.0022 uF, ±5%, 50V
C229		not used
C230,231	21-13740B01	1 pF, ±5%, 50V
C231	21-13740B11	2.7 pF, ±5%, 50V
C233	21-13740B11	1 pF, ±5%, 50V
C234	21-13740B21	6.8 pF, ±5%, 50V
C235	21-13740B17	4.7 pF, ±5%, 50V
C236	21-13740B15	3.9 pF, ±5%, 50V
C237	21-13740B45	68 pF, ±5%, 50V
C238		not used
C239	21-13740B45	68 pF, ±5%, 50V
C240	21-13740B01	1 pF, ±5%, 50V
C241		not used
C242	21-13740B45	68 pF, ±5%, 50V
C243	21-13740B09	2.2 pF, ±5%, 50V
C245	21-13740B45	68 pF, ±5%, 50V
C246		not used
C247	21-13740B29	15 pF, ±5%, 50V
C248	21-13740B05	1.5 pF, ±5%, 50V
C250	21-13740B45	68 pF, ±5%, 50V
C251,252	21-13740B45	68 pF, ±5%, 50V
C253		not used
C256	21-13741B45	.01 uF, ±5%, 50V
C258	08-11051A07	.01 uF, ±5%, 63V
C259	21-13740B22	7.5 pF, ±5%, 50V
C260	21-13740B19	5.6 pF, ±5%, 50V
C263	21-13740B19	5.6 pF, ±5%, 50V
C266	21-13740B03	1.2 pF, ±5%, 50V
C267	21-13740B01	1 pF, ±5%, 50V
C268	21-13740B13	3.3 pF, ±5%, 50V
C269	21-13740B09	2.2 pF, ±5%, 50V
C276	21-13741B45	.01 uF, ±5%, 50V
C277,278	23-11048B19	.47 uF, ±20%, 16V, electrolytic
C301	21-13741B45	.01 uF, ±5%, 50V
C302-313	21-13740B45	68 pF, ±5%, 50V
diode (see note)		
CR1	48-80236E16	Schottky
CR2	48-80154K02	Schottky
CR3	48-80939T01	Schottky
CR51	48-83654H01	silicon
CR101,102	48-83654H01	silicon
CR151,152	48-05129M21	varactor
CR153,154	48-83654H01	silicon
CR176	48-83654H02	silicon
CR203	48-84534N02	varactor
CR205	48-84534N02	varactor
CR206	48-80154K02	Schottky
CR209	48-84534N02	varactor
CR211	48-84534N02	varactor
CR213	48-84534N02	varactor
CR214	48-80939T01	Schottky

UHF RF Board Transistor D.C. Volta

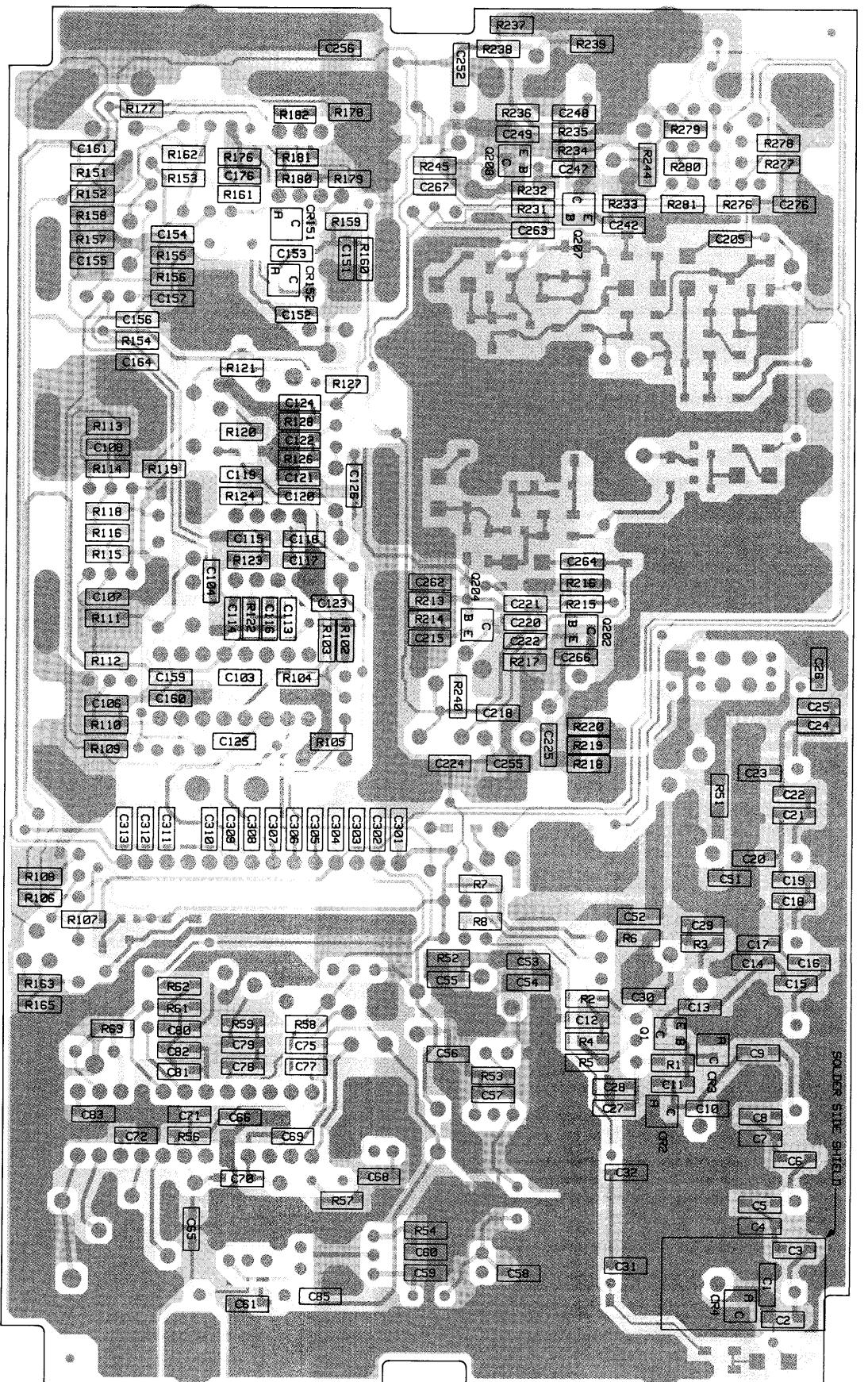


Transistor Ref. No.	VOLTAGE			VOLTAGE		
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN
Q1	.7	0	5.9	—	—	—
Q2	5.3	5.9	.9	—	—	—
Q51	—	—	—	0	1.8	9.6
Q52	—	—	—	0	1.8	9.6
Q53	0	0 (W/ SIG)	9.6	—	—	—
Q101	5.0	4.9	.1 (LOCKED)	—	—	—
Q102	.7	0	0.1	—	—	—
Q103	5.0	4.4	9.6	—	—	—
Q104	8.1	2.8v	2-8v	—	—	—
Q105	1.4	VAR.	2-8v	—	—	—
Q106	6.0	5.0	9.6	—	—	—
Q107	2.0	1.3	9.6	—	—	—
Q151	5.5	5.2	9.5	—	—	—
Q152	8.7	9.5	6.7	—	—	—
Q201	—	9.6	0(U) 9.3(L)	U=UPPER L=LOWER RANGE		
Q202	0(U).7(L)	0	6.7(U)0(L)	—	—	—
Q203	—	—	—	2.6(R)	4.8(R)	7.9(R)
Q204	1.8(R)	1.2(R)	8.2(R)	—	—	—
Q205	1.8(R)	1.2(R)	9.6	—	—	—
Q206	—	—	—	-.5(T)	1.1(T)	7.8(T)
Q207	1.8(T)	1.2(T)	8.5(T)	—	—	—
Q208	1.8(T)	1.2(T)	9.6	—	—	—
Q276	9.5	8.6	9.6	—	—	—
Q277	9.6	8.5(T)	8.5	—	—	—
Q278	9.6	8.3	7.6(R)	—	—	—
Q279	7.6(R)	8.5	8.5	—	—	—

- HMS, CAPACITANCE, TYPE UNLESS OTHERWISE INDICATED. MEGOHM) OR RF MILLIVOLTS. CODE UNLESS OTHERWISE INDICATED. UNMODULATED SIGNAL AT A FREQUENCY OF 100 KHZ WITH AN AC COUPLED INPUT. WITH ON-CHANNEL AND OFF-CHANNEL KHZ DEV. M

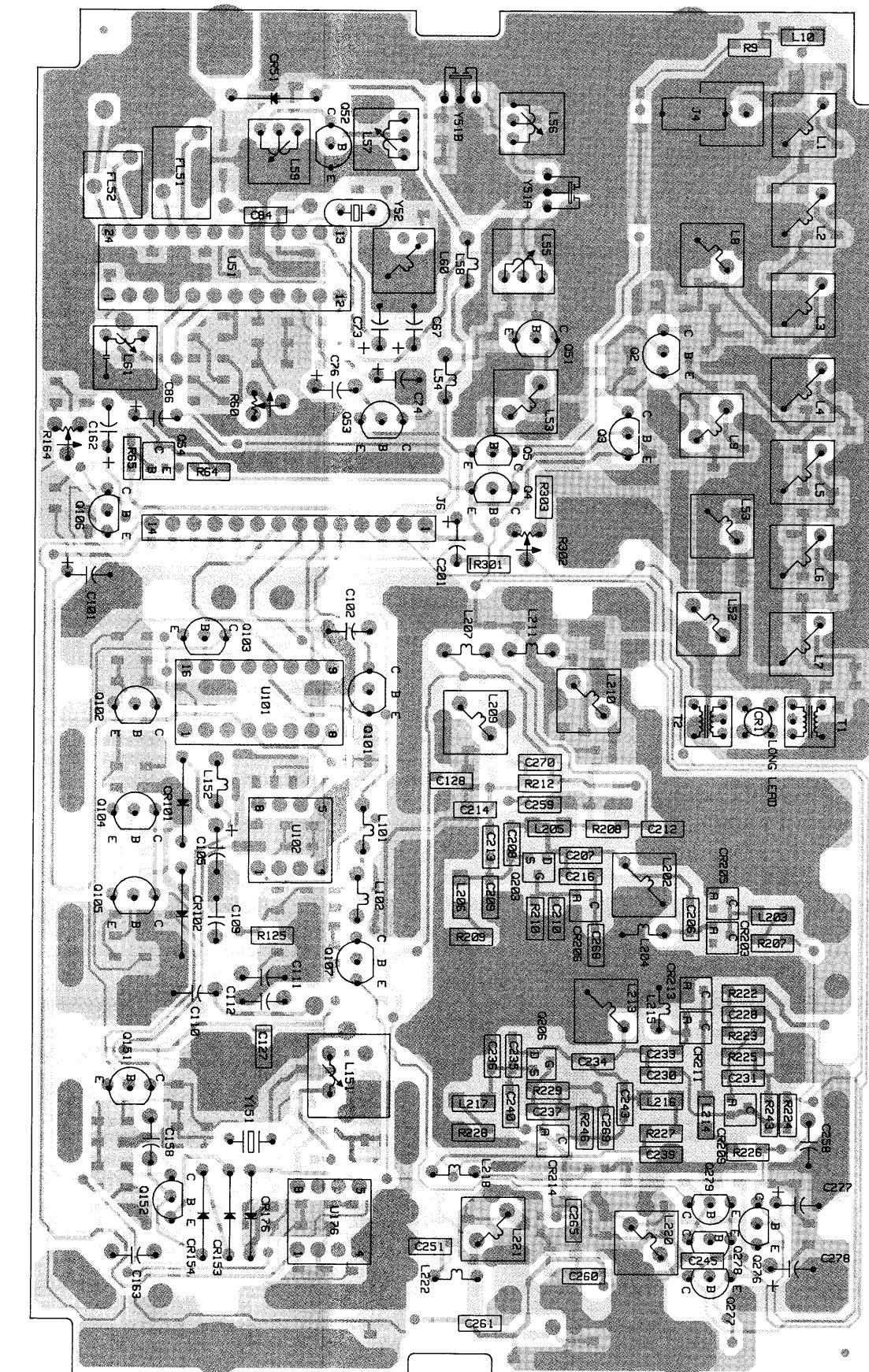
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SOLDER SIDE VIEW

Schematic, Circuit Board Diagrams, and
Parts List for HLE9310B UHF RF Board
PW-7582-O
(Sheet 2 of 3)
3/31/90



COMPONENT SIDE VIEW

SOLDER SIDE	RED	GAW-7704-O
COMPONENT SIDE	GREY	GAW-7705-O
OVERLAYS	BLACK	GDW-7706-O

parts list

HLE9310B UHF RF Board

MXW-7584-O

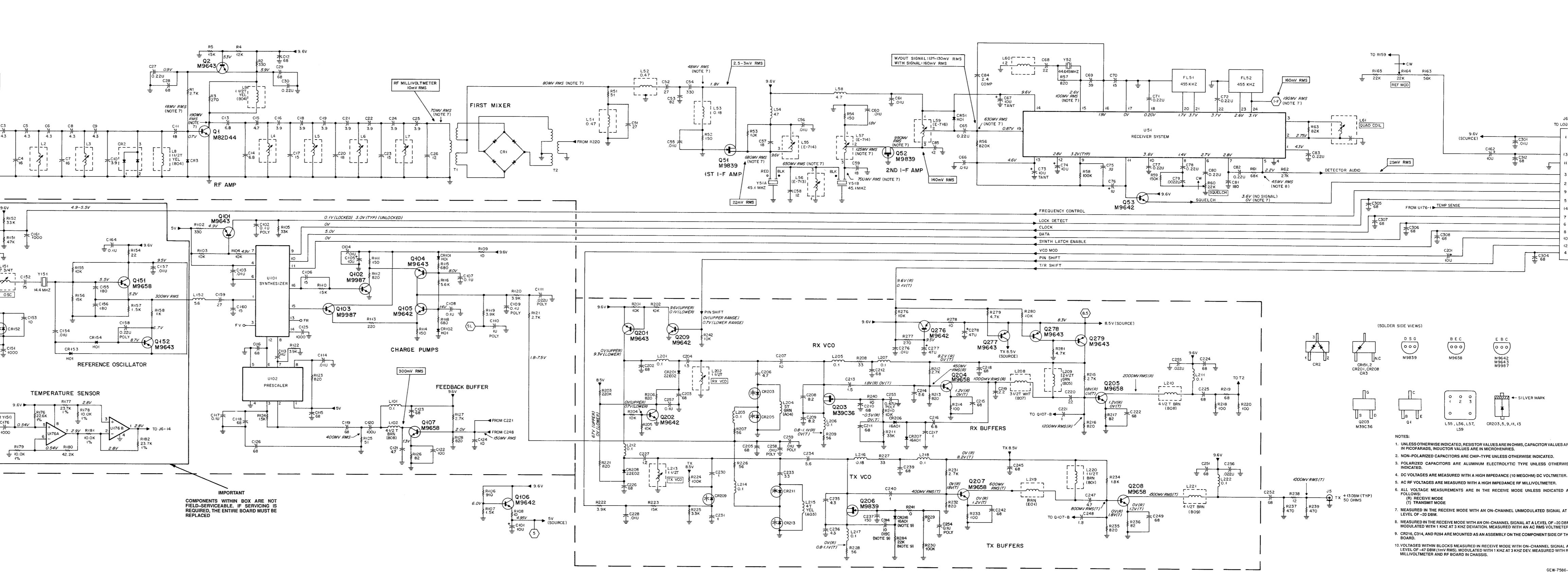
MXW-7584-O (2)

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C1	21-13740B21	6.8 pF, ±5%, 50V
C2	21-13740B17	4.7 pF, ±5%, 50V
C3	21-13740B15	3.9 pF, ±5%, 50V
C4	21-13740B29	15 pF, ±5%, 50V
C5..6	21-13740B15	3.9 pF, ±5%, 50V
C7	21-13740B29	15 pF, ±5%, 50V
C8	21-13740B15	3.9 pF, ±5%, 50V
C9	21-13740B14	3.6 pF, ±5%, 50V
C10	21-13740B15	3.9 pF, ±5%, 50V
C11	21-13740B31	18 pF, ±5%, 50V
C12	21-13740B45	68 pF, ±5%, 50V
C13..14	21-13740B21	6.8 pF, ±5%, 50V
C15	21-13740B15	3.9 pF, ±5%, 50V
C16	21-13740B13	3.3 pF, ±5%, 50V
C17	21-13740B29	15 pF, ±5%, 50V
C18..19	21-13740B14	3.6 pF, ±5%, 50V
C20	21-13740B30	16 pF, ±5%, 50V
C21..22	21-13740B14	3.6 pF, ±5%, 50V
C23	21-13740B29	15 pF, ±5%, 50V
C24..25	21-13740B11	2.7 pF, ±5%, 50V
C27	21-11032B15	.22 uF, +80, -20%, 50V
C28..29	21-13740B45	68 pF, ±5%, 50V
C30	21-11032B15	.22 uF, +80, -20%, 50V
C51	21-13740B55	180 pF, ±5%, 50V
C52	21-13740B27	12 pF, ±5%, 50V
C53	21-13740B47	82 pF, ±5%, 50V
C54	21-13740B61	330 pF, ±5%, 50V
C55..56	21-13741B45	.01 uF, ±5%, 50V
C57	21-13740B31	18 pF, ±5%, 50V
C58	21-13740B27	12 pF, ±5%, 50V
C59	21-13740B31	18 pF, ±5%, 50V
C60..61	21-13741B45	.01 uF, ±5%, 50V
C65	21-11032B15	.22 uF, +80, -20%, 50V
C66	21-13741B45	.01 uF, ±5%, 50V
C67	23-13749C39	10 uF, ±10%, 50V, tantalum
C68	21-13740B33	22 pF, ±5%, 50V
C69	21-13740B39	39 pF, ±5%, 50V
C70	21-13740B29	15 pF, ±5%, 50V
C71	21-11032B15	.22 uF, +80, -20%, 50V
C72	21-11032B15	.22 uF, +80, -20%, 50V
C73	23-13749C39	10 uF, ±10%, 50V, tantalum
C74	23-11048B13	10 uF, ±20%, 16V, electrolytic
C75	21-13741B69	.1 uF, ±5%, 50V
C76	23-11048B05	1 uF, ±20%, 50V, electrolytic
C77..78	21-11032B15	.22 uF, +80, -20%, 50V
C79	21-13741B29	.0022 uF, ±5%, 50V
C80	21-11032B15	.22 uF, +80, -20%, 50V
C81	21-13740B55	180 pF, ±5%, 50V
C82..83	21-11032B15	.22 uF, ±80, -20%, 50V
C84	21-13740B09	2.2 pF, ±5%, 50V
C85	21-13740B27	12 pF, ±5%, 50V
C86	23-11048B49	47 uF, ±20%, 16V, electrolytic
C101	23-11048B13	10 uF, ±20%, 16V, electrolytic
C102	08-11051A13	.1 uF, ±5%, 63V
C103..104	21-13741B45	.01 uF, ±5%, 50V
C105	23-11048B13	10 uF, ±20%, 16V, electrolytic
C106	21-13740B29	15 pF, ±5%, 50V
C107..108	21-13741B69	.1 uF, ±5%, 50V
C109	08-11051A13	.1 uF, ±5%, 63V
C110	08-11051A19	1 uF, ±5%, 63V
C111	08-11051A09	.022 uF, ±5%, 63V
C113..114	21-13741B45	.01 uF, ±5%, 50V
C115	21-13740B45	68 pF, ±5%, 50V
C116	21-13740B49	100 pF, ±5%, 50V
C117	21-13741B69	.1 uF, ±5%, 50V
C118..120	21-13740B45	68 pF, ±5%, 50V
C121	not used	
C122	21-13740B49	100 pF, ±5%, 50V
C123	21-13740B45	68 pF, ±5%, 50V
C124	21-13740B19	5.6 pF, ±5%, 50V
C125	21-13740B73	.001 uF, ±5%, 50V
C126	21-13740B37	33 pF, ±5%, 50V
C127	21-11032B15	.22 uF, +80, -20%, 50V
C151	21-13740B73	.001 uF, ±5%, 50V
C152	21-13740B47	82 pF, ±5%, 50V
C153	21-13740B25	10 pF, ±5%, 50V
C154	21-13741B45	.01 uF, ±5%, 50V
C155..156	21-13740B55	180 pF, ±5%, 50V
C157	21-13741B45	.01 uF, ±5%, 50V
C158	08-11051A15	.22 uF, ±5%, 63V
C159	21-13740B35	27 pF, ±5%, 50V
C160	21-13740B29	15 pF, ±5%, 50V
C161	21-13740B73	.001 uF, ±5%, 50V
C162	23-11048B13	10 uF, ±20%, 16V, electrolytic
C163	08-11051A17	.47 uF, ±5%, 63V
C164	21-13741B69	.1 uF, ±5%, 50V
C165	not used	
C166	not used	
C167	not used	
C168	21-13740B73	.001 uF, ±5%, 50V
C201	23-11048B13	10 uF, ±20%, 16V, electrolytic
C205	21-13740B45	68 pF, ±5%, 50V
C206	21-13740B19	5.6 pF, ±5%, 50V
C207	21-13740B27	12 pF, ±5%, 50V
C208..209	21-13740B23	8.2 pF, ±5%, 50V
C210	21-13740B49	100 pF, ±5%, 50V
C211	not used	
C212	21-13740B49	100 pF, ±5%, 50V

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C213	21-13740B01	1 pF, ±5%, 50V
C211	not used	
C215	21-13740B49	100 pF, ±5%, 50V
C216	21-13740B13	3.3 pF, ±5%, 50V
C218	21-13741B49	100 pF, ±5%, 50V
C219	not used	
C220	21-13740B23	8.2 pF, ±5%, 50V
C221	21-13740B05	1.5 pF, ±5%, 50V
C222	21-13740B49	100 pF, ±5%, 50V
C223	not used	
C224..225	21-13740B49	100 pF, ±5%, 50V
C228	21-13741B29	.0022 uF, ±5%, 50V
C229	not used	
C230..231	21-13740B01	1 pF, ±5%, 50V
C233	21-13740B11	2.7 pF, ±5%, 50V
C234	21-13740B21	6.8 pF, ±5%, 50V
C235	21-13740B17	4.7 pF, ±5%, 50V
C236	21-13740B15	3.9 pF, ±5%, 50V
C237	21-13740B45	68 pF, ±5%, 50V
C238	not used	
C239	21-13740B45	68 pF, ±5%, 50V
C240	21-13740B01	1 pF, ±5%, 50V
C241	not used	
C242	21-13740B45	68 pF, ±5%, 50V
C243	21-13740B09	2.2 pF, ±5%, 50V
C245	21-13740B45	68 pF, ±5%, 50V
C246	not used	
C247	21-13740B29	15 pF, ±5%, 50V
C248	21-13740B05	1.5 pF, ±5%, 50V
C249	21-13740B45	68 pF, ±5%, 50V
C250	not used	
C251..252	21-13740B45	68 pF, ±5%, 50V
C253	not used	
C256	21-13741B45	.01 uF, ±5%, 50V
C258	08-11051A07	.01 uF, ±5%, 63V
C259	21-13740B22	7.5 pF, ±5%, 50V
C260	21-13740B19	5.6 pF, ±5%, 50V
C263	21-13740B19	5.6 pF, ±5%, 50V
C266	21-13740B03	1.2 pF, ±5%, 50V
C267	21-13740B01	1 pF, ±5%, 50V
C268	21-13740B13	3.3 pF, ±5%, 50V
C269	21-13740B09	2.2 pF, ±5%, 50V
C276	21-13741B45	.01 uF, ±5%, 50V
C277..278	23-11048B19	47 uF, ±20%, 16V, electrolytic
C301	21-13741B45	.01 uF, ±5%, 50V
C302..313	21-13740B45	68 pF, ±5%, 50V
diode (see note)		
CR1	48-80236E16	Schottky
CR2	48-80154K02	Schottky
CR3	48-80939T01	Schottky
CR51	48-83654H01	silicon
CR101..102	48-83654H01	silicon
CR151..152	48-05129M21	varactor
CR153..154	48-83654H01	silicon
CR176	48-82256C11	zener
CR203	48-84534N02	varactor
CR205	48-84534N02	varactor
CR206	48-80154K02	Schottky
CR209	48-84534N02	varactor
CR211	48-84534N02	varactor
CR213	48-80939T01	Schottky
filter		
FL51	91-80097D06	6 element, ceramic
FL52	91-80098D06	3 element, ceramic

UHF RF Board Transistor D.C. Voltage Table

Transistor Ref. No.	VOLTAGE		VOLTAGE				
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN	
Q1	.7	0	5.9	—	—	—	
Q2	5.3	5.9	.9	—	—	—	
Q51	—	—	—	0	1.8	9.6	
Q52	—	—	—	0	1.8	9.6	
Q53	0	0 (W SIG)	9.6	.1 (LOCKED)	—	—	
Q101	5.0	4.9	.1 (LOCKED)	—	—	—	
Q102	.7	0	0.1	—	—	—	
Q103	5.0	4.4	9.6	—	—	—	
Q104	8.1	2.8V	2-8V	—	—	—	
Q105	1.4	VAR.	2-8V	—	—	—	
Q106	6.0	5.0	9.6	—	—	—	
Q107	2.0	1.3	9.6	—	—	—	
Q151	5.5	5.2	9.5	—	—	—	
Q152	8.7	9.5	6.7	—	—	—	
Q201	—	9.6	0(U) 9.3(L)	U-UPPER L-LOWER RANGE			
Q202	0(U),7(L)	0	6.7(U)(L)	—	—	—	
Q203	—	—	2.6(R)	4.8(R)	7.9(R)	—	
Q204	1.8(R)	1.2(R)	8.2(R)	—	—	—	
Q205	1.8(R)	1.2(R)	9.6	—	—	—	
Q206	—	—	—5(T)	1.1(T)	7.8(T)	—	
Q207	1.8(T)	1.2(T)	8.5(T)	—	—	—	
Q208	1.8(T)	1.2(T)	9.6	—	—	—	
Q276	9.5	8.6	9.6	—	—	—	
Q277	9.6	8.5(T)	8.5	—	—	—	
Q278	9.6	8.3	7.6(R)	—	—	—	
Q279	7.6(R)	8.5	8.5	—	—	—	



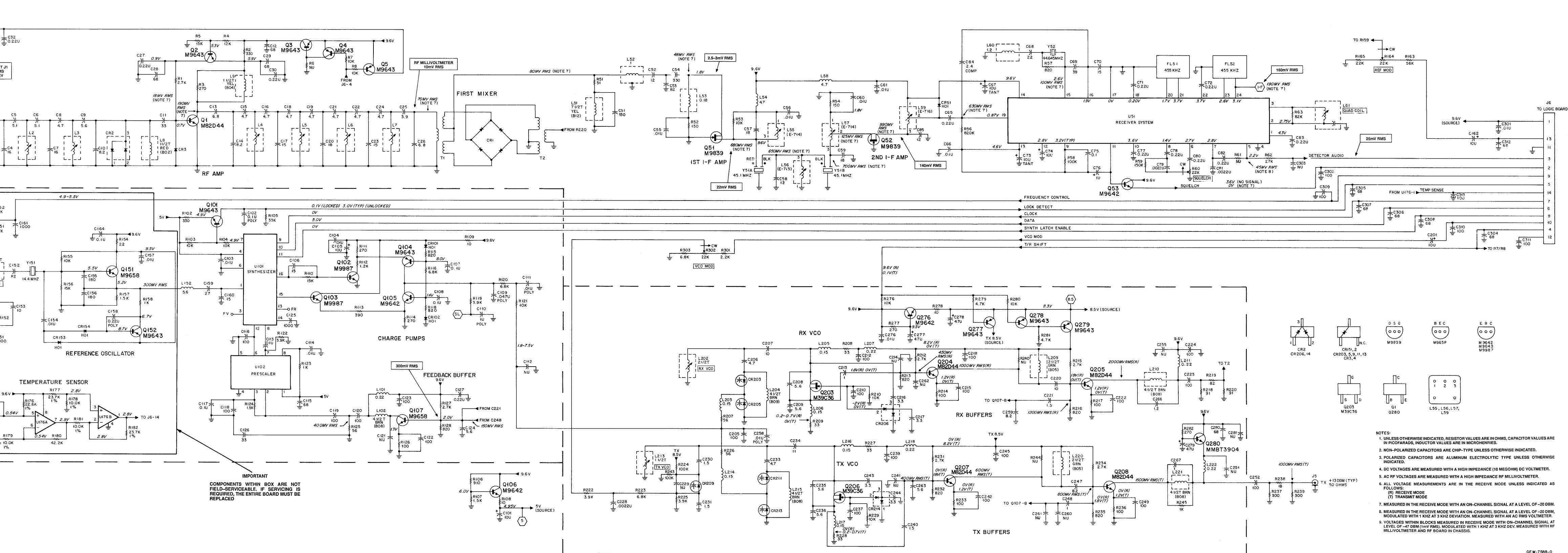
Schematic, Circuit Board Diagrams, and
Parts List for HLE4425B UHF RF Board
PW-5283-C
(Sheet 1 of 2)
4/28/90

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C221	21-13740B01	1 pF, ±5%, 50V
C222	21-13740B45	68 pF, ±5%, 50V
C223		not used
C224-226	21-13740B45	68 pF, ±5%, 50V
C227	21-13740B01	1 pF, ±5%, 50V
C228	21-13741B45	.01 pF, ±5%, 50V
C229	21-13740B01	1 pF, ±5%, 50V
C230,231	21-13740B13	3.3 pF, ±5%, 50V
C232	21-13740B19	5.6 pF, ±5%, 50V
C233	21-13740B19	5.6 pF, ±5%, 50V
C234	21-13740B19	5.6 pF, ±5%, 50V
C235,236	21-13740B19	4.3 pF, ±5%, 50V
C237	21-13740B53	.01 pF, ±5%, 50V
C238		not used
C239	21-13740B45	68 pF, ±5%, 50V
C240	21-13740B01	1 pF, ±5%, 50V
C241	21-13740B45	68 pF, ±5%, 50V
C242	21-13740B17	4.7 pF, ±5%, 50V
C243	21-13740B17	1 pF, ±5%, 50V
C244	21-13740B45	68 pF, ±5%, 50V
C245	21-13740B45	68 pF, ±5%, 50V
C246	08-11051A17	.47 uF, ±5%, 63V
C247	08-11051A13	.1 uF, ±5%, 63V
C248	21-13741B53	.022 uF, ±5%, 50V
C249	21-13741B53	.1 uF, ±5%, 50V
C250,251	21-13740B45	.022 uF, ±5%, 50V
C252	21-13740B45	.022 uF, ±5%, 50V
C253	21-13740B45	.022 uF, ±5%, 50V
C254	08-11051A13	.1 uF, ±5%, 63V
C255,256	21-13741B53	.022 uF, ±5%, 50V
C257	21-13740B45	.022 uF, ±5%, 50V
C258	21-13740B31	.18 pF, ±5%, 50V
C259	21-13740B31	.22 uF, ±80, -20%, 50V
C260	21-13740B31	.22 uF, ±80, -20%, 50V
C261	21-13740B31	.22 uF, ±80, -20%, 50V
C262	21-13740B31	.22 uF, ±80, -20%, 50V
C263	21-13740B47	.82 pF, ±5%, 50V
C264	21-13740B61	.330 pF, ±5%, 50V
C265,C54	21-13741B45	.01 uF, ±5%, 50V
C266,C55,56	21-13740B31	.18 pF, ±5%, 50V
C267	21-13740B31	.18 pF, ±5%, 50V
C268	21-13740B31	.18 pF, ±5%, 50V
C269	21-13740B31	.18 pF, ±5%, 50V
C270	21-13740B31	.22 uF, ±80, -20%, 50V
C271	21-13740B31	.22 uF, ±80, -20%, 50V
C272	21-13740B31	.22 uF, ±80, -20%, 50V
C273	21-13740B31	.22 uF, ±80, -20%, 50V
C274	21-13740B31	.22 uF, ±80, -20%, 50V
C275	21-13740B31	.22 uF, ±80, -20%, 50V
C276	21-13740B31	.22 uF, ±80, -20%, 50V
C277,278	21-13741B45	.47 uF, ±20%, 16V, electrolytic
C279	21-13741B45	.01 uF, ±5%, 50V
C280	21-13741B45	.01 uF, ±5%, 50V
C281	21-13741B45	.01 uF, ±5%, 50V
C282	21-13741B45	.01 uF, ±5%, 50V
C283	21-13741B45	.01 uF, ±5%, 50V
C284	21-13740B27	.12 pF, ±5%, 50V
C285	21-13740B27	.10 uF, ±20%, 16V, electrolytic
C286	21-13740B27	.01 uF, ±5%, 50V
C287	21-13740B27	.01 uF, ±5%, 50V
C288	21-13740B27	.01 uF, ±5%, 50V
C289	21-13740B27	.01 uF, ±5%, 50V
C290	21-13740B27	.01 uF, ±5%, 50V
C291	21-13740B27	.01 uF, ±5%, 50V
C292	21-13740B27	.01 uF, ±5%, 50V
C293	21-13740B27	.01 uF, ±5%, 50V
C294	21-13740B27	.01 uF, ±5%, 50V
C295	21-13740B27	.01 uF, ±5%, 50V
C296	21-13740B27	.01 uF, ±5%, 50V
C297	21-13740B27	.01 uF, ±5%, 50V
C298	21-13740B27	.01 uF, ±5%, 50V
C299	21-13740B27	.01 uF, ±5%, 50V
C300	21-13740B27	.01 uF, ±5%, 50V
C301	21-13740B27	.01 uF, ±5%, 50V
C302	21-13740B27	.01 uF, ±5%, 50V
C303	21-13740B27	.01 uF, ±5%, 50V
C304-308	21-13740B45	.68 pF, ±5%, 50V
C305	21-13740B45	.01 uF, ±5%, 50V
C306	21-13740B45	.01 uF, ±5%, 50V
C307	21-13740B45	.01 uF, ±5%, 50V
C308	21-13740B45	.01 uF, ±5%, 50V
C309	21-13740B45	.01 uF, ±5%, 50V
C310	21-13740B45	.01 uF, ±5%, 50V
C311	21-13740B45	.01 uF, ±5%, 50V
C312	21-13740B45	.01 uF, ±5%, 50V
C313	21-13740B45	.01 uF, ±5%, 50V
C314	21-13740B45	.01 uF, ±5%, 50V
diode (see note)	CR1	48-80236E16
	CR2	48-80154K01
	CR3	48-80939T01
	CR51	48-83654H01
	CR52	48-83654H04
	CR53	48-83654H05
	CR54	48-83654H06
	CR55	48-83654H07
	CR56	48-83654H08
	CR57	48-83654H09
	CR58	48-83654H10
	CR59	48-83654H11
	CR60	18-05500L00
	CR61	06-11077A19
	CR62	06-11077B09
	CR63	06-11077B21
	CR64	06-11077A62
	R102	06-11077A92
	R103,104	06-11077A94
	R105	06-11077B11
	R106	06-11077A73
	R107	06-11077A76
	R108,109	06-11077A26
	R109	06-11077B03
	R110	06-11077A52
	R111	06-11077A54
	R112	06-11077A72
	R113	06-11077A58
	R114	06-11077A74
	R115	06-11077A70
	R116	06-11077A72
	R117	06-11077A70
	R118	06-11077A70
	R119,120	06-11077A88
	R121	06-11077A84
	R122	06-11077A88
	R123	06-11077A72
	R124	06-11077A76
	R125	06-11077A51
	R126	06-11077A48
	R127	06-11077A84
	R128	06-11077A72
	R151	06-11077B15
	R152	06-11077B15
	R153	06-11077A51
	R154	06-11077A34
	R155	06-11077A98
	R156	06-11077B08
	R157	06-11077A78
	R158,159	06-11077A74
	R161	06-11077B16
	R162	06-11077A76
	R163	06-11077A17
	R164	18-05500L08
	R165	06-11077B07
	R166	06-11077A15
	R167	06-11077A26
	R168	06-11077A49
	R169	06-11077A98
	R170	06-11077B26
	R171	06-11077G22
	R172	06-11077G23
	R173	06-11077F91
	R174	06-11077G19
	R175	06-11077G33
	R176	06-11077G26
	R177	06-11077G27
	R178,179	06-11077F91
	R180	06-11077G33
	R181	06-11077G19
	R182	06-11077G28
	R201,202	06-11077A98
	R203	06-11077B31
	R204,205	06-11077A98
	R206	06-11077A72
	R207	06-11077A44
	R208	06-11077A33
	R209	06-11077A44
	R210	06-11077A98
	R211	06-11077B11
	R212	06-11077A84
	R213	06-11077A82
	R214	06-11077A70
	R215	06-11077A94
	R216	06-11077A22
	R217	06-11077A48
	R218	06-11077A50
	R219	06-11077A46
	R220	06-11077A50
	R221	06-11077A72
	R222	06-11077A88
	R223	06-11077B03
	R224	06-11077B23
transformer	T1,2	25-80163M02
transistor (see note)	Q1	48-80950X01

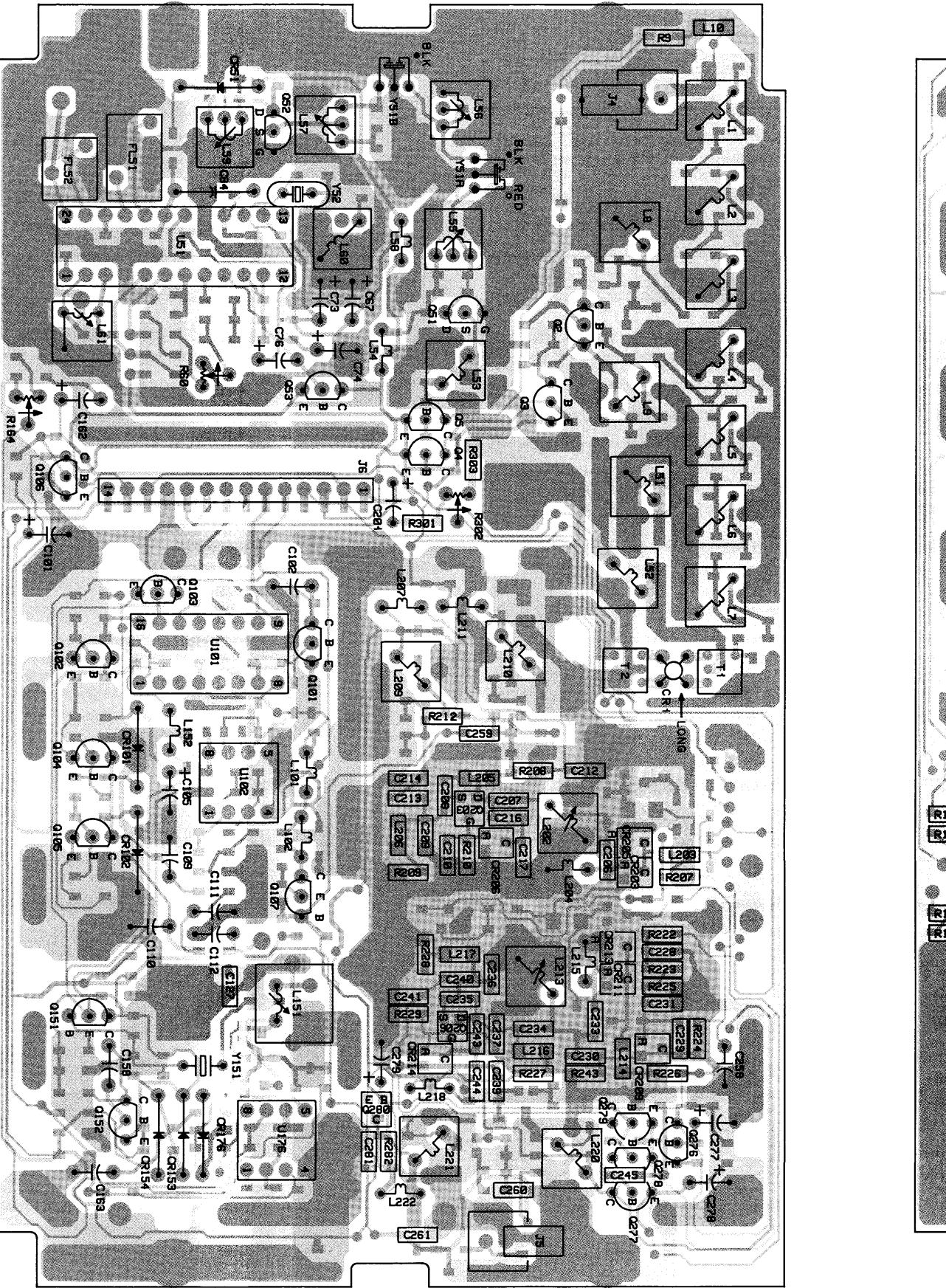
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
resistor, fixed, ohm, +5% 180 °C (unless otherwise stated)		
R1	06-11077A94	

UHF RF Board Transistor D.C. Voltage Table

Transistor Ref. No.	VOLTAGE			VOLTAGE		
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN
Q1	.7	0	5.9	—	—	—
Q2	5.3	5.9	.9	—	—	—
Q51	—	—	—	0	1.8	9.6
Q52	—	—	—	0	1.8	9.6
Q53	0	0 (W/SIG)	9.6	—	—	—
Q101	5.0	4.9	.1 (LOCKED)	—	—	—
Q102	.7	0	0.1	—	—	—
Q103	5.0	4.4	9.6	—	—	—
Q104	8.1	2.8V	—	—	—	—
Q105	1.4	VAR.	2-8V	—	—	—
Q106	6.0	5.0	9.6	—	—	—
Q107	2.0	1.3	9.6	—	—	—
Q151	5.5	5.2	9.5	—	—	—
Q152	8.7	9.5	6.7	—	—	—
Q201	—	9.6	0(U) 9.3(L)	U=UPPER L=LOWER RANGE	—	—
Q202	0(U).7(L)	0	6.7(U)0(L)	—	—	—
Q203	—	—	2.6(R)	4.8(R)	7.9(R)	—
Q204	1.8(R)	1.2(R)	8.2(R)	—	—	—
Q205	1.8(R)	1.2(R)	9.6	—	—	—
Q206	—	—	—.5(T)	1.1(T)	7.8(T)	—
Q207	1.8(T)	1.2(T)	8.5(T)	—	—	—
Q208	1.8(T)	1.2(T)	9.6	—	—	—
Q209	9.5	8.6	9.6	—	—	—
Q277	9.6	8.5(T)	8.5	—	—	—
Q278	9.6	8.3	7.6(R)	—	—	—
Q279	7.6(R)	8.5	8.5	—	—	—

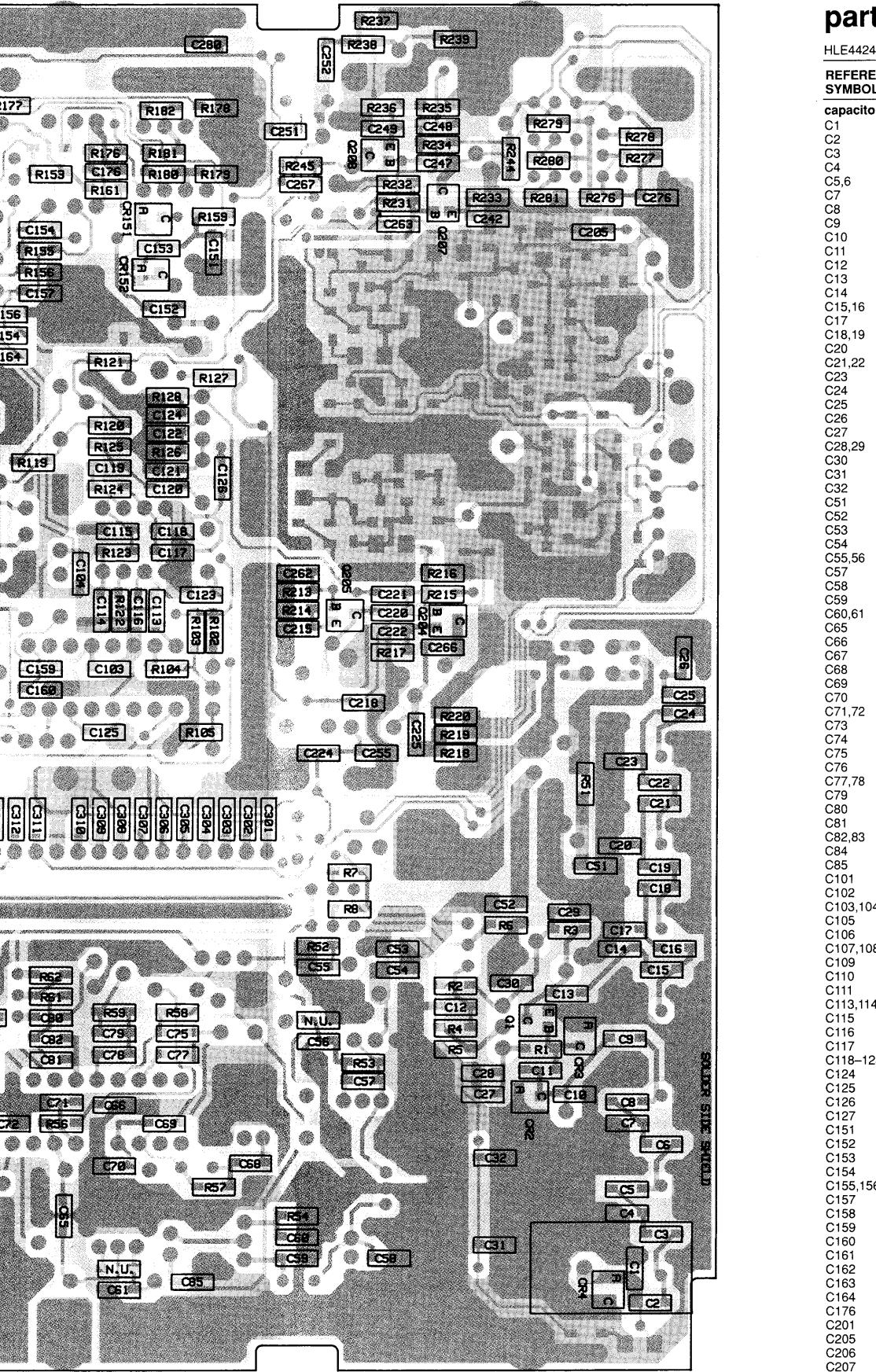


Schematic, Circuit Board Diagrams, and Parts List for HLE442A UHF RF Board
PW-7587-O
(Sheet 1 of 2)
3/31/90



COMPONENT SIDE VIEW

SOLDER SIDE
COMPONENT SIDE
OVERLAYS



VIEW C212
C213
C215

st

UHF 25 UH-Bay +1 RF Board

Trac UHF 25 kHz Range 1 RF Board MXW-7408-O

MOTOROLA PART NO.	DESCRIPTION	REFERENCE SYMBOL
(unless otherwise stated)		
21-13740B23	8.2 pF, ±5%, 50V	C222
21-13740B21	6.8 pF, ±5%, 50V	C224,225
21-13740B17	4.7 pF, ±5%, 50V	C228
21-13740B30	16 pF, ±5%, 50V	C230,231
21-13740B18	5.1 pF, ±5%, 50V	C233
21-13740B30	16 pF, ±5%, 50V	C234
21-13740B17	4.7 pF, ±5%, 50V	C235,236
21-13740B19	5.6 pF, ±5%, 50V	C237
21-13740B23	8.2 pF, ±5%, 50V	C239
21-13740B37	33 pF, ±5%, 50V	C240
21-13740B45	68 pF, ±5%, 50V	C242
21-13740B21	6.8 pF, ±5%, 50V	C243,244
21-13740B23	8.2 pF, ±5%, 50V	C245
21-13740B17	4.7 pF, ±5%, 50V	C247
21-13740B29	15 pF, ±5%, 50V	C248
21-13740B17	4.7 pF, ±5%, 50V	C249
21-13740B17	4.7 pF, ±5%, 50V	C252
21-13740B31	18 pF, ±5%, 50V	C258
21-13740B17	4.7 pF, ±5%, 50V	C259
21-13740B29	15 pF, ±5%, 50V	C263
21-13740B17	4.7 pF, ±5%, 50V	C266
21-13740B15	3.9 pF, ±5%, 50V	C267
21-13740B21	6.8 pF, ±5%, 50V	C276
21-11032B15	.22 uF, +80, -20%, 50V	C277-279
21-13740B45	68 pF, ±5%, 50V	C280
21-11032B15	.22 uF, +80, -20%, 50V	C301
21-13740B49	100 pF, ±5%, 50V	C302
21-11032B15	.22 uF, +80, -20%, 50V	C304-308
21-13740B55	150 pF, ±5%, 50V	C309-311
21-13740B27	12 pF, ±5%, 50V	diode (see note)
21-13740B31	18 pF, ±5%, 50V	CR1
21-13740B27	12 pF, ±5%, 50V	CR2
21-13741B45	.01 uF, ±5%, 50V	CR3
21-11032B15	.22 uF, +80, -20%, 50V	CR4
21-13741B45	.01 uF, ±5%, 50V	CR51
23-13749C39	10 uF, ±10%, 50V, tantalum	CR101,102
21-13740B33	22 pF, ±5%, 50V	CR151,152
21-13740B39	39 pF, ±5%, 50V	CR153,154
21-13740B29	15 pF, ±5%, 50V	CR176
21-11032B15	.22 uF, +80, -20%, 50V	CR203
23-13749C39	10 uF, ±10%, 50V, tantalum	CR205
23-11048B13	10 uF, ±20%, 16V, electrolytic	CR206
21-13741B69	.1 uF, ±5%, 50V	CR209
23-11048B05	1 uF, ±20%, 50V, electrolytic	CR211
21-11032B15	.22 uF, +80, -20%, 50V	CR213
21-13741B29	.0022 uF, ±5%, 50V	CR214
21-13740B55	.22 uF, +80, -20%, 50V	filter
21-11032B15	.0022 uF, ±5%, 50V	FL51
21-13741B29	.22 uF, +80, -20%, 50V	FL52
21-13740B55	.180 pF, ±5%, 50V	connector receptacle
21-11032B15	.22 uF, +80, -20%, 50V	J4,5
21-13740B27	.22 uF, +80, -20%, 50V	J6
21-13740B27	12 pF, ±5%, 50V	RF coil
23-11048B13	10 uF, ±20%, 16V, electrolytic	L1-7
08-11051A13	.1 uF, ±5%, 63V	L8
21-13741B45	.01 uF, ±5%, 50V	L9
23-11048B13	10 uF, ±20%, 16V, electrolytic	L10
21-13740B29	15 pF, ±5%, 50V	L51
21-13741B69	.1 uF, ±5%, 50V	L52
08-11051A11	.047 uF, ±5%, 63V	L53
08-11051A19	1 uF, ±5%, 63V	L54
08-11051A07	.01 uF, ±5%, 63V	L55
21-13741B45	.01 uF, ±5%, 50V	L56
21-13740B45	.68 pF, ±5%, 50V	L57
21-13740B49	100 pF, ±5%, 50V	L58
21-13741B69	.1 uF, ±5%, 50V	L59
21-13740B49	100 pF, ±5%, 50V	L60
21-13740B37	33 pF, ±5%, 50V	L61
21-11032B15	.22 uF, +80, -20%, 50V	L101
21-13740B73	.001 uF, ±5%, 50V	L102
21-13740B47	82 pF, ±5%, 50V	L151
21-13740B25	10 pF, ±5%, 50V	L152
21-13741B45	.01 uF, ±5%, 50V	L202
21-13740B55	180 pF, ±5%, 50V	L203
21-13741B45	.01 uF, ±5%, 50V	L204
08-11051A15	.22 uF, ±5%, 63V	L205,206
21-13740B35	.27 pF, ±5%, 50V	L207
21-13740B29	15 pF, ±5%, 50V	L209
21-13740B73	.001 uF, ±5%, 50V	L210
23-11048B13	10 uF, ±20%, 16V, electrolytic	L211
08-11051A17	.47 uF, ±5%, 63V	L213
21-13741B69	.1 uF, ±5%, 50V	L214
21-13740B73	.001 uF, ±5%, 50V	L215
23-11048B13	10 uF, ±20%, 16V, electrolytic	L216
21-13740B49	100 pF, ±5%, 50V	L217
21-13740B17	4.7 pF, ±5%, 50V	L218
21-13740B25	10 pF, ±5%, 50V	L220
21-13740B19	5.6 pF, ±5%, 50V	L221
21-13740B49	100 pF, ±5%, 50V	L222
21-13740B49	100 pF, ±5%, 50V	L223
21-13740B01	1 pF, ±5%, 50V	transistor (see note)
21-13740B49	100 pF, ±5%, 50V	Q1
21-13740B13	3.3 pF, ±5%, 50V	Q2-5
21-13741B49	100 pF, ±5%, 50V	Q51,52
21-13740B25	10 pF, ±5%, 50V	Q53
21-13740B05	1.5 pF, ±5%, 50V	

[View all posts by **John Doe**](#) [View all posts in **Category A**](#) [View all posts in **Category B**](#)

MOTOROLA PART NO.	DESCRIPTION
1-13740B49	100 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-13741B29	.0022 uF, ±5%, 50V
1-13740B05	1.5 pF, ±5%, 50V
1-13740B17	4.7 pF, ±5%, 50V
1-13740B26	11 pF, ±5%, 50V
1-13740B19	5.6 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-13740B05	1.5 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-13740B13	3.3 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-13740B23	8.2 pF, ±5%, 50V
1-13740B01	1 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
8-11051A07	.01 uF, ±5%, 63V
1-13740B23	8.2 pF, ±5%, 50V
1-13740B19	5.6 pF, ±5%, 50V
1-13740B03	1.2 pF, ±5%, 50V
1-13740B01	1 pF, ±5%, 50V
1-13741B45	.01 uF, ±5%, 50V
3-11048B19	47 uF, ±20%, 16V, elect
1-13740B45	68 pF, ±5%, 50V
1-13741B45	.01 uF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-13740B45	68 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-13740B45	68 pF, ±5%, 50V
1-13740B49	100 pF, ±5%, 50V
1-11022PH27	10 nF, + 5% 50V

MXW-7408-O (2)

	REFEREN SYMBOL
Q101	
Q102,103	
Q104	
Q105,106	
Q107	
Q151	
Q152	
Q203	
Q204,205	
Q206	
Q207,208	
Q276	
Q277-279	
Q280	
	resistor, f.
R1	
R2	
R3	
R4	
R5	
R7,8	
R9	
R51	
R52	
R53	
R54	
R56	
R57	
R58	
R59	
R60	

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IC	MOTOROLA PART NO.	DE
	48-00869643	PN
	48-80182D20	NI
	48-00869643	PN
	48-00869642	NI
	48-00869658	NI
	48-00869658	NI
	48-00869643	PN
	48-05128M66	N- NI
	48-80950X01	NI
	48-05128M66	N- NI
	48-80950X01	NI
	48-00869642	NI
	48-00869643	PN
	48-80214G02	PN
Fixed, ohm, +5%, 1/8 watt (unless otherwise specified)		
	06-11077A84	2.2
	06-11077A62	33
	06-11077A60	27
	06-11077B01	12
	06-11077B03	15
	06-11077A98	10
	06-11077A72	82
	06-11077A43	51
	06-11077A54	15
	06-11077A98	10
	06-11077A54	15
	06-11077B45	82
	06-11077A72	82
	06-11077B23	10
	06-11077B27	15
	18-05500L08	22

MXW-7408-O

DESCRIPTION

NP
PN
NP
PN
PN
PN
NP
-channel
PN
-channel
PN
PN
NP
otherwise stated)
7k
30
70
2k
5k
1k
20
60
1k
50
20k
20
100k
50k
2k, ±20%, potentiometer

(3) _____

REFERENCE SYMBOL	MO/PAGE
R236	06
R237	06
R238	06
R239	06
R243	06
R245	06
R276	06
R277	06
R278	06
R279	06
R280	06
R281	06
R282	06
R301	06
R302	18
R303	06
transformer	
T1,2	25
integrated circuits (see note)	
U51	51
U101	51
U102	51
U176	51
crystal (see note)	
Y51	91
Y52	48
Y151	48

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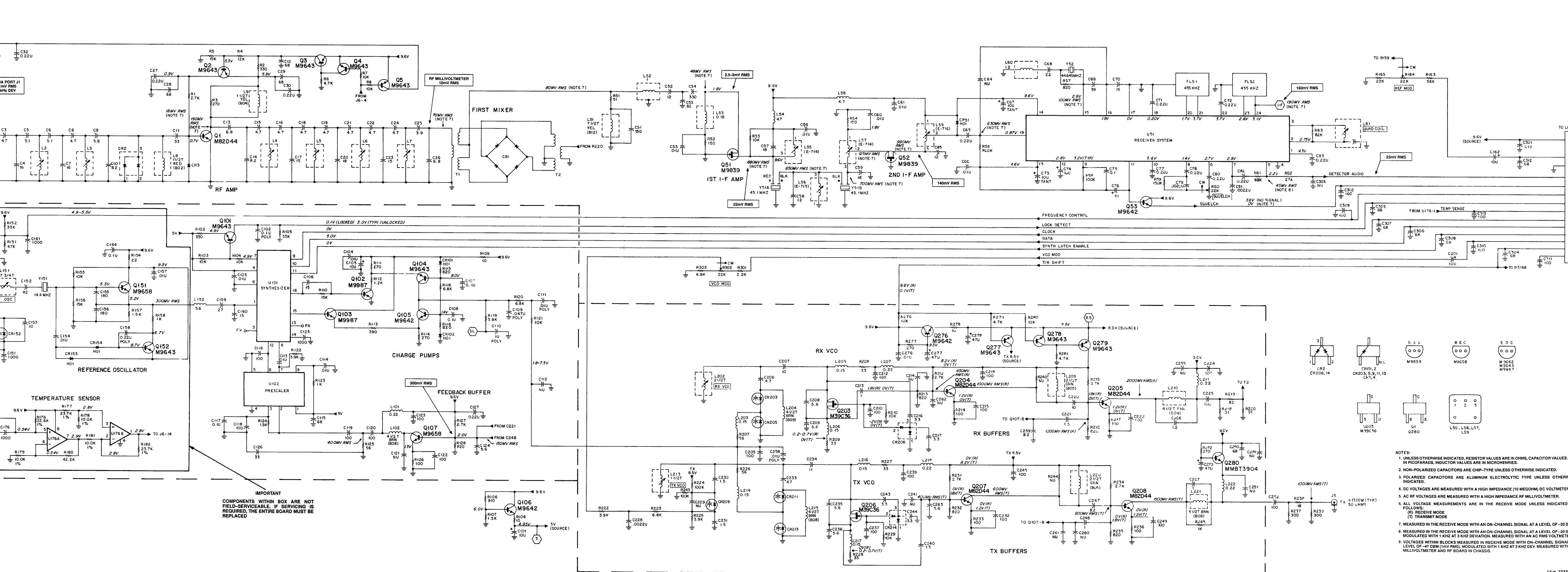
TOTOROLA PART NO.	DESCRIPTION
-11077A50	100
-11077A61	300
-11077A32	18
-11077A61	300
-11077B23	100k
-11077A74	1k
-11077A98	10k
-11077A60	270
-11077A26	10
-11077A90	4.7k
-11077A98	10k
-11077A90	4.7k
-11077A60	270
-11077A82	2.2k
-05500L08	22k, ±20%, 100V
-11077A94	6.8k
-80163M02 (ote)	500 MHz balan-
-05479G05	linear
-84704M75	synthesizer
-83977M45	prescaler
-84621K89	dual opamp
-80022M02	45.1 MHz
-80008K02	44.645 MHz
-80174D05	14.4 MHz
non-referenced parts	
-00003152	eyelet
05160A01	insulator

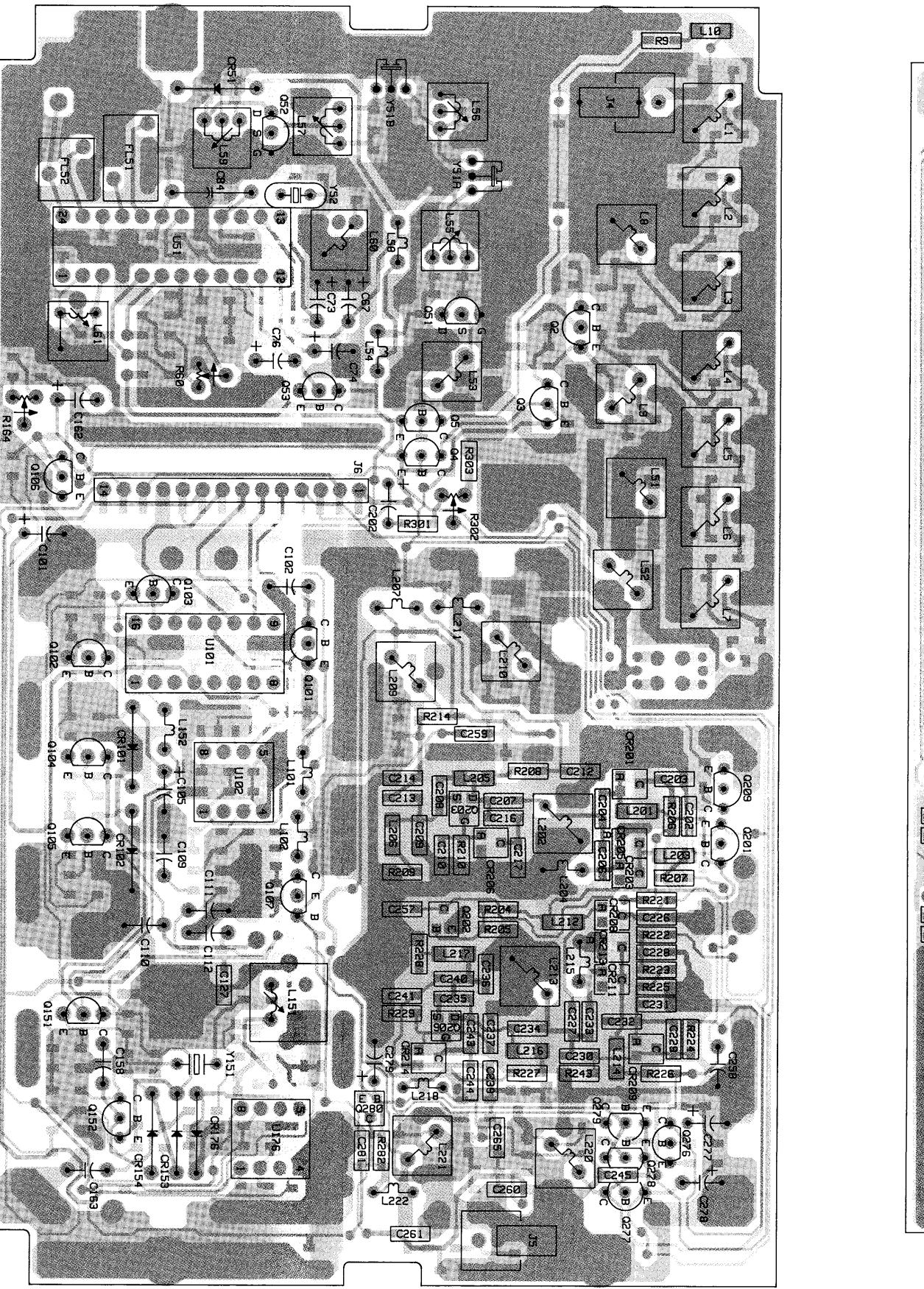
Integrated circuit devi

**RF Diagrams,
UHF RF B
PW 758**

UHF RF Board Transistor D.C. Voltage Table

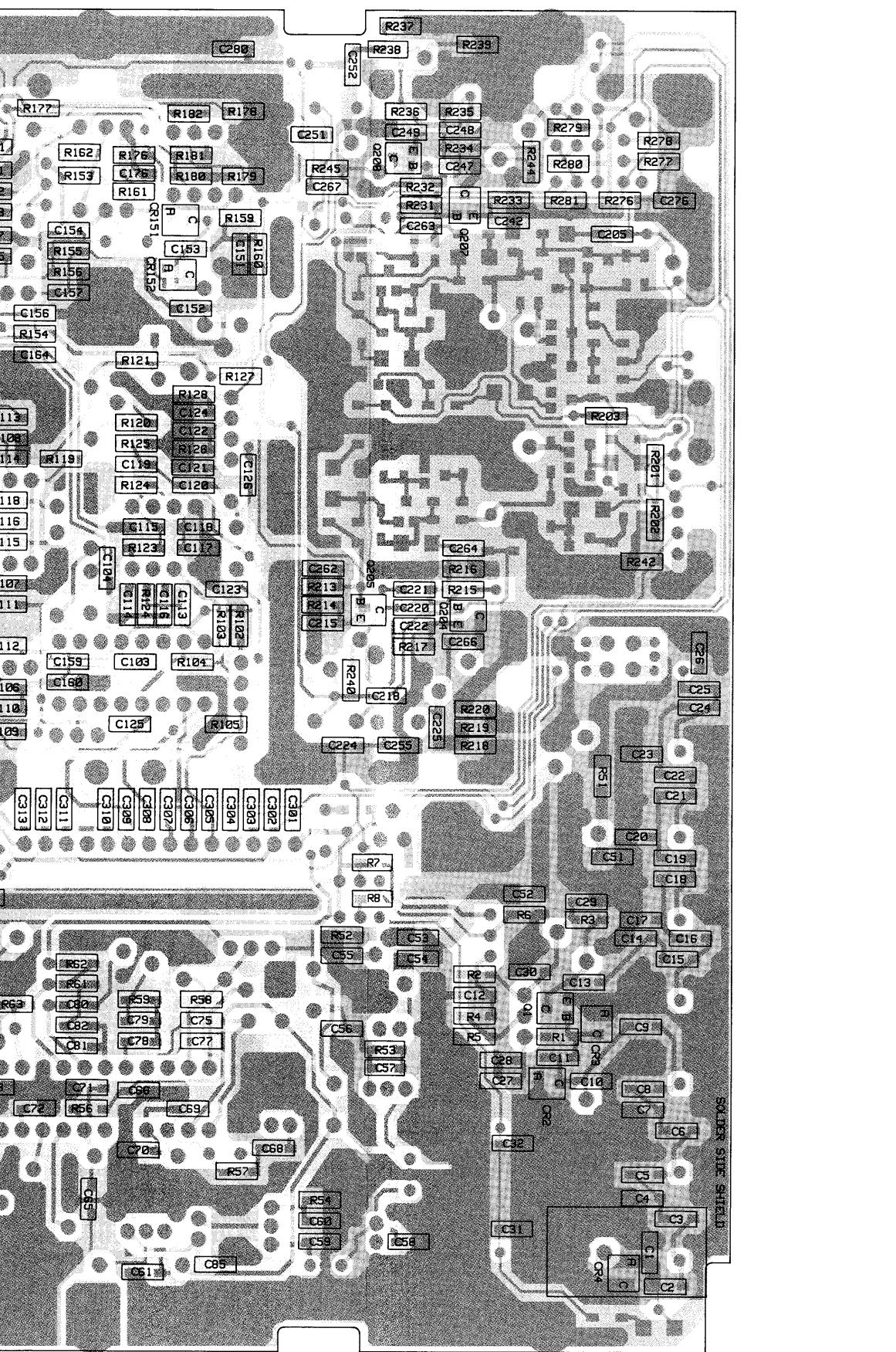
Transistor Ref. No.	VOLTAGE			VOLTAGE		
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN
Q1	.7	0	5.9	—	—	—
Q2	/ 5.3	5.9	.9	—	—	—
Q51	—	—	—	0	1.8	9.6
Q52	—	—	—	0	1.8	9.6
Q53	0	0 (W/SIG)	9.6	—	—	—
Q101	5.0	4.9	.1 (LOCKED)	—	—	—
Q102	.7	0	0.1	—	—	—
Q103	5.0	4.4	9.6	—	—	—
Q104	8.1	2.8V	2-BV	—	—	—
Q105	1.4	VAR.	2-BV	—	—	—
Q106	6.0	5.0	9.6	—	—	—
Q107	2.0	1.3	9.6	—	—	—
Q151	5.5	5.2	9.5	—	—	—
Q152	8.7	9.5	6.7	—	—	—
Q201	—	9.6	0(U) 9.3(L)	U=UPPER L=LOWER RANGE	—	—
Q202	0(U) 7(L)	0	6.7(U) 0(L)	—	—	—
Q203	—	—	2.6(R)	4.8(R)	7.9(R)	—
Q204	1.8(R)	1.2(R)	8.2(R)	—	—	—
Q205	1.8(R)	1.2(R)	9.6	—	—	—
Q206	—	—	-5(T)	1.1(T)	7.8(T)	—
Q207	1.8(T)	1.2(T)	8.5(T)	—	—	—
Q208	1.8(T)	1.2(T)	9.6	—	—	—
Q276	9.5	8.6	9.6	—	—	—
Q277	9.6	8.5(T)	8.5	—	—	—
Q278	9.6	8.3	7.6(R)	—	—	—
Q279	7.6(R)	8.5	8.5	—	—	—





COMPONENT SIDE VIEW

SOLDER SIDE
RED GAW-7724-O
COMPONENT SIDE
GREY GAW-7725-O
OVERLAYS BLACK GDW-7726-O



SOLDER SIDE VIEW

parts list

HLE4424B MaxTrac UHF 25 kHz Range 1 RF Board

MXW-7758-O

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C1	21-13740B23	8.2 pF, ±5%, 50V
C2	21-13740B23	6.8 pF, ±5%, 50V
C3	21-13740B17	4.7 pF, ±5%, 50V
C4	21-13740B30	16 pF, ±5%, 50V
C5,6	21-13740B18	5.1 pF, ±5%, 50V
C7	21-13740B17	4.7 pF, ±5%, 50V
C8	21-13740B19	5.6 pF, ±5%, 50V
C9	21-13740B23	8.2 pF, ±5%, 50V
C10	21-13740B07	33 pF, ±5%, 50V
C11	21-13740B17	4.7 pF, ±5%, 50V
C12	21-13740B45	3.3 pF, ±5%, 50V
C13	21-13740B21	6.8 pF, ±5%, 50V
C14	21-13740B23	8.2 pF, ±5%, 50V
C15,16	21-13740B17	4.7 pF, ±5%, 50V
C17	21-13740B29	15 pF, ±5%, 50V
C18,19	21-13740B17	4.7 pF, ±5%, 50V
C20	21-13740B31	18 pF, ±5%, 50V
C21,22	21-13740B17	4.7 pF, ±5%, 50V
C23	21-13740B29	15 pF, ±5%, 50V
C24	21-13740B17	4.7 pF, ±5%, 50V
C25	21-13740B15	3.9 pF, ±5%, 50V
C26	21-13740B21	6.8 pF, ±5%, 50V
C27	21-13740B15	22 pF, ±80, -20%, 50V
C28,29	21-13740B45	63 pF, ±5%, 50V
C30	21-1032B15	22 pF, ±80, -20%, 50V
C31	21-13740B49	100 pF, ±5%, 50V
C32	21-1032B15	22 pF, ±80, -20%, 50V
C51	21-13740B55	150 pF, ±5%, 50V
C52	21-13740B27	12 pF, ±5%, 50V
C53	21-13740B47	82 pF, ±5%, 50V
C54	21-13740B61	330 pF, ±5%, 50V
C55,56	21-13741B45	.01 uF, ±5%, 50V
C57	21-13740B31	18 pF, ±5%, 50V
C58	21-13740B27	12 pF, ±5%, 50V
C59	21-13740B31	18 pF, ±5%, 50V
C60,61	21-1032B15	.01 uF, ±80, -20%, 50V
C66	21-13741B45	.01 uF, ±5%, 50V
C67	23-13749C39	.23 uF, ±10%, 50V, tantalum
C68	21-13740B33	22 pF, ±5%, 50V
C69	21-13740B39	39 pF, ±5%, 50V
C70	21-13740B29	15 pF, ±5%, 50V
C71,72	21-1032B15	.22 uF, ±80, -20%, 50V
C73	23-13749C39	10 uF, ±10%, 50V, tantalum
C74	23-1048B13	10 uF, ±20%, 16V, electrolytic
C75	21-13741B63	.1 uF, ±5%, 50V
C76	23-1048B05	.1 uF, ±20%, 50V, electrolytic
C77,78	21-1032B15	.22 uF, ±80, -20%, 50V
C79	21-13740B39	.001 uF, ±5%, 50V
C80	21-1032B15	.22 uF, ±80, -20%, 50V
C81	21-13740B55	.180 pF, ±5%, 50V
C82,83	21-1032B15	.22 uF, ±80, -20%, 50V
C85	21-13740B27	12 pF, ±5%, 50V
C101	23-1048B13	10 uF, ±20%, 16V, electrolytic
C102	08-11051A13	.1 uF, ±5%, 63V
C103,104	23-1048B13	.01 uF, ±20%, 16V, electrolytic
C105	21-13740B29	15 pF, ±5%, 50V
C106	21-13741B63	.1 uF, ±5%, 50V
C107,108	08-11051A17	.047 uF, ±5%, 63V
C109	08-11051A19	.1 uF, ±5%, 63V
C110	08-11051A07	.01 uF, ±5%, 63V
C111	21-13741B45	.01 uF, ±5%, 50V
C112,114	21-13740B45	.68 pF, ±3%, 50V
C115	21-13740B49	.100 pF, ±5%, 50V
C116	21-13741B69	.1 uF, ±5%, 50V
C117	21-13740B49	.100 pF, ±5%, 50V
C118-120	21-13740B49	.100 pF, ±5%, 50V
C122,123	21-13740B19	.56 pF, ±5%, 50V
C124	21-13740B73	.001 uF, ±5%, 50V
C125	21-13740B37	.33 pF, ±5%, 50V
C126	21-11032B15	.22 uF, ±80, -20%, 50V
C127	21-13740B73	.001 uF, ±5%, 50V
C151	21-13740B47	.82 pF, ±5%, 50V
C152	21-13740B47	.001 uF, ±5%, 50V
C154	21-13741B45	.01 uF, ±5%, 50V
C155,156	21-13740B55	.180 pF, ±5%, 50V
C157	21-13741B45	.001 uF, ±5%, 50V
C158	08-11051A15	.22 uF, ±5%, 63V
C159	21-13740B35	.27 pF, ±5%, 50V
C160	21-13740B23	.15 pF, ±5%, 50V
C161	21-13740B73	.001 uF, ±5%, 50V
C162	23-1048B13	.10 uF, ±20%, 16V, electrolytic
C163	08-11051A17	.47 uF, ±5%, 63V
C164	21-13741B69	.1 uF, ±5%, 50V
C176	21-13740B73	.001 uF, ±5%, 50V
C201	23-1048B13	.10 uF, ±20%, 16V, electrolytic
C205	21-13740B19	.001 pF, ±5%, 50V
C206	21-13740B17	.47 pF, ±5%, 50V
C207	21-13740B25	.10 pF, ±5%, 50V
C208,209	21-13740B19	.56 pF, ±5%, 50V
C210	21-13740B49	.100 pF, ±5%, 50V
C212	21-13740B49	.100 pF, ±5%, 50V
C213	21-13740B01	.1 pF, ±5%, 50V
C215	21-13740B49	.100 pF, ±5%, 50V
C216,217	21-13740B13	.3.3 pF, ±5%, 50V
C218	21-13741B49	.100 pF, ±5%, 50V
C220	21-13740B25	.10 pF, ±5%, 50V
C221	21-13740B05	.15 pF, ±5%, 50V

MXW-7758-O (2)

MXW-7758-O (3)

MXW-7758-O (4)

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C101	48-00869643	NPN
O102,103	48-80182D20	NPN
C104	48-00869643	NPN
O105,106	48-00869643	NPN
C107	48-00869658	NPN
O115	48-00869643	NPN
C123,236	48-00869643	N-channel
C237	48-05128M66	N-channel
C239	48-80950X01	NPN
C240	48-05128M65	N-channel
C242	48-80950X00	NPN
C243,244	48-00869642	NPN
C245	48-00869643	NPN
C247	48-0214G02	resistor, fixed, ohm, ±5%, 1/8 watt (unless otherwise stated)
R1	08-1077A84	2.7k
R2	08-1077A62	330
R3	08-1077A60	270
R4	08-1077B01	12k
R5	08-1077B03	15k
R6	08-1077A90	4.7k
R7,8	08-1077A98	10k
R9	08-1077A72	820
R10	08-1077A43	51
R11	08-1077A44	150
R12	08-1077A98	10k
R13	08-1077A54	150
R14	08-1077B45	820k
R15	08-1077A72	200k
R16	08-1077B27	150k
R17	08-1077B19	68k
R18	08-1077B09	27k
R19	08-1077B21	82k
R20	08-1077A62	330
R21	08-1077A98	10k
R22	08-1077B11	33k
R23	08-1077A73	910
R24	08-1077A78	1.5k
R25	08-1077A26	10
R26	08-1077B03	15k
R27	08-1077A70	270
R28	08-1077A90	4.7k
R29	08-1077A98	10k
R30	08-1077A98	10k
R31	08-1077A98	10k
R32	08-1077A72	820
R33	08-1077A84	6.8k

transformer

T1,2

25-80163M02

500 MHz balance transformer

integrated circuits (see note)

U51

51-0547C05

linear

U101

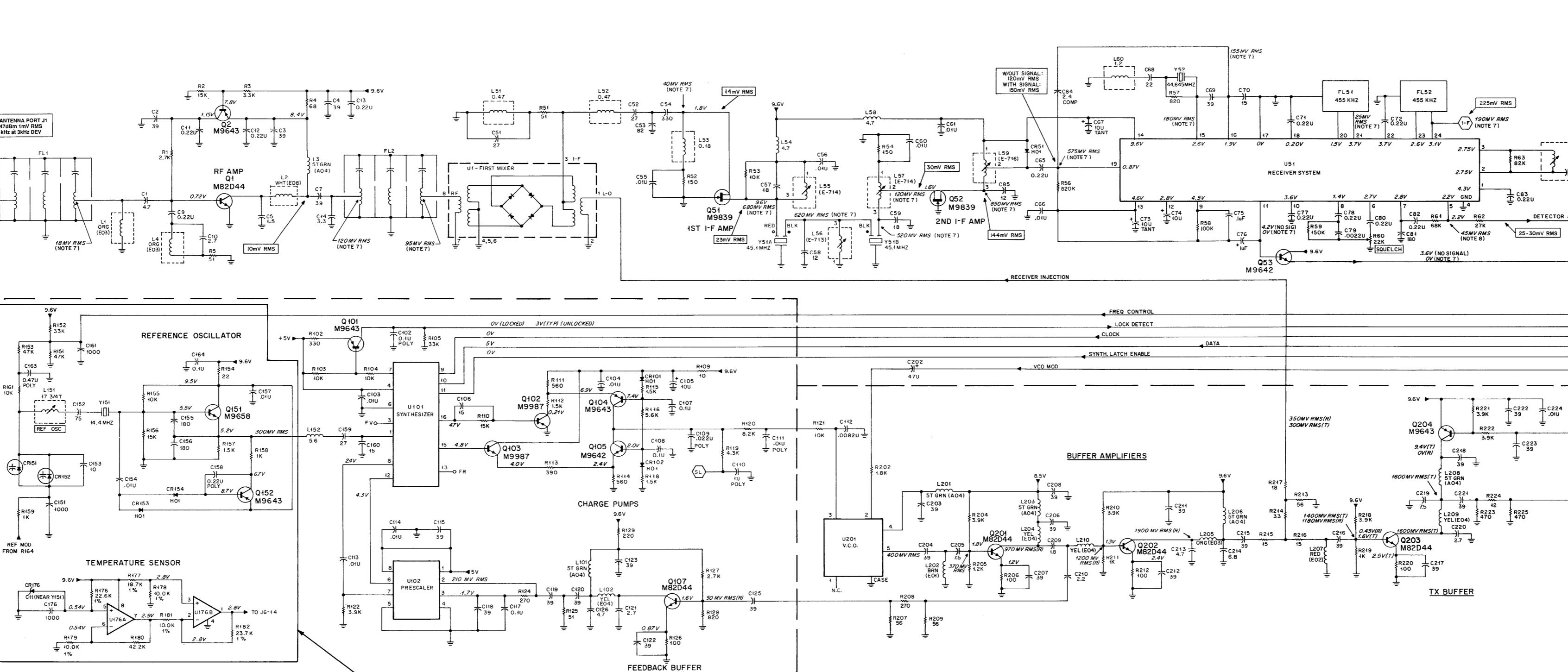
51-8470M75

synthesizer

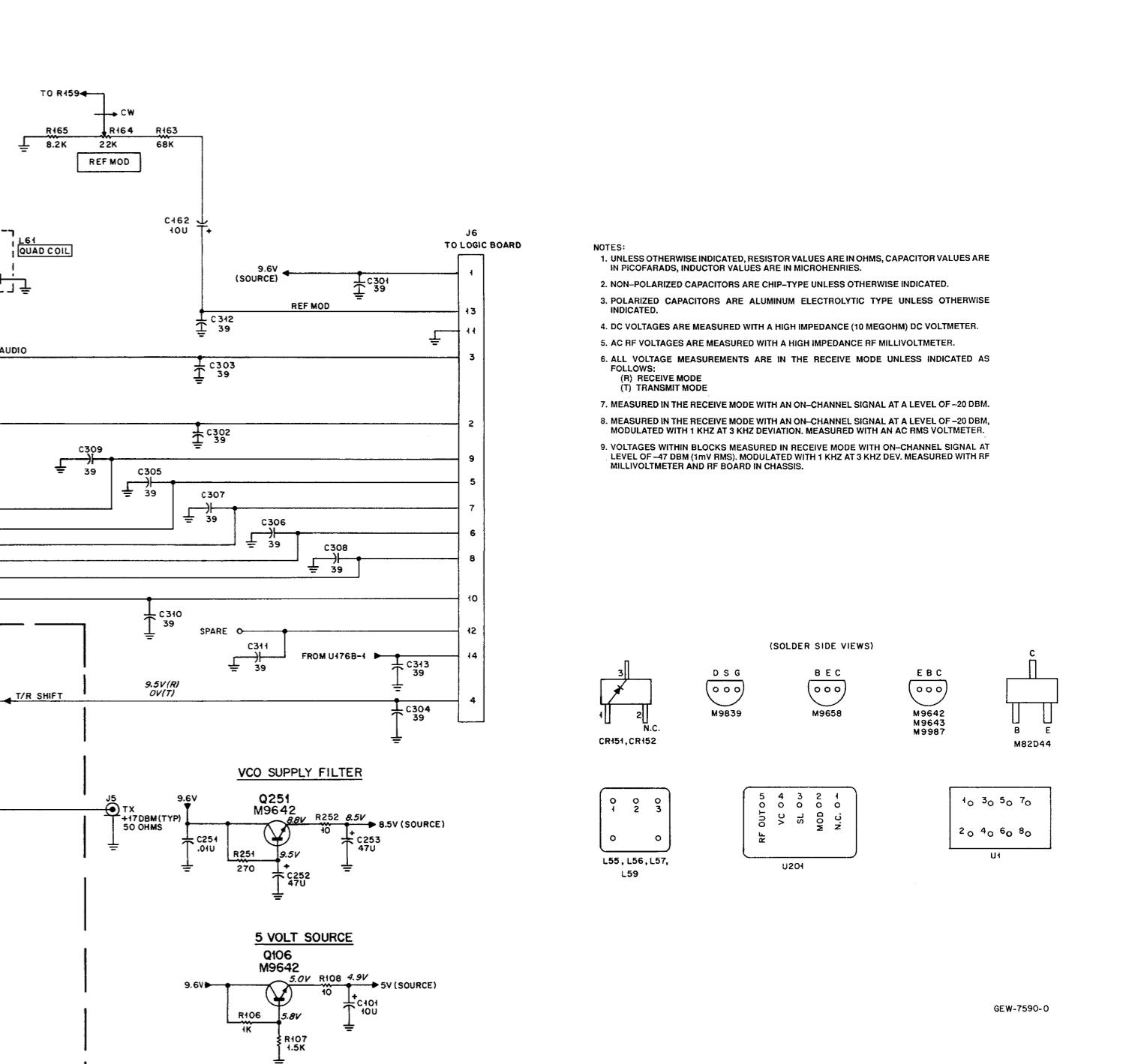
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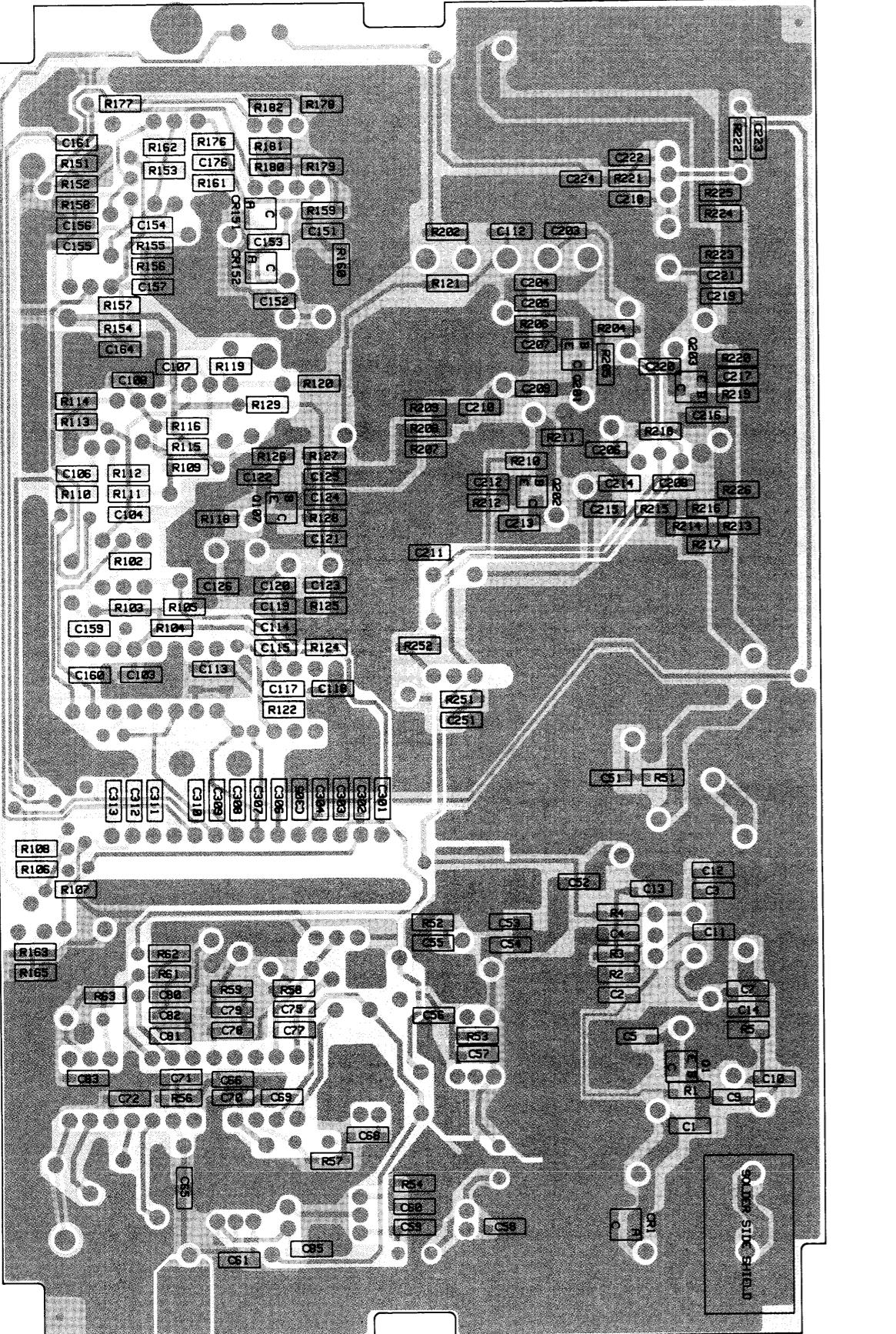
MHz RF Board Transistor D.C. Voltage Table

Transistor Ref. No.	VOLTAGE			VOLTAGE		
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN
Q1	7.2	0	8.4	—	—	—
Q2	7.8	8.4	1.2	—	—	—
Q51	—	—	—	0	1.8	9.6
Q52	—	—	—	0	1.8	9.6
Q53	0(SIG)	0(SIG)	9.6	—	—	—
Q101	4.8	4.8	0 (LOCK)	—	—	—
Q102	.72(R)	0	.21	—	—	—
Q103	4.8	4.0	9.6	—	—	—
Q104	7.4	6.9	2-8v	—	—	—
Q105	2.0	2.4	2-8v	—	—	—
Q106	5.8	5.0	9.6	—	—	—
Q107	1.6	.87	9.6	—	—	—
Q151	5.5	5.2	9.5	—	—	—
Q152	8.7	9.5	6.7	—	—	—
Q201	1.8	1.2	8.5	—	—	—
Q202	1.3	2.4	9.6	—	—	—
Q203	1.6(T)	2.5(T)	9.4(T)	—	—	—
Q204	9.5(R)	9.6	9.4(T)	—	—	—
Q251	9.5	8.8	9.6	—	—	—



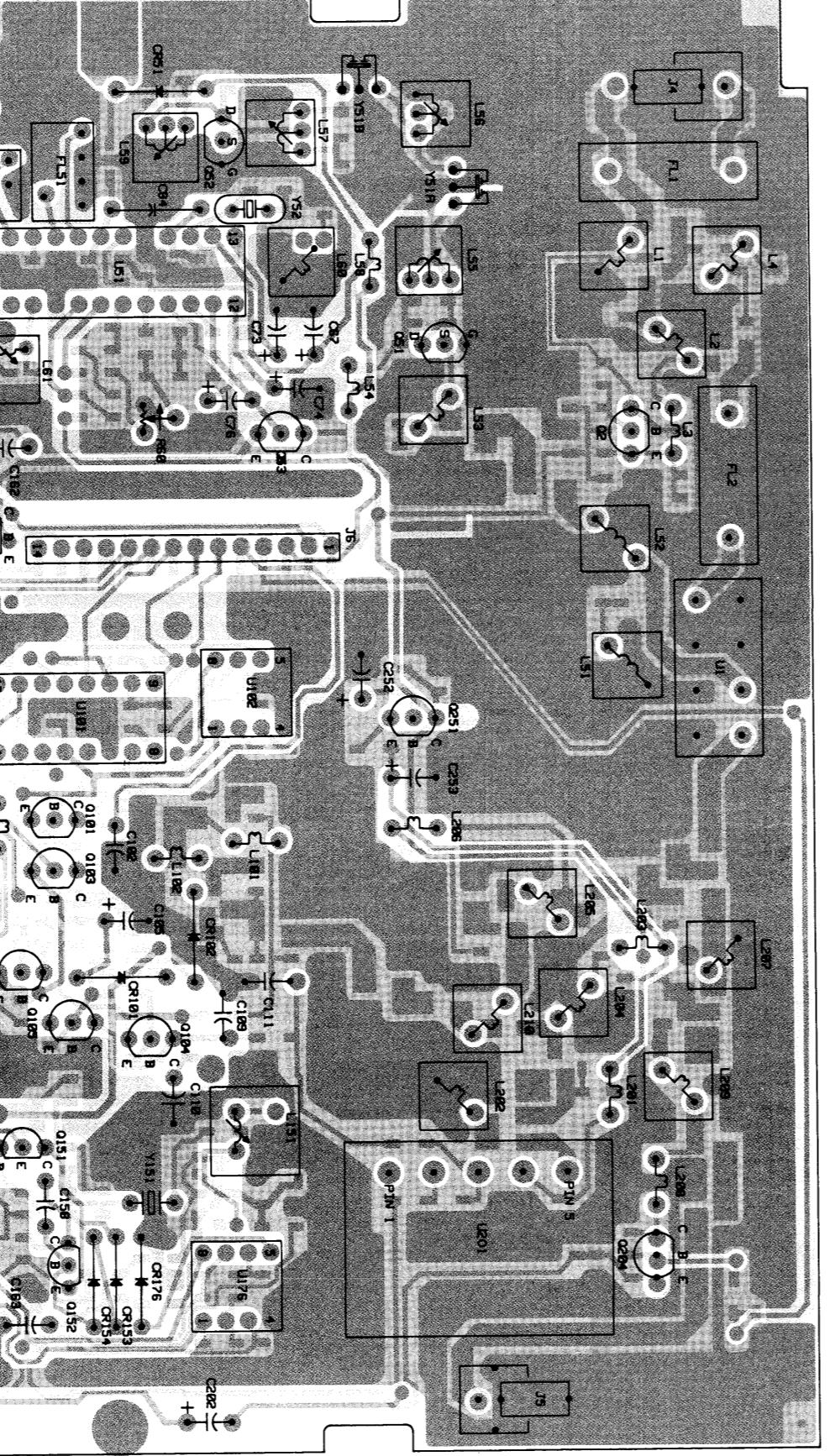
COMPONENTS WITHIN BOX ARE NOT
FIELD-SERVICEABLE. IF SERVICING IS
REQUIRED, THE ENTIRE BOARD MUST BE
REPLACED





SOLDER SIDE VIEW

RED GAW-7727-O
GREY GAW-7728-O
BLACK GDW-7729-O



COMPONENT SIDE VIEW

parts list

HLF4095B MaxTrac 800 MHz RF Board

MXW-7409-O

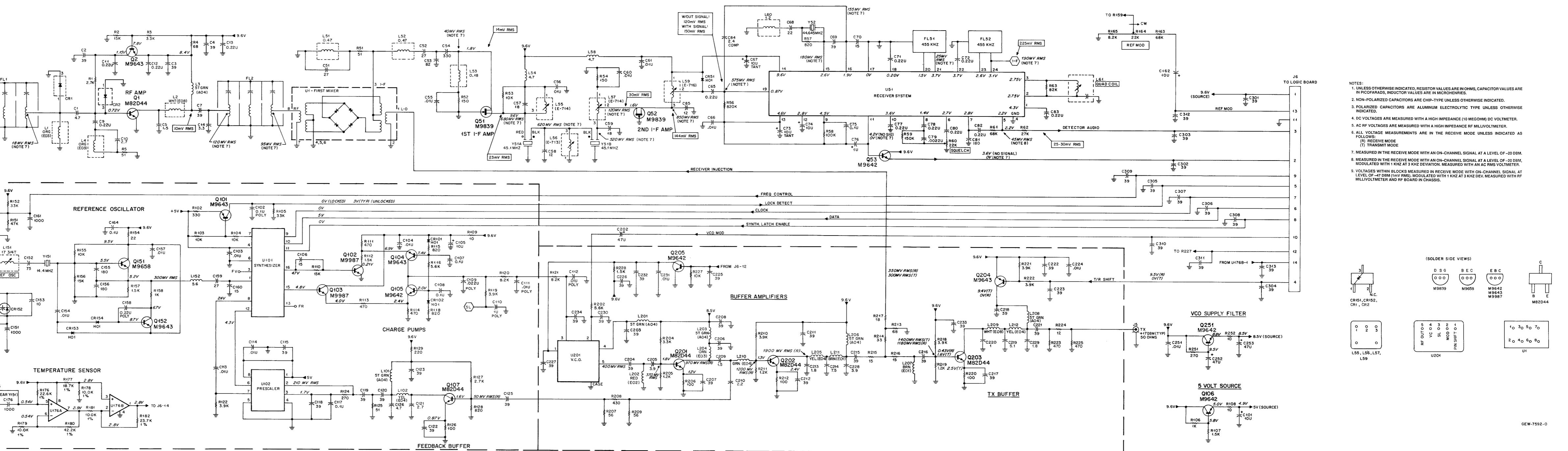
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C1	21-13740B17	4.7 pF, ±5%, 50V
C2-4	21-13740B39	39 pF, ±5%, 50V
C5	21-13740B05	1.5 pF, ±5%, 50V
C7	21-13740B39	39 pF, ±5%, 50V
C9	21-11032B15	.22 uF, ±80%, -20%, 50V
C10	21-13740B11	2.7 pF, ±5%, 50V
C11-13	21-11032B15	.22 uF, ±80%, -20%, 50V
C14	21-13740B13	3.3 pF, ±5%, 50V
C51	21-13740B35	27 pF, ±5%, 50V
C52	21-13740B35	27 pF, ±5%, 50V
C53	21-13740B47	.82 pF, ±5%, 50V
C54	21-13740B61	.33 nF, ±5%, 50V
C55,56	21-13741B45	.01 uF, ±5%, 50V
C57	21-13740B31	18 pF, ±5%, 50V
C58	21-13740B27	12 pF, ±5%, 50V
C59	21-13740B31	18 pF, ±5%, 50V
C60,61	21-13741B45	.01 uF, ±5%, 50V
C65	21-11032B15	.22 uF, ±80%, -20%, 50V
C66	21-13741B45	.01 uF, ±5%, 50V
C67	23-11013D13	10 uF, ±5%, 20V, tantalum
C68	21-13740B33	22 pF, ±5%, 50V
C69	21-13740B39	39 pF, ±5%, 50V
C70	21-13740B29	15 pF, ±5%, 50V
C71,72	21-11032B15	.22 uF, ±80%, -20%, 50V
C73	23-11013D13	10 uF, ±5%, 20V, tantalum
C74	23-11048B13	10 uF, ±20%, 16V, electrolytic
C75	21-11048B9	1.0 uF, ±5%, 50V
C76	23-11048B5	1.0 uF, ±20%, 16V, electrolytic
C77,78	21-1032B15	.22 uF, ±80%, -20%, 50V
C79	21-11032B29	.0022 uF, ±5%, 50V
C80	21-11032B15	.22 uF, ±80%, -20%, 50V
C81	21-13740B5	.180 pF, ±5%, 50V
C82,83	21-11032B15	.22 uF, ±80%, -20%, 50V
C84	21-82450B14	2.4 pF, ±5%, 500V
C85	21-13740B27	.12 pF, ±5%, 50V
C101	23-11048B13	10 uF, ±20%, 16V, electrolytic
C102	09-11051A13	.1 uF, ±5%, 63V
C103,104	21-13741B45	.01 uF, ±5%, 50V
C105	23-11048B13	10 uF, ±20%, 16V, electrolytic
C106	21-13740B29	15 pF, ±5%, 50V
C107	21-13741B69	.1 uF, ±5%, 50V
C108	21-13741B69	.1 uF, ±5%, 50V
C109	09-11051A09	.022 uF, ±5%, 63V
C110	09-11051A19	.1 uF, ±5%, 63V
C111	09-11051A07	.01 uF, ±5%, 63V
C112	21-13741B43	.0082 uF, ±5%, 50V
C113,114	21-13741B45	.01 uF, ±5%, 50V
C115	21-13740B39	.39 pF, ±5%, 50V
C117	21-13741B69	.1 uF, ±5%, 50V
C118-120	21-13740B39	.39 pF, ±5%, 50V
C121	21-13740B11	.27 pF, ±5%, 50V
C122,123	21-13740B39	.39 pF, ±5%, 50V
C125	21-13740B39	.39 pF, ±5%, 50V
C126	21-13740B17	4.7 pF, ±5%, 50V
C151	21-13740B73	.001 uF, ±5%, 50V
C152	21-13740B46	.75 pF, ±5%, 50V
C153	21-13740B25	10 pF, ±5%, 50V
C154	21-13741B45	.01 uF, ±5%, 50V
C155,156	21-13740B55	.180 pF, ±5%, 50V
C157	21-13741B45	.01 uF, ±5%, 50V
C158	08-11051A15	.22 uF, ±5%, 63V
C159	21-13740B35	.27 pF, ±5%, 50V
C160	21-13740B29	.15 pF, ±5%, 50V
C161	21-13740B73	.001 uF, ±5%, 50V
C162	23-11048B13	10 uF, ±20%, 16V, electrolytic
C163	08-11051A17	.47 uF, ±5%, 63V
C164	21-13741B69	.1 uF, ±5%, 50V
C176	23-11048B73	.001 uF, ±5%, 50V
C202,204	23-11048B19	47 uF, ±20%, 16V, electrolytic
C205	21-13740B22	7.5 pF, ±5%, 50V
C206-208	21-13740B39	.39 pF, ±5%, 50V
C209	21-13740B07	1.8 pF, ±5%, 50V
C210	21-13740B09	2.2 pF, ±5%, 50V
C211,212	21-13740B39	.39 pF, ±5%, 50V
C213	21-13740B17	4.7 pF, ±5%, 50V
C214	21-13740B21	6.8 pF, ±5%, 50V
C215-217	21-13740B39	.39 pF, ±5%, 50V
C218	21-13741B39	.39 pF, ±5%, 50V
C219	21-13740B22	7.5 pF, ±5%, 50V
C220	21-13740B11	2.7 pF, ±5%, 50V
C221-223	21-13740B39	.39 pF, ±5%, 50V
C224	21-13740B45	.01 uF, ±5%, 50V
C251,C252,253	23-11048B19	.68 pF, ±5%, 50V
C301-313	21-13740B39	.47 uF, ±20%, 16V, electrolytic
diode (see note)	48-83654H01	silicon
CR51	48-83654H01	silicon
CR101,102	48-83654H01	varactor
CR151,152	48-05129M21	
CR153,154	48-83654H01	silicon
CR176	48-82256C11	10V zener
filter	FL1,2	91-80054M01
	FL51	91-80097D06
	FL52	91-80098D06
RF coil	L1	24-11030E03

MXW-7409-O (2)

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
REFERENCE SYMBOL		
L2	24-11030E08	white
L3	24-11030A04	5 turns, green
L4	24-11030E03	orange
L5,152	24-80063M09	.47 uH
L53	24-80063M04	4.7 uH
L54	24-80164M01	5.2 turns, variable
L56	24-80164M01	1.6 ratio, variable
L57	24-80164M01	5.2 turns, variable
L58	24-80063M21	.47 uH
L59	24-80164M03	4.3 turns, variable
L60	24-80063M14	.12 uH
L61	25-8000E001	transformer
L101	24-11030A04	5 turns, green
L102	24-11030E04	yellow
L151	24-80299D01	17.75 turns, orange
L152	24-80063M22	.56 uH
L201	24-11030A04	5 turns, green
L202	24-11030E01	brown
L203	24-11030A04	5 turns, green
L204	24-11030E04	yellow
L205	24-11030E03	orange
L206	24-11030A04	5 turns, green
L207	24-11030E02	red
L208	24-11030A04	5 turns, green
L209,210	24-11030E04	yellow
connector receptacle	J4,5	09-80135M01
	J6	09-80130M03
transformer	T1,2	25-80163M02
transistor (see note)	Q1	48-80950X01
	Q2	48-00869E43
	Q51,52	N-channel
	Q53	48-00869E42
	Q54	48-00869E43
	Q55	48-01812D20
	Q56	48-00869E43
	Q57	48-00869E42
	Q58	48-00869E43
	Q59	48-00869E42
	Q60	48-00869E43
	Q201-203	48-80950X01
	Q204	48-00869E43
	Q251	48-00869E42
resistor, fixed, ohm, +5%, 1/8 watt (unless otherwise stated)	R1	06-11077A84
	R2	06-11077B03
	R3	06-11077A86
	R4	06-11077A46
	R5	06-11077A43
	R51	06-11077A43
	R52	06-11077A45
	R53	06-11077A98
	R54	06-11077A54
	R55	06-11077B45
	R56	06-11077A72
	R57	06-11077B23
	R58	06-11077B23
	R59	06-11077B27
	R60	14-05160A01
	R61	26-90099M01
	R62	26-90228L01
	R63	26-90228L01
	R64	26-90256L01
	R65	30-10286A72
	R66	42-80047N01
	R67	54-90111F01
	R68	75-05295B02
	R69	75-05295B07
	R70	84-80132L01
note: For best performance, order diodes, transistors, and integrated circuit devices by Motorola part number.		

800 MHz RF Board Transistor D.C. Voltage Table

Transistor Ref. No.	VOLTAGE			VOLTAGE		
	BASE	EMITTER	COLLECTOR	GATE	SOURCE	DRAIN
Q1	7.2	0	8.4	—	—	—
Q2	7.8	8.4	1.2	—	—	—
Q51	—	—	—	0	1.8	9.6
Q52	—	—	—	0	1.8	9.6
Q53	0(SIG)	0(SIG)	9.6	—	—	—
Q101	4.8	4.8	0(LOCK)	—	—	—
Q102	.72(R)	0	.21	—	—	—
Q103	4.8	4.0	9.6	—	—	—
Q104	7.4	6.9	2-8V	—	—	—
Q105	2.0	2.4	2-8V	—	—	—
Q106	5.8	5.0	9.6	—	—	—
Q107	1.6	.87	9.6	—	—	—
Q151	5.5	5.2	9.5	—	—	—
Q152	8.7	9.5	6.7	—	—	—
Q201	1.8	1.2	8.5	—	—	—
Q202	1.3	2.4	9.6	—	—	—
Q203	1.6(T)	2.5(T)	9.4(T)	—	—	—
Q204	9.5(R)	9.6	9.4(T)	—	—	—
Q251	9.5	8.8	9.6	—	—	—



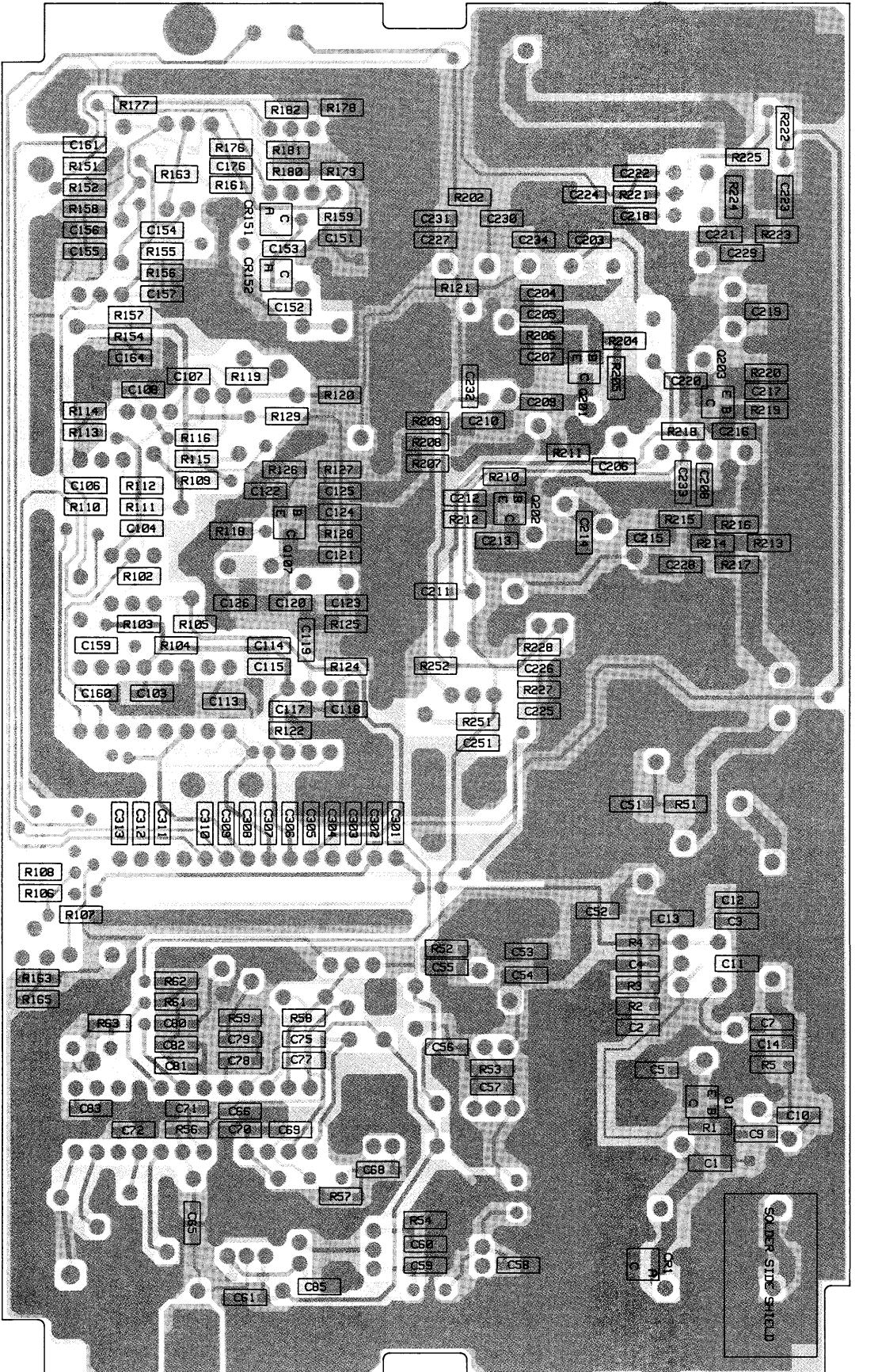
Schematic, Circuit Board Diagrams, and

Parts List for HLF9122A 800 MHz RF Board

PW-7591-O

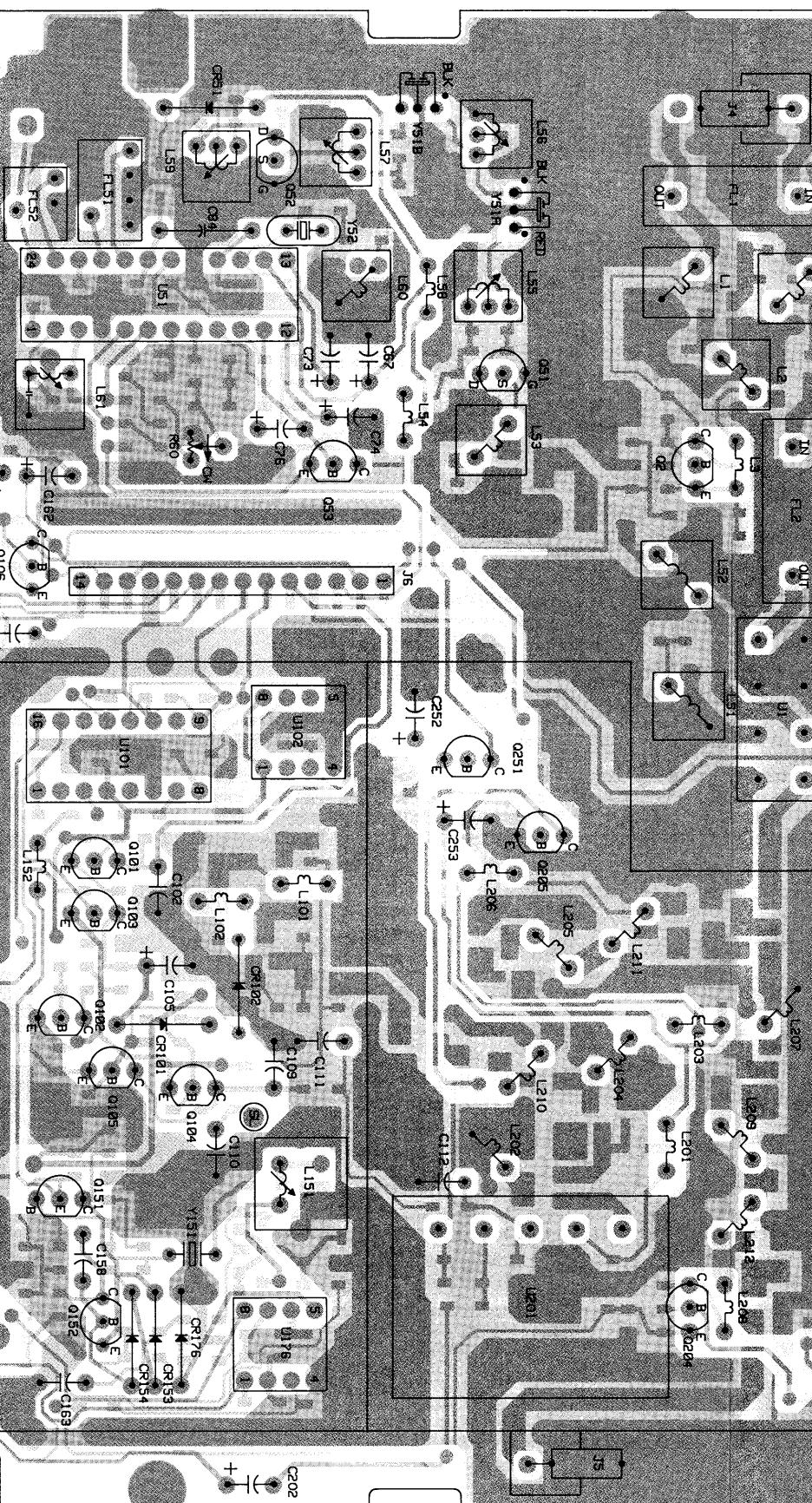
(Sheet 1 of 2)

3/31/90



SOLDER SIDE VIEW

RED GAW-7730-0
GREY GAW-7731-0
BLACK GDW-7732-0



COMPONENT SIDE VIEW

parts list

HLF9122A MaxTrac 800 MHz RF Board with Talkaround MXW-7410-O

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
capacitor, fixed (unless otherwise stated)		
C1	21-13740B17	.47 pF, ±5%, 50V
C2-4	21-13740B39	.39 pF, ±5%, 50V
C5	21-13740B05	1.5 pF, ±5%, 50V
C7	21-13740B39	.39 pF, ±5%, 50V not used
C8	21-60521H41	.22 uF, ±80%, -20%, 50V
C9	21-13740B11	.27 pF, ±5%, 50V
C10	21-60521H41	.22 uF, ±80%, -20%, 50V
C11-13	21-13740B13	.33 pF, ±25pF, 50V
C14	21-13740B35	.27 pF, ±5%, 50V
C51,52	21-13740B47	.82 pF, ±5%, 50V
C53	21-13740B61	.330 pF, ±5%, 50V
C54	21-13741B45	.01 uF, ±5%, 50V
C55,56	21-13741B45	.01 uF, ±5%, 50V
C56	21-13740B31	.18 pF, ±5%, 50V
C57	21-13740B27	.12 pF, ±5%, 50V
C58	21-13740B31	.18 pF, ±5%, 50V
C59	21-13741B45	.01 uF, ±5%, 50V
C60,61	21-60521H41	.22 uF, -80%, -20%, 50V
C65	21-13741B45	.01 uF, ±5%, 50V
C66	23-43749C39	.10 uF, ±10%, 50V, tantalum
C67	21-13740B33	.22 pF, ±5%, 50V
C68	21-13740B39	.39 pF, ±5%, 50V
C69	21-13740B29	.15 pF, ±5%, 50V
C71,72	21-60521H41	.22 uF, -80%, -20%, 50V
C73	23-11013D13	.10 uF, ±10%, 20V, tantalum
C74	23-11048B13	.10 uF, ±20%, 16V, electrolytic
C75	23-11048B05	.1 uF, ±20%, 50V
C76	21-60521H41	.22 uF, -80%, -20%, 50V
C77,78	21-13741B29	.0022 uF, ±5%, 50V
C79	21-60521H41	.22 uF, -80%, -20%, 50V
C80	21-13740B55	.180 pF, ±5%, 50V
C81	21-60521H41	.22 uF, -80%, -20%, 50V
C82,83	21-82450B14	.24 pF, ±5%, 500V
C84	21-13740B27	.12 pF, ±5%, 50V
C85	23-11048B13	.10 uF, ±20%, 16V, electrolytic
C101	08-11051A13	.1 uF, ±5%, 63V
C102	21-13741B45	.01 uF, ±5%, 50V
C103,104	21-13740B13	.10 uF, ±20%, 16V, electrolytic
C105	21-13740B29	.15 pF, ±5%, 50V
C106	21-13741B69	.1 uF, ±5%, 50V
C107,108	08-11051A09	.022 uF, ±5%, 63V
C109	08-11051A19	.1 uF, ±5%, 63V
C110	08-11051A07	.01 uF, ±5%, 63V
C111,112	21-13741B45	.01 uF, ±5%, 50V
C113,114	21-13740B39	.39 pF, ±5%, 50V
C115	21-13740B39	not used
C116	21-13741B69	.1 uF, ±5%, 50V
C117	21-13740B39	.39 pF, ±5%, 50V
C118-120	21-13740B11	.27 pF, ±5%, 50V
C121	21-13740B39	.39 pF, ±5%, 50V
C122,123	21-13740B39	not used
C124	21-13740B39	.39 pF, ±5%, 50V
C125	21-13740B17	.47 pF, ±5%, 50V
C126	21-13740B17	not used
C127	21-13740B73	.001 uF, ±5%, 50V
C128	21-13740B46	.75 pF, ±5%, 50V
C129	21-13740B25	.20 pF, ±5%, 50V
C130	21-13741B45	.01 uF, ±5%, 50V
C131	21-13740B55	.180 pF, ±5%, 50V
C132	21-13741B45	.01 uF, ±5%, 50V
C133	08-11051A15	.22 uF, ±5%, 63V
C134	21-13740B35	.27 pF, ±5%, 50V
C135	21-13740B29	.15 pF, ±5%, 50V
C136	21-13740B73	.001 uF, ±5%, 50V
C137	23-1046B13	.23 pF, ±20%, 16V, electrolytic
C138	08-11051A17	.47 uF, ±5%, 63V
C139	21-13741B69	.1 uF, ±5%, 50V
C140	21-13740B73	.001 uF, ±5%, 50V
C141	23-11048B19	.47 uF, ±20%, 16V, electrolytic
C142	21-13740B39	.39 pF, ±5%, 50V
C143	21-13740B15	.39 pF, ±5%, 50V
C144	21-13740B39	.51 pF, ±5%, 50V
C145	21-13740B39	.15 pF, ±5%, 50V
C146	21-13740B05	.22 pF, ±5%, 50V
C147	21-13740B05	.39 pF, ±5%, 50V
C148	21-13740B39	.39 pF, ±5%, 50V
C149	21-13740B39	.39 pF, ±5%, 50V
C150	21-13740B39	.39 pF, ±5%, 50V
C151	21-13740B39	.39 pF, ±5%, 50V
C152	21-13740B46	.75 pF, ±5%, 50V
C153	21-13740B25	.20 pF, ±5%, 50V
C154	21-13741B45	.01 uF, ±5%, 50V
C155,156	21-13740B39	.39 pF, ±5%, 50V
C157	21-13741B45	.01 uF, ±5%, 50V
C158	08-11051A15	.22 uF, ±5%, 63V
C159	21-13740B35	.27 pF, ±5%, 50V
C160	21-13740B29	.15 pF, ±5%, 50V
C161	21-13740B73	.001 uF, ±5%, 50V
C162	23-1046B13	.23 pF, ±20%, 16V, electrolytic
C163	08-11051A17	.47 uF, ±5%, 63V
C164	21-13741B69	.1 uF, ±5%, 50V
C165	21-13740B73	.001 uF, ±5%, 50V
C166	21-13740B73	.001 uF, ±5%, 50V
C167	21-13740B73	.001 uF, ±5%, 50V
C168	21-13740B39	.39 pF, ±5%, 50V
C169	21-13740B39	.39 pF, ±5%, 50V
C170	21-13740B39	.39 pF, ±5%, 50V
C171	21-13740B39	.39 pF, ±5%, 50V
C172	21-13740B39	.39 pF, ±5%, 50V
C173	21-13740B39	.39 pF, ±5%, 50V
C174	21-13740B39	.39 pF, ±5%, 50V
C175	21-13740B39	.39 pF, ±5%, 50V
C176	21-13740B39	.39 pF, ±5%, 50V
C177	21-13740B39	.39 pF, ±5%, 50V
C178	21-13740B39	.39 pF, ±5%, 50V
C179	21-13740B39	.39 pF, ±5%, 50V
C180	21-13740B39	.39 pF, ±5%, 50V
C181	21-13740B39	.39 pF, ±5%, 50V
C182	21-13740B39	.39 pF, ±5%, 50V
C183	21-13740B39	.39 pF, ±5%, 50V
C184	21-13740B39	.39 pF, ±5%, 50V
C185	21-13740B39	.39 pF, ±5%, 50V
C186	21-13740B39	.39 pF, ±5%, 50V
C187	21-13740B39	.39 pF, ±5%, 50V
C188	21-13740B39	.39 pF, ±5%, 50V
C189	21-13740B39	.39 pF, ±5%, 50V
C190	21-13740B39	.39 pF, ±5%, 50V
C191	21-13740B39	.39 pF, ±5%, 50V
C192	21-13740B39	.39 pF, ±5%, 50V
C193	21-13740B39	.39 pF, ±5%, 50V
C194	21-13740B39	.39 pF, ±5%, 50V
C195	21-13740B39	.39 pF, ±5%, 50V
C196	21-13740B39	.39 pF, ±5%, 50V
C197	21-13740B39	.39 pF, ±5%, 50V
C198	21-13740B39	.39 pF, ±5%, 50V
C199	21-13740B39	.39 pF, ±5%, 50V
C200	21-13740B39	.39 pF, ±5%, 50V
C201	21-13740B39	.39 pF, ±5%, 50V
C202	21-13740B39	.39 pF, ±5%, 50V
C203	21-13740B39	.39 pF, ±5%, 50V
C204	21-13740B39	.39 pF, ±5%, 50V
C205	21-13740B39	.39 pF, ±5%, 50V
C206-208	21-13740B39	.39 pF, ±5%, 50V
C209	21-13740B05	.1.5 pF, ±5%, 50V
C210	21-13740B09	.2.2 pF, ±5%, 50V
C211,212	21-13740B39	.39 pF, ±5%, 50V
C213	21-13740B07	.1.8 pF, ±5%, 50V
C214	21-13740B22	.7.5 pF, ±5%, 50V
C215-217	21-13740B39	.39 pF, ±5%, 50V
C218	21-13741B39	.39 pF, ±5%, 50V
C219	21-13740B18	.5.1 pF, ±5%, 50V
C220	21-13740B01	.1 pF, ±5%, 50V
C221-223	21-13740B39	.39 pF, ±5%, 50V
C224	21-13740B45	.01 uF, ±5%, 50V
C225-227	21-13740B39	.39 pF, ±5%, 50V
C228	21-13740B15	.3.9 pF, ±5%, 50V
C229	21-13740B07	.1.8 pF, ±5%, 50V
C230	21-13740B39	.39 pF, ±5%, 50V
C231	21-13741B45	.01 uF, ±5%, 50V
C232-234	21-13740B39	.39 pF, ±5%, 50V
C251	21-13741B45	.01 uF, ±5%, 50V
C252,253	23-11048B19	.47 uF, ±20%, 16V, electrolytic
C301-313	21-13740B39	.39 pF, ±5%, 50V
diode (see note)	CR1	48-